





TEXAS INSTRUMENTS

TPS544C26 SLVSFW7 – SEPTEMBER 2022

TPS544C26 4-V to 16-V Input, 35-A Synchronous Buck Converter With SVID And I²C Interfaces

1 Features

I²C Interfac

- Single chip power supply for SVID rails
- Intel[®] VR13 SVID compliant
- I²C interface with NVM for configuration, telemetry (V/I/T) and fault reporting
- Input power monitoring for DDR5 memory RAPL
- Integrated 4.0-m Ω and 1.0-m Ω MOSFETs for 35-A continuous current operation
- Supports external 5-V bias improving efficiency and enabling 2.7-V minimum input voltage
- V_{OUT} programmable from 0.25 V to 3.04 V
- Precision voltage reference and differential remote sense for high output accuracy
 - $-~\pm 0.5\%~V_{OUT}$ tolerance from 0°C to 85°C T_J
 - ±1% V_{OUT} tolerance from -40°C to 125°C T_{.1}
- D-CAP+[™] control topology with fast transient response, supporting all ceramic output capacitors
- Programmable internal loop compensation including droop
- Selectable cycle-by-cycle valley current limit
- Selectable operation frequency 0.6 MHz to 1.2 MHz with DCM or FCCM operation
- · Safe start-up into pre-biased outputs
- Programmable soft-start time from 1 ms to 16 ms
- Programmable soft-stop time from 0.5 ms to 4 ms
- Open-drain power-good output (VRRDY) and Catastrophic fault indicator (CAT_FAULT#)
- Programmable overcurrent, overvoltage, undervoltage, overtemperature protections
- 5 mm × 6 mm, 37-pin WQFN-FCRLF package
- TPS548C26 non-SVID/I²C analog converter in the same package available soon

2 Applications

- · Server and cloud-computing POLs
- Hardware accelerator
- Network interface card

3 Description

The TPS544C26 device is a highly integrated buck converter with D-CAP+ control topology for the fast transient response. All programmable parameters can be configured by the l^2C interface and stored in NVM as the new default values to minimize the external component count. These features make the device well-suited for space-constrained applications.

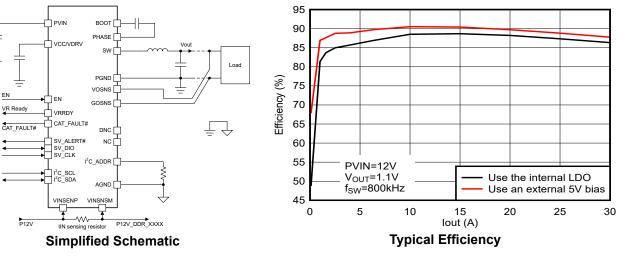
The TPS544C26 device is designed to work with Intel CPUs and fits well for single-phase, low-to-mid current SVID rails in Intel's server and SoC platforms.

Fault management and status reports for the Overcurrent limit, V_{OUT} OVF/UVF, and OTF are provided on the device. The TPS544C26 device provides a full set of telemetry, including V_{OUT} , I_{OUT} , and IC temperature. Additionally, input power monitoring through an external sensing resistor is provided for board-level power management.

The TPS544C26 device is a lead-free device and is RoHS compliant without exemption.

| Package Information | | | | |
|---------------------|------------------------|-------------------|--|--|
| PART NUMBER | PACKAGE ⁽¹⁾ | BODY SIZE (NOM) | | |
| TPS544C26 | RXX (WOEN-ECRI E 37) | 5.00 mm x 6.00 mm | | |

 For all available packages, see the orderable addendum at the end of the data sheet.



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



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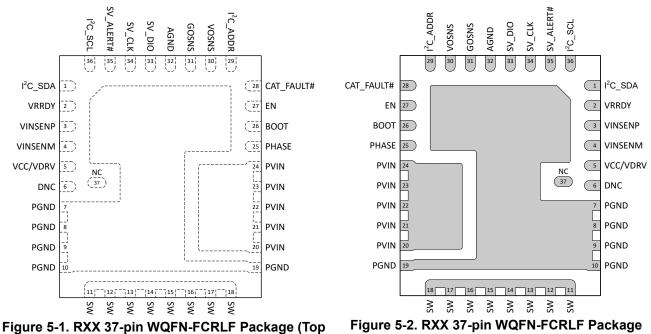
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| DATE | REVISION | NOTES |
|----------------|----------|-----------------|
| September 2022 | * | Initial release |



5 Pin Configuration and Functions



. View)

Table 5-1. Pin Functions

(Bottom View)

| PIN | | L(Q(1) | DECODIDION | | | |
|-----------------------|----------|--------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|
| NAME | NO. | I/O ⁽¹⁾ | DESCRIPTION | | | |
| AGND | 32 | G | Ground pin, reference point for internal control circuitry. | | | |
| BOOT | 26 | Р | Supply rail for the high-side gate driver (boost terminal). Connect the bootstrap capacito from this pin to PHASE pin. A high temperature (X7R) 0.1 μ F or greater value ceramic capacitor is recommended. | | | |
| CAT_FAULT# | 28 | 0 | Catastrophic Fault indicator, open-drain. The CAT_FAULT# indicator asserts low wher ny catastrophic fault event (over-voltage, under-voltage and over-temperature) happe During nominal operation, the CAT_FAULT# indicator holds high. | | | |
| DNC | 6 | _ | Do Not Connect (DNC) pin. This pin is the output of internal circuitry and must be floating. Pin 6 and pin 37 can be shorted together but NO any other PCB connection is allowed on pin 6. | | | |
| EN | 27 | I | Enable pin, an active-high input pin that, when asserted high, causes the converter to begin its soft-start sequence for its output voltage rail. When de-asserted low, the converter must de-assert VRRDY and begin the shutdown sequence of the output voltage rail and continue to completion. | | | |
| GOSNS | 31 | I | Negative input of the differential remote sense circuit, connect to the ground sense point on the load side. | | | |
| I ² C_ADDR | 29 | I | The I ² C address of the device is set by tying an external resistor between this pin and AGND. | | | |
| I ² C_SCL | 36 | I | I ² C serial clock pin, open drain. | | | |
| I ² C_SDA | 1 | I/O | I ² C bi-directional serial data pin, open drain. | | | |
| NC | 37 | | Not connected. This pin is floating internally. Pin 37 and pin 6 can be shorted together. | | | |
| PGND | 7–10, 19 | G | Power ground for the internal power stage. | | | |
| PHASE | 25 | _ | Return for high-side MOSFET driver. Shorted to SW internally. Connect the bootstrap capacitor from BOOT pin to this pin. | | | |
| PVIN | 20–24 | Р | Power input for both the power stage. PVIN is the input of the internal VCC LDO as well. | | | |
| SV_ALERT# | 35 | 0 | SVID active low ALERT# signal, open drain. This output is asserted to indicate the status of the converter has changed. | | | |



Table 5-1. Pin Functions (continued)

| PIN | | I/O ⁽¹⁾ | DESCRIPTION | | |
|----------|-------|--------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|
| NAME | NO. | | DESCRIPTION | | |
| SV_CLK | 34 | I | SVID clock pin, open drain. | | |
| SV_DIO | 33 | I/O | SVID bi-directional data pin, open drain. | | |
| sw | 11–18 | 0 | Output switching terminal of the power converter. Connect these pins to the output inductor. | | |
| VCC/VDRV | 5 | Ρ | Internal VCC LDO output and also the input for gate driver circuit. An external 5-V bias can be connected to this pin to save the power losses on the internal LDO. The voltage source on this pin powers both the internal control circuitry and the gate driver. A 2.2 μ F (or 4.7 μ F), at least 6.3 V rating ceramic capacitor is required to be placed from VCC/VDRV pin to PGND pins to decouple the noise generated by driver circuitry. Check layout guidelines for more details. | | |
| VINSENM | 4 | I | more details. Negative input for the input power telemetry. Connect to the negative side of the inp power sense resistor. Input voltage is also sensed at this pin. To minimize the impact from switching noise, a ceramic decoupling capacitor with at least 100 pF capacitan required from this pin to PGND. Check layout guidelines for more details. | | |
| VINSENP | 3 | I | Positive input for the input power telemetry. Connect to the positive side of the input power sense resistor. To minimize the impact from switching noise, a ceramic decoupling capacitor with at least 100-pF capacitance is required from this pin to PGND. Check layout guidelines for more details. | | |
| VOSNS | 30 | I | Positive input of the differential remote sense circuit, connect to the Vout sense point on the load side. | | |
| VRRDY | 2 | 0 | Voltage regulator "Ready" output signal. The VRRDY indicator is asserted when the controller is ready to accept SVID commands after the EN is asserted. VRRDYalso de- asserts low when a shutdown fault occurs. This open-drain output requires an external pullup resistor. | | |



6 Specifications

6.1 Absolute Maximum Ratings

Over operating junction temperature range (unless otherwise noted) (1)

| | | MIN | MAX | UNIT |
|------------------|-----------------------------------------------------------------------|------|------|------|
| Pin voltage | PVIN | -0.3 | 18 | V |
| Pin voltage | PVIN – SW, DC | -0.3 | 18 | V |
| Pin voltage | PVIN – SW, transient < 10 ns | -1.5 | 26 | V |
| Pin voltage | SW – PGND, DC | -0.3 | 18 | V |
| Pin voltage | SW – PGND, transient < 10 ns | -3.0 | 21.5 | V |
| Pin voltage | BOOT – PGND | -0.3 | 23.5 | V |
| Pin voltage | BOOT – SW | -0.3 | 5.5 | V |
| Pin voltage | VCC/VDRV | -0.3 | 5.5 | V |
| Pin voltage | PHASE | -0.3 | 18 | V |
| Pin voltage | VINSENP, VINSENM | -0.3 | 20 | V |
| Pin voltage | EN, VOSNS, I ² C_ADDR, VRRDY, CAT_FAULT# | -0.3 | 5.5 | V |
| Pin voltage | SV_CLK, SV_DIO, SV_ALERT#, I ² C_SCL, I ² C_SDA | -0.3 | 5.5 | V |
| Pin voltage | GOSNS – AGND | -0.3 | 0.3 | V |
| Pin voltage | DNC, NC | -0.3 | 1.9 | V |
| Sink current | VRRDY | 0 | 10 | mA |
| TJ | Operating junction temperature | -40 | 150 | °C |
| T _{stg} | Storage temperature | -55 | 150 | °C |

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|-----------------------------------------------------------------------|-------|------|
| | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | M |
| V _(ESD) | | Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾ | ±500 | v |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating junction temperature range (unless otherwise noted)

| | | | MIN | NOM MAX | UNIT |
|-------------------|--------------------------------|-------------------------------------------------------|------|---------|------|
| V _{OUT} | Programmable output voltage ra | ange | 0.25 | 3.04 | V |
| V | | PVIN when VCC/VDRV is powered by the internal LDO | 4.0 | 16 | V |
| V _{IN} | Input voltage | PVIN when VCC/VDRV is powered by an external 5 V bias | 2.7 | 16 | V |
| V _{BIAS} | Input voltage | VCC/VDRV external bias | 4.75 | 5.3 | V |
| I _{OUT} | Output current range | | | 35 | A |
| | Pin voltage | VINSENP, VINSENM | 8 | 16 | V |
| | Pin voltage | EN, VRRDY, CAT_FAULT# | -0.1 | 5.3 | V |
| | Pin voltage | SV_CLK, SV_DIO, SV_ALERT# | -0.1 | 1.5 | V |
| | Pin voltage | I ² C_SCL, I ² C_SDA | -0.1 | 5.3 | V |
| IVRRDY | VRRDY input current capability | | | 10 | mA |
| TJ | Operating junction temperature | | -40 | 125 | °C |



6.4 Thermal Information

| | | DE | | |
|-----------------------|----------------------------------------------|------------------|-------------------------------|------|
| | THERMAL METRIC ⁽¹⁾ | RXX (QFN, JEDEC) | RXX (QFN, TI EVM) | UNIT |
| | | 37 PINS | 37 PINS |] |
| R _{0JA} | Junction-to-ambient thermal resistance | 26.0 | 16.0 | °C/W |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 7.4 | Not applicable ⁽²⁾ | °C/W |
| R _{0JB} | Junction-to-board thermal resistance | 3.6 | Not applicable ⁽²⁾ | °C/W |
| ΨJT | Junction-to-top characterization parameter | 0.2 | 0.2 | °C/W |
| Ψјв | Junction-to-board characterization parameter | 3.6 | 5.7 | °C/W |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | 3.3 | Not applicable ⁽²⁾ | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

(2) The thermal test or simulation setup is not applicable to a TI EVM layout.

6.5 Electrical Characteristics

| | PARAMETER | TEST CONDITIONS | MIN | ТҮР | MAX | UNIT |
|----------------------|--------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| SUPPLY | | | | | | |
| | PVIN operating input range | | 4 | | 16 | V |
| I _{Q(PVIN)} | PVIN quiescent current | Non-switching, PVIN = 12 V, V _{EN} = 0 V, no bias on VCC/VDRV pin | 6 | 7.9 | 9 | mA |
| I _{VCC} | VCC/VDRV external bias current | $ \begin{array}{l} \mbox{External 5 V bias on VCC/VDRV pin, regular} \\ \mbox{switching. } T_J = 25^\circ C, \mbox{PVIN} = 12 \ V, \ I_{OUT} = 35 \\ \mbox{A}, \ V_{EN} = 2 \ V, \ f_{SW} = 0.6 \ \mbox{MHz} \end{array} $ | | 32.7 | | mA |
| Ivcc | VCC/VDRV external bias current | $ \begin{array}{l} \mbox{External 5 V bias on VCC/VDRV pin, regular} \\ \mbox{switching. } T_J = 25^\circ C, \mbox{PVIN} = 12 \ V, \ I_{OUT} = 35 \\ \mbox{A}, \ V_{EN} = 2 \ V, \ f_{SW} = 0.8 \ \mbox{MHz} \end{array} $ | | 39.7 | | mA |
| Ivcc | VCC/VDRV external bias current | $ \begin{array}{l} \mbox{External 5 V bias on VCC/VDRV pin, regular} \\ \mbox{switching. } T_J = 25^\circ C, \mbox{PVIN} = 12 \ V, \ I_{OUT} = 35 \\ \mbox{A}, \ V_{EN} = 2 \ V, \ f_{SW} = 1.0 \ \mbox{MHz} \end{array} $ | | 48.7 | | mA |
| I _{VCC} | VCC/VDRV external bias current | $ \begin{array}{l} \mbox{External 5 V bias on VCC/VDRV pin, regular} \\ \mbox{switching. } T_J = 25^\circ C, \mbox{PVIN} = 12 \ V, \ I_{OUT} = 35 \\ \mbox{A}, \ V_{EN} = 2 \ V, \ f_{SW} = 1.2 \ MHz \end{array} $ | | 57.3 | | mA |
| I _{Q(VCC)} | VCC/VDRV quiescent current | External 5 V bias on VCC/VDRV pin, non- switching. PVIN = 12V, V_{EN} = 2 V, V_{VOSNS} = $V_{O_Setting}$ + 50 mV | 6 | 7.9 | 9 | mA |
| UVLO | · | | | | | |
| PVIN _{OV} | PVIN overvoltage rising threshold | PVIN rising, register (55h) VIN_OV_FAULT_LIMIT = 00h | 16.3 | 16.9 | 17.5 | V |
| PVIN _{OV} | PVIN overvoltage rising threshold | PVIN rising, register (55h) VIN_OV_FAULT_LIMIT = 01h | 18.0 | 18.6 | 19.2 | V |
| PVIN _{OV} | PVIN overvoltage falling threshold | PVIN falling. PVIN_OVF status bit, once it is set, cannot be cleared unless PVIN falls below the PVIN overvoltage falling threshold | 12.9 | 13.4 | 13.9 | V |
| VIN_ON | PVIN turn-on voltage | PVIN rising, register (35h) VIN_ON = 00h | 9.7 | 10 | 10.2 | V |
| VIN_ON | PVIN turn-on voltage ⁽¹⁾ | PVIN rising, register (35h) VIN_ON = 01h | | 9 | | V |
| VIN_ON | PVIN turn-on voltage | PVIN rising, register (35h) VIN_ON = 02h | 7.8 | 8 | 8.2 | V |
| VIN_ON | PVIN turn-on voltage | PVIN rising, register (35h) VIN_ON = 03h, V _{VCC} = Internal LDO | 3.6 | 3.8 | 4.0 | V |
| VIN_OFF | PVIN turn-off voltage | PVIN falling, register (36h) VIN_OFF = 00h | 4.0 | 4.2 | 4.4 | V |
| VIN_OFF | PVIN turn-off voltage | PVIN falling, register (36h) VIN_OFF = 01h | 9.1 | 9.5 | 9.8 | V |
| VIN_OFF | PVIN turn-off voltage ⁽¹⁾ | PVIN falling, register (36h) VIN_OFF = 02h | | 8.5 | | V |
| VIN_OFF | PVIN turn-off voltage ⁽¹⁾ | PVIN falling, register (36h) VIN_OFF = 03h | | 7.5 | | V |
| VIN_OFF | PVIN turn-off voltage ⁽¹⁾ | PVIN falling, register (36h) VIN_OFF = 04h | | 6.5 | | V |
| VIN_OFF | PVIN turn-off voltage ⁽¹⁾ | PVIN falling, register (36h) VIN_OFF = 05h | | 5.5 | | V |
| VIN_OFF | PVIN turn-off voltage | PVIN falling, register (36h) VIN_OFF = 06h | 4.0 | 4.2 | 4.4 | V |



| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------------|---------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------|-------|------|------|-------|
| VIN_OFF | PVIN turn-off voltage | PVIN falling, register (36h) VIN_OFF = 07h, V_{VCC} = Internal LDO | 3.2 | 3.4 | 3.6 | V |
| PVIN _{UVLO(R)} | PVIN UVLO rising threshold | PVIN rising, external 5 V bias on VCC/ VDRV pin | 2.35 | 2.55 | 2.75 | V |
| PVIN _{UVLO(F)} | PVIN UVLO falling threshold | PVIN falling, external 5 V bias on VCC/ VDRV pin | 2.10 | 2.30 | 2.50 | V |
| PVIN _{UVLO(H)} | PVIN UVLO hysteresis | | | 0.25 | | V |
| ENABLE | 1 | | | | I | |
| V _{EN(R)} | EN voltage rising threshold | EN rising, enable switching | 1.14 | 1.19 | 1.24 | V |
| V _{EN(F)} | EN voltage falling threshold | EN falling, disable switching | 0.94 | 0.98 | 1.02 | V |
| V _{EN(H)} | EN voltage hysteresis | | | 0.21 | | V |
| t _{EN(DIG)} | EN Deglitch Time | | 0.2 | | | μs |
| | EN internal pulldown resistor | V _{EN} = 2 V, EN pin to AGND | 110 | 125 | 140 | kΩ |
| INTERNAL VCC | LDO | | | | 1 | |
| t _{delay(uvlo_l2C)} | Delay from VCC_OK to I ² C ready to communicate ⁽¹⁾ | VCC/VDRV >= 3 V | | 300 | | μs |
| | Internal VCC LDO output voltage | PVIN= 4 V, I _{VCC(load)} = 5 mA | 3.925 | 3.97 | 4.0 | V |
| | Internal VCC LDO output voltage | PVIN= 5 V to 16 V, I _{VCC(load)} = 5 mA | 4.28 | 4.44 | 4.55 | V |
| | VCC_OK rising threshold | $T_J = -40^{\circ}$ C to 85°C. VCC rising, enabling initial power-on including digital communication | 3.0 | 3.15 | 3.3 | V |
| | VCC_OK falling threshold | $T_J = -40^{\circ}$ C to 85°C. VCC falling, disabling controller circuit including digital communication | 2.95 | 3.10 | 3.25 | V |
| | VCC LDO dropout voltage | PVIN – V _{VCC} , PVIN = 4 V, I _{VCC(load)} = 50 mA | | 184 | 300 | mV |
| | VCC LDO short-circuit current limit | | 150 | | | mA |
| VOUT VOLTAGE | | 1 | | | | |
| | Output Voltage controlled through SVID interface | Output voltage range by SetVID & SetWP commands | 0.5 | | 3.04 | V |
| | Output Voltage controlled through SVID interface | Output voltage resolution by SetVID & SetWP commands | | 5 | | mV |
| | Output Voltage controlled through SVID interface | SVID fast slew rate, register (AFh) DVS_CFG = 02h | 2.5 | 2.78 | 3.06 | mV/µs |
| | Output Voltage controlled through SVID interface | SVID fast slew rate, register (AFh) DVS_CFG = 04h | 5 | 5.5 | 6.1 | mV/µ |
| | Output Voltage controlled through SVID interface | SVID fast slew rate, register (AFh) DVS_CFG = 06h | 10 | 11.1 | 12.2 | mV/με |
| | Output Voltage controlled through SVID interface | SVID OFFSET range | -128 | | 127 | Step |
| | Output Voltage controlled through SVID interface | SVID OFFSET resolution | | 1 | | Step |
| | Output Voltage controlled through I ² C interface | Output voltage range by register (A6h) VOUT_CMD | 0.5 | | 3.04 | V |
| | Output Voltage controlled through I ² C interface | Output voltage resolution by register (A6h) VOUT_CMD | | 5 | | mV |
| | Output Voltage controlled through I ² C interface | Output voltage transition slew rate by register (A6h) VOUT_CMD, register (AFh) DVS_CFG = 02h | 0.625 | | | mV/µ |
| | Output Voltage controlled through I ² C interface | Output voltage transition slew rate by register (A6h) VOUT_CMD, register (AFh) DVS_CFG = 04h | 1.25 | | | mV/µs |
| | Output Voltage controlled through I ² C interface | Output voltage transition slew rate by register (A6h) VOUT_CMD, register (AFh) DVS_CFG = 06h | 2.5 | | | mV/µs |
| | Output Voltage controlled through I ² C interface | I ² C offset (register A8h) range, V _{OUT} step = 5 mV | -64 | | 63 | mV |



| | PARAMETER | TEST CONDITIONS | MIN | ТҮР | MAX | UNIT |
|-----------------------|--------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|------|--------|------|
| | Output Voltage controlled through I ² C interface | I ² C offset (register A8h) resolution, V _{OUT} step = 5 mV | | 0.5 | | mV |
| | Output Voltage controlled through I ² C interface | I ² C offset (register A8h) range, V _{OUT} step = 10 mV | -128 | | 127 | mV |
| | Output Voltage controlled through I ² C interface | I ² C offset (register A8h) resolution, V _{OUT} step = 5 mV | | 1.0 | | mV |
| V _{OUT(ACC)} | Output voltage accuracy | T _J = 0°C to 85°C, V _{OUT_Setting} = 0.75 V, V _{VOSNS} -V _{GOSNS} | 0.7425 | 0.75 | 0.7575 | V |
| V _{OUT(ACC)} | Output voltage accuracy | T _J = 0°C to 85°C, V _{OUT_Setting} = 1.1 V, V _{VOSNS} -V _{GOSNS} | 1.0945 | 1.1 | 1.1055 | V |
| V _{OUT(ACC)} | Output voltage accuracy | T _J = 0°C to 85°C, V _{OUT_Setting} = 1.8 V, V _{VOSNS} -V _{GOSNS} | 1.791 | 1.8 | 1.809 | V |
| V _{OUT(ACC)} | Output voltage accuracy | $T_J = -40^{\circ}$ C to 125°C, $V_{OUT_Setting} = 0.75$ V, $V_{VOSNS} = V_{GOSNS}$ | 0.739 | 0.75 | 0.761 | V |
| V _{OUT(ACC)} | Output voltage accuracy | $T_J = -40^{\circ}$ C to 125°C, $V_{OUT_Setting} = 1.1$ V, V _{VOSNS} -V _{GOSNS} | 1.089 | 1.1 | 1.111 | V |
| V _{OUT(ACC)} | Output voltage accuracy | $T_J = -40^{\circ}$ C to 125°C, $V_{OUT_Setting} = 1.8$ V, $V_{VOSNS} - V_{GOSNS}$ | 1.782 | 1.8 | 1.818 | V |
| I _{VOS} | VOSNS input current | V _{VOSNS} = 1.8 V | | 120 | 130 | μA |
| SWITCHING FR | EQUENCY | | | | | |
| f _{SW(FCCM)} | Switching frequency, FCCM operation | $T_J = -40^{\circ}$ C to 125°C, PVIN = 12 V, V _{OUT} = 1.1 V, no load, register (33h) FREQUENCY_SWITCH = 00h | 510 | 600 | 660 | kHz |
| f _{SW(FCCM)} | Switching frequency, FCCM operation | $ \begin{array}{l} T_J = -40^\circ C \text{ to } 125^\circ C, \mbox{ PVIN} = 12 \ V, \\ V_{OUT} = 1.1 \ V, \ no \ load, \ register \ (33h) \\ FREQUENCY_SWITCH = 01h \end{array} $ | 680 | 800 | 920 | kHz |
| f _{SW(FCCM)} | Switching frequency, FCCM operation | $ \begin{array}{l} T_J = -40^\circ C \mbox{ to } 125^\circ C, \mbox{ PVIN} = 12 \mbox{ V}, \\ V_{OUT} = 1.1 \mbox{ V}, \mbox{ no load, register (33h)} \\ FREQUENCY_SWITCH = 02h \end{array} $ | 850 | 1000 | 1150 | kHz |
| f _{SW(FCCM)} | Switching frequency, FCCM operation | $T_{J} = -40^{\circ}C \text{ to } 125^{\circ}C, PVIN = 12 \text{ V},$ $V_{OUT} = 1.1 \text{ V}, \text{ no load, register (33h)}$ FREQUENCY_SWITCH = 03h | 1020 | 1200 | 1440 | kHz |
| STARTUP | | | | | | |
| t _{ON(DLY)} | Power on sequence delay | V _{VCC} = 4.5 V, register (60h) TON_DELAY = 00h | | 0.5 | 0.55 | ms |
| t _{ON(DLY)} | Power on sequence delay | V _{VCC} = 4.5 V, register (60h) TON_DELAY = 01h | | 1.0 | 1.1 | ms |
| t _{ON(DLY)} | Power on sequence delay | V _{VCC} = 4.5 V, register (60h) TON_DELAY = 02h | | 1.5 | 1.65 | ms |
| t _{ON(DLY)} | Power on sequence delay | V _{VCC} = 4.5 V, register (60h) TON_DELAY = 03h | | 2.0 | 2.2 | ms |
| t _{OFF(DLY)} | Power off sequence delay | V _{VCC} = 4.5 V, register (64h) TOFF_DELAY = 00h | | 0 | 0.02 | ms |
| t _{OFF(DLY)} | Power off sequence delay | V _{VCC} = 4.5 V, register (64h) TOFF_DELAY = 01h | | 1.0 | 1.1 | ms |
| t _{OFF(DLY)} | Power off sequence delay | V _{VCC} = 4.5 V, register (64h) TOFF_DELAY = 02h | | 1.5 | 1.65 | ms |
| t _{OFF(DLY)} | Power off sequence delay | V _{VCC} = 4.5 V, register (64h) TOFF_DELAY = 03h | | 2.0 | 2.2 | ms |
| t _{ON(Rise)} | Soft-start time | V _{VCC} = 4.5 V, register (61h) TON_RISE = 00h | | 1.0 | 1.1 | ms |
| t _{ON(Rise)} | Soft-start time | V _{VCC} = 4.5 V, register (61h) TON_RISE = 01h | | 2.0 | 2.2 | ms |
| t _{ON(Rise)} | Soft-start time | V _{VCC} = 4.5 V, register (61h) TON_RISE = 02h | | 4.0 | 4.4 | ms |
| t _{ON(Rise)} | Soft-start time | V _{VCC} = 4.5 V, register (61h) TON_RISE = 03h | | 8.0 | 8.8 | ms |



| | PARAMETER | TEST CONDITIONS | MIN TYP MAX | UNIT |
|------------------------|--------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------|-------------|------|
| t _{ON(Rise)} | Soft-start time | V _{VCC} = 4.5 V, register (61h) TON_RISE = 04h to 07h | 16.0 17.6 | ms |
| t _{OFF(Fall)} | Soft-stop slew rate, V _{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 00h, Vboot = 1.1V, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 2.2 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 01h, Vboot = 1.1V, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 1.1 | V/ms |
| tOFF(Fall) | Soft-stop slew rate, V _{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 02h, Vboot = 1.1V, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 0.55 | V/ms |
| tOFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 03h, Vboot = 1.1V, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 0.275 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 00h, Vboot = 1.8V, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 3.6 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 01h, Vboot = 1.8V, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 1.8 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 02h, Vboot = 1.8V, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 0.9 | V/ms |
| ^t OFF(Fall) | Soft-stop slew rate, V _{OUT} controlled by SVID | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 03h, Vboot = 1.8V, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 0.45 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by I^2C | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 00h, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 2.2 | V/ms |
| t OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by I ² C | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 01h, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 1.1 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by I^2C | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 02h, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 0.55 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by I ² C | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 03h, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 0.275 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by I^2C | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 00h, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 3.6 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by I^2C | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 01h, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 1.8 | V/ms |
| OFF(Fall) | Soft-stop slew rate, V_{OUT} controlled by $\mathrm{I}^{2}\mathrm{C}$ | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 02h, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 0.9 | V/ms |
| OFF(Fall) | Soft-stop slew rate, $V_{\mbox{OUT}}$ controlled by $\mbox{I}^2\mbox{C}$ | V _{VCC} = 4.5 V, register (65h) TOFF_FALL = 03h, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 0.45 | V/ms |
| POWER STAGE | | | | |
| RDSON(HS) | High-side MOSFET on-resistance | T _J = 25°C, PVIN = 12 V, V _{BOOT-SW} = 4.5 V | 4 | mΩ |
| R _{DSON(HS)} | High-side MOSFET on-resistance | T _J = 25°C, PVIN = 12 V, V _{BOOT-SW} = 5.0 V | 3.91 | mΩ |
| R _{DSON(LS)} | Low-side MOSFET on-resistance | T _J = 25°C, PVIN = 12 V, V _{VCC} = 4.5 V | 1 | mΩ |
| R _{DSON(LS)} | Low-side MOSFET on-resistance | T _J = 25°C, PVIN = 12 V, V _{VCC} = 5 V | 0.98 | mΩ |
| t _{ON(min)} | Minimum ON pulse width | V _{VCC} = 4.5 V | 60 | ns |
| | 1 | V _{VCC} = 4.5 V, I _O =1.5A, V _{VOSNS} = V _{OUT} Setting | 210 250 | |



| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------|----------------------------------------------------|------------------------------------------------------------------------------------------------------|-------|-------|------|------|
| I _{BOOT(LKG)} | BOOT leakage current | V _{EN} = 2 V, V _{BOOT-SW} = 5 V | | | 150 | μA |
| V _{BOOT-SW(UV_F)} | BOOT-SW UVLO falling threshold | | 2.60 | 2.76 | | V |
| OVERCURRENT L | IMIT | | | | | |
| I _{LS(OC)} | Low-side valley overcurrent limit | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 00h | 8.5 | 10 | 11.5 | A |
| I _{LS(OC)} | Low-side valley overcurrent limit ⁽¹⁾ | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 01h | 10.2 | 12 | 13.8 | А |
| I _{LS(OC)} | Low-side valley overcurrent limit | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 02h | 13.5 | 15 | 16.5 | А |
| I _{LS(OC)} | Low-side valley overcurrent limit ⁽¹⁾ | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 03h | 17.1 | 19 | 20.9 | А |
| I _{LS(OC)} | Low-side valley overcurrent limit | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 04h | 18 | 20 | 22 | А |
| I _{LS(OCL)} | Low-side valley overcurrent limit | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 05h | 22.5 | 25 | 27.5 | A |
| I _{LS(OCL)} | Low-side valley overcurrent limit ⁽¹⁾ | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 06h | 23.4 | 26 | 28.6 | A |
| I _{LS(OCL)} | Low-side valley overcurrent limit | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 07h | 27 | 30 | 33 | А |
| I _{LS(OCL)} | Low-side valley overcurrent limit ⁽¹⁾ | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 08h | 29.7 | 33 | 36.3 | A |
| I _{LS(OCL)} | Low-side valley overcurrent limit | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 09h | 31.5 | 35 | 38.5 | А |
| I _{LS(OCL)} | Low-side valley overcurrent limit ⁽¹⁾ | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 0Ah | 35.1 | 39 | 42.9 | А |
| I _{LS(OCL)} | Low-side valley overcurrent limit | Valley current limit on LS FET, register (46h) IOUT_OC_FAULT_LIMIT = 0Bh to 0Fh | 36 | 40 | 44 | А |
| I _{LS(NOC)} | Low-side negative overcurrent limit | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 00h, I _{CCMAX} ≥ 15A | -24 | -21 | -18 | A |
| I _{LS(NOC)} | Low-side negative overcurrent limit | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 01h, I _{CCMAX} ≥ 15A | -18 | -16 | -14 | A |
| I _{LS(NOC)} | Low-side negative overcurrent limit | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 02h, I _{CCMAX} ≥ 15A | -14.5 | -12.8 | -11 | A |
| I _{LS(NOC)} | Low-side negative overcurrent limit | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 03h, I _{CCMAX} ≥ 15A | -12.5 | -10.8 | -9 | A |
| I _{LS(NOC)} | Low-side negative overcurrent limit ⁽¹⁾ | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 00h, $I_{CCMAX} \le 10$ A | -14 | -11.3 | -9 | A |
| Ils(NOC) | Low-side negative overcurrent limit ⁽¹⁾ | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 01h, $I_{CCMAX} \le 10$ A | -12 | -8.7 | -6 | A |
| I _{LS(NOC)} | Low-side negative overcurrent limit ⁽¹⁾ | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 02h, $I_{CCMAX} \le 10$ A | -10 | -7.2 | -4.5 | A |
| LS(NOC) | Low-side negative overcurrent limit (1) | Sinking current limit on LS FET, register (B4h) IOUT_NOC_LIMIT = 03h, $I_{CCMAX} \le 10$ A | -8.5 | -6.2 | -3.9 | A |
| Izc | Zero-cross detection current threshold | ZC comparator threshold, enter DCM. PVIN = 12 V, V_{VCC} = 4.5 V, | | 900 | | mA |
| | Response delay before entering Hiccup | UVF RESPONSE_DELAY = 00b | | 2 | 4 | μs |
| | Response delay before entering Hiccup | UVF RESPONSE_DELAY = 01b | | 16 | 20 | μs |
| | Response delay before entering Hiccup | UVF RESPONSE_DELAY = 10b | | 64 | 80 | μs |
| | Response delay before entering Hiccup | UVF RESPONSE_DELAY = 11b | | 256 | 320 | μs |
| | Hiccup sleep time before a restart | | 49 | 56 | 59 | ms |



| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------|---------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|-------|------|-------|------|
| OUTPUT OVP AI | ND UVP | | | | | |
| V _{OVF} | V _{OUT} tracking overvoltage fault (OVF) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (40h) VOUT_OV_FAULT_LIMIT = 00h | 80 | 100 | 120 | mV |
| V _{OVF} | V _{OUT} tracking overvoltage fault (OVF) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (40h) VOUT_OV_FAULT_LIMIT = 01h | 120 | 150 | 180 | mV |
| V _{OVF} | V _{OUT} tracking overvoltage fault (OVF) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (40h) VOUT_OV_FAULT_LIMIT = 02h | 160 | 200 | 240 | mV |
| V _{OVF} | V _{OUT} tracking overvoltage fault (OVF) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (40h) VOUT_OV_FAULT_LIMIT = 03h | 240 | 300 | 360 | mV |
| V _{ovw} | V _{OUT} tracking overvoltage warning (OVW) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (42h) VOUT_OV_WARN_LIMIT = 00h | 80 | 100 | 120 | mV |
| V _{ovw} | V _{OUT} tracking overvoltage warning (OVW) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (42h) VOUT_OV_WARN_LIMIT = 01h | 120 | 150 | 180 | mV |
| V _{ovw} | V _{OUT} tracking overvoltage warning (OVW) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (42h) VOUT_OV_WARN_LIMIT = 02h | 160 | 200 | 240 | mV |
| V _{ovw} | V _{OUT} tracking overvoltage warning (OVW) threshold, offset above V _{OUT} setting value | (VOSNS – GOSNS) rising. Register (42h) VOUT_OV_WARN_LIMIT = 03h | 240 | 300 | 360 | mV |
| V _{FixOVF} | V_{OUT} fixed OVF threshold, V_{OUT} step = 5 mV | (VOSNS – GOSNS) rising. SEL_FIX_OVF = 0b, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 1.425 | 1.5 | 1.575 | V |
| V _{FixOVF} | V_{OUT} fixed OVF threshold, V_{OUT} step = 5 mV | (VOSNS – GOSNS) rising. SEL_FIX_OVF = 1b, PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 1.71 | 1.8 | 1.89 | V |
| V _{FixOVF} | V_{OUT} fixed OVF threshold, V_{OUT} step = 10 mV | (VOSNS – GOSNS) rising. SEL_FIX_OVF = 0b, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 2.3 | 2.4 | 2.47 | V |
| V _{FixOVF} | V_{OUT} fixed OVF threshold, V_{OUT} step = 10 mV | (VOSNS – GOSNS) rising. SEL_FIX_OVF = 1b, PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 2.85 | 3.0 | 3.07 | V |
| V _{UVF} | V _{OUT} tracking undervoltage fault (UVF) threshold, offset below V _{OUT} setting value | (VOSNS – GOSNS) falling. Register (44h) VOUT_UV_FAULT_LIMIT = 00h | -180 | -150 | -120 | mV |
| V _{UVF} | V _{OUT} tracking undervoltage fault (UVF) threshold, offset below V _{OUT} setting value | (VOSNS – GOSNS) falling. Register (44h) VOUT_UV_FAULT_LIMIT = 01h | -240 | -200 | -160 | mV |
| V _{UVF} | V_{OUT} tracking undervoltage fault (UVF) threshold, offset below V_{OUT} setting value | (VOSNS – GOSNS) falling. Register (44h) VOUT_UV_FAULT_LIMIT = 02h | -240 | -200 | -160 | mV |
| V _{UVF} | V_{OUT} tracking undervoltage fault (UVF) threshold, offset below V_{OUT} setting value | (VOSNS – GOSNS) falling. Register (44h) VOUT_UV_FAULT_LIMIT = 03h | -360 | -300 | -240 | mV |
| V _{UVW} | V_{OUT} tracking undervoltage warning (UVW) threshold, offset below V_{OUT} setting value | (VOSNS – GOSNS) falling. Register (43h) VOUT_UV_WARN_LIMIT = 00h | -120 | -100 | -80 | mV |
| V _{UVW} | V_{OUT} tracking undervoltage warning (UVW) threshold, offset below V_{OUT} setting value | (VOSNS – GOSNS) falling. Register (43h) VOUT_UV_WARN_LIMIT = 01h | -180 | -150 | -120 | mV |
| V _{UVW} | V_{OUT} tracking undervoltage warning (UVW) threshold, offset below V_{OUT} setting value | (VOSNS – GOSNS) falling. Register (43h) VOUT_UV_WARN_LIMIT = 02h | -240 | -200 | -160 | mV |
| V _{UVW} | V_{OUT} tracking undervoltage warning (UVW) threshold, offset below V_{OUT} setting value | (VOSNS – GOSNS) falling. Register (43h) VOUT_UV_WARN_LIMIT = 03h | -360 | -300 | -240 | mV |
| | V _{OUT} tracking UVF response delay time | UVF RESPONSE_DELAY = 00b. From UVF detection to tri-state of the power FETs | | 2 | 4 | μs |
| | V _{OUT} tracking UVF response delay time | UVF RESPONSE_DELAY = 01b. From UVF detection to tri-state of the power FETs | | 16 | 20 | μs |
| | V _{OUT} tracking UVF response delay time | UVF RESPONSE_DELAY = 10b. From UVF detection to tri-state of the power FETs | | 64 | 80 | μs |
| | V _{OUT} tracking UVF response delay time | UVF RESPONSE_DELAY = 11b. From UVF detection to tri-state of the power FETs | | 256 | 320 | μs |
| VR READY AND | CATASTROPHIC FAULT | | | | | |
| V _{OL(VRRDY)} | VRRDY pin output low-level voltage | I _{VRRDY} = 10 mA, PVIN = 12 V, V _{VCC} = 4.5 V | | | 300 | mV |
| I _{LKG(VRRDY)} | VRRDY pin Leakage current when open drain output is high | R_{pullup} = 10 k Ω , V_{VRRDY} = 5 V | | | 5 | μA |



| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------|------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|---------|-------|------|
| | Minimum VCC for valid VRRDY pin output | PVIN = 0 V, V _{EN} = 0 V, R _{pullup} = 10 k Ω , V _{VRRDY} \leq 0.3 V | | | 1.2 | V |
| | CAT_FAULT# pin output low-level voltage | R_{pullup} = 4.99 kΩ, V_{pullup} = 3.3 V | | 210 | 300 | mV |
| | CAT_FAULT# pin Leakage current when open drain output is high | R_{pullup} = 4.99 kΩ, V_{pullup} = 3.3 V | | | 5 | μA |
| OUTPUT DISCH | ARGE | | | | | |
| | Output discharge on VOSNS pin | PVIN = 12 V, V _{VCC} = 4.5 V, V _{VOSNS} = 0.5 V, EN=0V | 1.15 | 1.47 | 1.85 | kΩ |
| THERMAL SHU | TDOWN | · · · · | | | | |
| T _{J(SD)} | Thermal shutdown (Analog OTP) threshold (1) | Junction temperature rising | 153 | 166 | | °C |
| T _{J(HYS)} | Thermal shutdown (Analog OTP) hysteresis | | | 30 | | °C |
| MEASUREMEN | T SYSTEM (I ² C) | | | | I | |
| M _{IOUT(rng)} | Output current measurement range | Register (C0h) ICC_MAX = 07h (40 A) | 0 | | 40 | А |
| M _{IOUT(acc)} | Output current measurement accuracy ⁽²⁾ | Register (C0h) ICC_MAX = 07h (40 A), $0 \le I_{OUT} \le 4 A$ | -0.7 | | 0.7 | А |
| M _{IOUT(acc)} | Output current measurement accuracy ⁽²⁾ | Register (C0h) ICC_MAX = 07h (40 A), I _{OUT} = 12 A | -8% | | 8% | |
| M _{IOUT(acc)} | Output current measurement accuracy ⁽²⁾ | Register (C0h) ICC_MAX = 07h (40 A), 24 A ≤ I _{OUT} < 40 A | -6% | | 6% | |
| M _{IOUT(Isb)} | Output current measurement bit resolution | Register (C0h) ICC_MAX = 07h (40 A) | | 0.15686 | | Α |
| M _{VOUT(rng)} | Output voltage measurement range | PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | 0 | | 1.6 | V |
| M _{VOUT(rng)} | Output voltage measurement range | PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | 0 | | 3.2 | V |
| M _{VOUT(acc)} | Output voltage measurement accuracy | $0.75 \text{ V} \le \text{VOUT} \le 1.52 \text{ V}, \text{ PROTOCOL_ID} =$ 01b or 10b (V _{OUT} step = 5 mV) | -18.75 | | 18.75 | mV |
| M _{VOUT(acc)} | Output voltage measurement accuracy | $0.75 \text{ V} \le \text{VOUT} \le 3.04 \text{ V}, \text{ PROTOCOL}_\text{ID} = 00b \text{ or } 11b (V_{\text{OUT}} \text{ step} = 10 \text{ mV})$ | -37.5 | | 37.5 | mV |
| M _{VOUT(Isb)} | Output voltage measurement bit resolution | PROTOCOL_ID = 01b or 10b (V _{OUT} step = 5 mV) | | 6.25 | | mV |
| $M_{VOUT(lsb)}$ | Output voltage measurement bit resolution | PROTOCOL_ID = 00b or 11b (V _{OUT} step = 10 mV) | | 12.5 | | mV |
| M _{PIN(rng)} | Input power measurement range | (6Bh) PIN_OP_WARN_LIMIT = 00h (510 W) | 0 | | 510 | W |
| M _{PIN(acc)} | Input power measurement accuracy ⁽³⁾ | $ \begin{array}{l} T_{J} = 25 \ ^\circ \!\!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!\!\!\!^\circ \!\!\!\!\!^\circ \!\!\!\!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!\!\!\!\!$ | | 174 | | W |
| M _{PIN(acc)} | Input power measurement accuracy ⁽³⁾ | $ \begin{array}{l} T_{J} = 25 \ ^\circ C, \ V_{IN} = 12 \ V, \ IIN = 20 \ A, \ register \\ (6Bh) \ PIN_OP_WARN_LIMIT = 03h \ (360 \\ W), \ register \ (B3h) \ PIN_SENSE_RES = 03h \\ (R_{SENSE} = 1.0 \ m\Omega, \ IIN_MAX = 40 \ A) \end{array} $ | | 233.4 | | W |
| MPIN(acc) | Input power measurement accuracy ⁽³⁾ | $ \begin{array}{l} T_{J} = 25 \ ^\circ \!\!\!\!^{C} \!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!$ | | 292.8 | | W |
| M _{PIN(acc)} | Input power measurement accuracy ⁽³⁾ | $ \begin{array}{l} T_{J} = 25 \ ^\circ \!\!\!\!\!^\circ \!\!\!\!\!\!\!^\circ \!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!$ | | 171 | | W |
| M _{PIN(acc)} | Input power measurement accuracy ⁽³⁾ | eq:starsessessessessessessessessessessessesses | | 230.4 | | W |



| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------|-----------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|---------|------|------|
| M _{PIN(acc)} | Input power measurement accuracy ⁽³⁾ | $ \begin{array}{l} T_J = 25 \ ^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!^\circ \!\!^\circ \!\!\!^\circ \!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!\!^\circ\!\!\!\!\!\!$ | | 289.8 | | W |
| M _{PIN(Isb)} | Input power measurement bit resolution | (6Bh) PIN_OP_WARN_LIMIT = 03h (360 W) | | 1.412 | | W |
| M _{VIN(rng)} | Input voltage measurement range | VINSNSM – PGND. READ_VIN reporting range | 8 | | 16 | V |
| M _{VIN(acc)} | Input voltage measurement accuracy | 10 V ≤ VINSNSM – PGND ≤ 14 V | -0.5% | | 0.5% | |
| M _{VIN(Isb)} | Input voltage measurement bit resolution | VINSNSM – PGND | | 31.25 | | mV |
| M _{IIN(rng)} | Input current measurement range | Register (B3h) PIN_SENSE_RES = 03h or 05h | 0 | | 40 | А |
| M _{IIN(acc)} | Input current measurement accuracy (3) | $ \begin{array}{l} T_J = 25 \ ^\circ C, \ V_{IN} = 12 \ V, \ IIN = 15 \ A, \ register \\ (B3h) \ PIN_SENSE_RES = 03h \ (R_{SENSE} = \\ 1.0 \ m\Omega, \ IIN_MAX = 40 \ A) \end{array} $ | | 14.5 | | A |
| M _{IIN(acc)} | Input current measurement accuracy (3) | $ \begin{array}{l} T_J = 25 \ ^\circ \!\!\!^\circ \!\!\!^\circ \!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!^\circ \!\!^\circ \!\!^\circ \!\!\!^\circ \!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!\!$ | | 19.45 | | A |
| M _{IIN(acc)} | Input current measurement accuracy ⁽³⁾ | $ \begin{array}{l} T_J = 25 \ ^\circ \!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!^\circ \!\!^\circ \!\!\!^\circ \!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!$ | | 24.4 | | A |
| M _{IIN(acc)} | Input current measurement accuracy (3) | $ \begin{array}{l} T_J = 25 \ ^\circ \!\!\!^\circ \!\!\!^\circ \!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!^\circ \!\!^\circ \!\!^\circ \!\!\!^\circ \!\!\!^\circ\!\!\!^\circ \!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!\!$ | | 14.25 | | A |
| M _{IIN(acc)} | Input current measurement accuracy (3) | $ \begin{array}{l} T_J = 25 \ ^\circ \!\!\!^\circ \!\!\!^\circ \!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!^\circ \!\!^\circ \!\!^\circ \!\!\!^\circ \!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!\!$ | | 19.2 | | A |
| M _{IIN(acc)} | Input current measurement accuracy (3) | $ \begin{array}{l} T_J = 25 \ ^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!\!^\circ \!\!\!\!^\circ \!\!\!\!^\circ \!\!\!^\circ \!\!^\circ \!\!^\circ \!\!\!^\circ \!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!^\circ\!\!\!\!\!$ | | 24.15 | | A |
| M _{IIN(Isb)} | Input current measurement bit resolution | | | 0.15625 | | А |
| M _{TSNS(rng)} | Internal temperature sense range | Temperature sensor on the Controller die | -40 | | 125 | °C |
| M _{TSNS(acc)} | Internal temperature sense accuracy | $-40^{\circ}C \le T_{J} \le 125^{\circ}C$ | -5 | | 5 | °C |
| M _{TSNS(lsb)} | Internal temperature sense bit resolution | | | 1 | | °C |
| SVID Timing and | Physical Characteristics | | | | | |
| C _{PAD_SVID} | SVID pin pad capacitance ⁽¹⁾ | | 0 | | 4 | pF |
| C _{PIN_SVID} | SVID pin capacitance ⁽¹⁾ | | 0 | | 5 | pF |
| V _{MAX_SVID} | VDS max open drain buffer to accommodate ringing on bus | | -1 | | 3.3 | V |
| VIL_SVID | SV_CLK, SV_DIO input low voltage | | 0.45 | 0.5 | 0.55 | V |
| VIH_SVID | SV_CLK, SV_DIO input high voltage | | 0.54 | 0.59 | 0.64 | V |
| V _{HYS_SVID} | SV_CLK, SV_DIO input voltage hysteresis | | 0.05 | | | V |
| R _{RSVIDL} | Open Drain Pulldown resistance | SV_DIO, SV_ALERT# pins pulldown resistance | 4 | 8 | 13 | Ω |
| I _{LKG_SVID} | Input leakage current | Pullup source = 5.5 V, off state | | | 20 | μA |
| D _{CLK_SVID} | SVID clock duty ratios (Period and duty cycle are measured with respect to 0.5 x VccIO) | | 0.4 | | 0.6 | |
| | VR Clock to Data delay without board parasitic | | | | 12 | ns |
| t _{SU_VR_SVID} | Setup time of data at VR side | | | | 7 | ns |
| t _{H_VR_SVID} | Hold time of data at VR side | | | | 14 | ns |
| t _{CO_CPU_SVID} | CPU Clock to Data delay | | -3.6 | | 0.65 | ns |
| t _{SU_CPU_SVID} | Setup time of data at CPU side | | | 1 | | ns |
| t _{H_CPU_SVID} | Hold time of data at CPU side | | | 3 | | ns |
| SR _{F_DATA} | Falling slew rate of SV_DIO ⁽¹⁾ | SV DIO from 0.735V to 0.315V, Rpu=64.9Ω | 1.2 | | 4 | V/ns |



 $T_J = -40^{\circ}$ C to +125°C. PVIN = 4 V to 16 V, V_{VCC} = 4.5 V to 5.0 V (unless otherwise noted). Typical values are at T_J = 25°C, PVIN = 12 V and V_{VCC} = 4.5 V.

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------|------------------------------------------------------------------------|--------------------------------------------------|-------|-------|-------|--------|
| SR _{R_DATA} | Rising slew rate of SV_DIO ⁽¹⁾ | SV_DIO from 0.315V to 0.735V, Rpu=64.9Ω | 1.1 | | 3.6 | V/ns |
| SR _{F_ALERT} | Falling slew rate of SV_ALERT# ⁽¹⁾ | SV_ALERT# from 0.735V to 0.315V, Rpu=75Ω | 1.25 | | 4.2 | V/ns |
| SR _{R_ALERT} | Rising slew rate of SV_ALERT# (1) | SV_ALERT# from 0.315V to 0.735V, Rpu=75 Ω | 1.15 | | 3.3 | V/ns |
| FREQ _{SVID} | Max SVID Clock frequency Support | | 43 | | | MHz |
| I ² C Timing and F | Physical Characteristics | | | | | |
| FREQ _{I2C} | I ² C operating frequency range | | 50 | | 1000 | kHz |
| V _{IH_I2C} | I ² C_SCL, I ² C_SDA High-level input voltage | | 0.535 | 0.585 | 0.635 | V |
| V _{IL_I2C} | I ² C_SCL, I ² C_SDA Low-level input voltage | | 0.465 | 0.515 | 0.565 | V |
| V _{HYS_I2C} | I ² C_SCL, I ² C_SDA Input voltage hysteresis | | 0.05 | | | V |
| N _{WRNVM} | Number of NVM writeable cycles ⁽¹⁾ | $-40^{\circ}C \le T_{J} \le 125^{\circ}C$ | 1000 | | | Cycles |
| C _{BUS_I2C} | I ² C bus capacitance on each bus line ⁽¹⁾ | | 0 | | 400 | pF |
| C _{PIN_I2C} | I ² C pin capacitance ⁽¹⁾ | | 0 | | 10 | pF |
| t _{H_STA} | Hold time for a (repeated) START condition | | 0.26 | | | μs |
| t _{LOW} | Low period of I ² C_SCL | | 0.5 | | | μs |
| t _{HIGH} | High period of I ² C_SCL | | 0.26 | | | μs |
| t _{SU_STA} | Setup time for a repeated START condition | | 0.26 | | | μs |
| t _{H_I2C} | I ² C DATA hold time | | 0 | | | μs |
| t _{SU_I2C} | I2C DATA setup time | | 50 | | | ns |
| | | 100 kHz class | | | 1000 | ns |
| t _{R_I2C} | I ² C_SCL and I ² C_SDA rise time ⁽¹⁾ | 400 kHz class | | | 300 | ns |
| | | 1000 kHz class | | | 120 | ns |
| | | 100 kHz class | | | 1000 | ns |
| t _{F_I2C} | I ² C_SCL and I ² C_SDA fall time ⁽¹⁾ | 400 kHz class | | | 300 | ns |
| | | 1000 kHz class | | | 120 | ns |
| t _{su_sто} | Setup time for a STOP condition | | 0.26 | | | μs |
| t _{BUF} | Bus free time between a STOP and START condition | | 0.5 | | | μs |

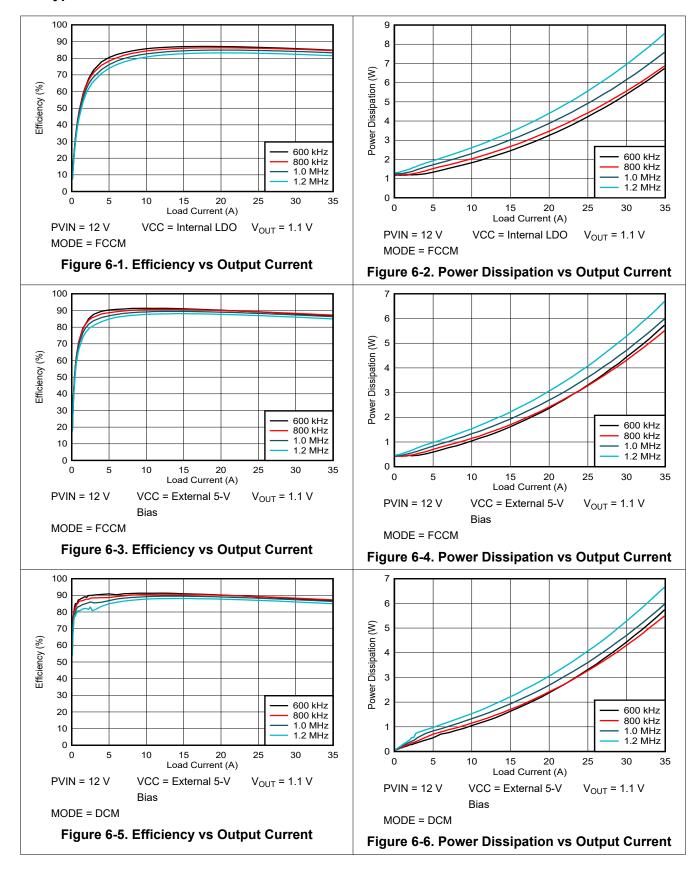
(1) These parameters are provided for reference only, and do not constitute part of TI's published device specifications for purpose of TI's product warranty.

(2) Accuracy can be improved by utilizing (A4h) IMON_CAL register.

(3) Accuracy can be improved by utilizing (A5h) IIN_CAL register.



6.6 Typical Characteristics



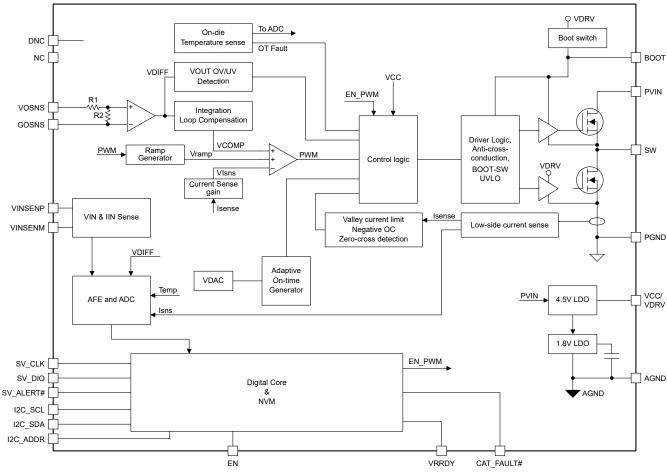


7 Detailed Description

7.1 Overview

The TPS544C26 device is highly integrated buck converter with D-CAP+ control topology for fast transient response and reduced output capacitance. All programmable parameters can be configured by the I2C interface and stored in NVM as the new default values to minimize the external component count. These features make the device well-suited for space-constrained applications. The TPS544C26 device is designed for low-to-mid current SVID rails in Intel's server and SoC CPUs. The TPS544C26 device with SVID and I2C interface feature can be configured for single phase CPU power rail.

Overcurrent, overvoltage, and undervoltage, Overtemperature protections are provided internally in the device. The TPS544C26 device offers a full set of telemetry features, including output voltage, output current, IC temperature, and input power monitoring through an external sensing resistor. TPS544C26 is a lead-free device and is RoHS compliant without exemption.



7.2 Functional Block Diagram

7.3 Feature Description

7.3.1 Internal VCC LDO and Using an External Bias on VCC/VDRV Pin

TPS544C26 device has an internal 4.5-V LDO featuring input from PVIN and output to VCC/VDRV pin. When the PVIN voltage rises, the internal LDO is enabled automatically and starts regulating LDO output voltage on the VCC/VDRV pin. The VCC voltage provides the bias voltage for the internal analog circuitry in controller side and the VDRV voltage provides the supply voltage for the power stage side.



A 2.2 μ F or 4.7 μ F, at least 6.3-V rating ceramic capacitor must be closely placed from VCC/VDRV pin to the PGND pin to decouple the noise generated by driver circuitry. Referring this decoupling capacitor to AGND introduces extra noise to the analog circuitry in the controller, which likely causes more noise on digital interface pins.

An external bias ranging 4.75 V to 5.30 V can be connect to VCC/VDRV pin and power the IC. This enhances the efficiency of the converter because the VCC and VDRV power supply current now runs off this external bias instead of the internal linear regulator.

A VDRV UVLO circuit monitors the VCC/VDRV pin voltage and disables the switching when VDRV falls below the VDRV UVLO falling threshold. Maintaining a stable and clean VCC/VDRV voltage is required for a smooth operation of the device.

Considerations when using an external bias on the VDRV and VCC pin are shown below:

- Connect the external bias to VCC/VDRV pin.
- When the external bias is applied on the VCC/VDRV pin earlier than PVIN rail, the internal LDO is be always forced off and the internal analog circuits have a stable power supply rail at their power enable.
- (Not recommended) When the external bias is applied on the VCC/VDRV pin late (for example, after PVIN rail ramp-up), any power-up and power-down sequencing can be applied as long as there is no excess current pulled out of the VCC/VDRV pin. Understand that an external discharge path on the VCC/VDRV pin, which can pull a current higher than the current limit of the internal LDO, can potentially turn off VCC LDO thereby shutting off the converter output.
- A good power-up sequence is: the external 5 V bias is applied first, then the 12 V bus is applied on PVIN, and then EN signal goes high.

7.3.2 Input Undervoltage Lockout (UVLO)

The TPS544C26 device provides four independent UVLO functions for the broadest range of flexibility in start-up control. While only the fixed VCC UVLO is required to enable I²C connectivity as well as PIN/IOUT/VOUT/ TEMPERATURE monitoring, all four UVLO functions must be met before switching can be enabled.

7.3.2.1 Fixed VCC_OK UVLO

The TPS544C26 device has an internally fixed UVLO of 3.15 V (typical) on VCC to enable the digital core and initiate power-on reset, including pin strap detection. The off-threshold on VCC is 3.1 V (typical). Once VCC level rises above 3.15 V (typical) and stays above 3.1 V (typical), the I²C communication is enabled.

7.3.2.2 Fixed VDRV UVLO

The TPS544C26 device has an internally fixed UVLO of 3.6 V (typical) on VDRV to enable drivers for power FETs and output voltage conversion. The off-threshold on VDRV is 3.4 V (typical).

7.3.2.3 Programmable PVIN UVLO

Two I2C commands ((35h) VIN_ON and (36h) VIN_OFF) allow the user to set PVIN voltage turn-on and turn-off thresholds independently.

The highest register data value on each command (*VIN_ON* = 11b or *VIN_OFF* = 111b) utilizes multiple UVLO circuitries (VCC, VDRV and PVIN UVLO) to enable or disable the power conversion. When *VIN_ON* = 11b is selected, both PVIN > 2.55 V and VCC > 3.8 V conditions have to be satisfied to enable the power conversion. When *VIN_OFF* = 111b is selected, either PVIN \leq 2.3 V or VDRV \leq 3.4 V disables the power conversion. This particular configuration together with an external 5 V bias on VCC/VDRV pin allows power conversion under low PVIN condition down to 2.7 V, as long as the external bias maintains at 5 V level to satify both the VCC rising threshold (3.8 V typical) and the VDRV falling threshold (3.4 V typical).

| PVIN_ON[1:0] | PVIN_ON Threshold (V) | |
|--------------|-----------------------|--|
| 00 | 10 | |
| 01 | 9 | |
| 10 | 8 | |

Table 7-1. PVIN ON Thresholds

| | Table 7-1. P | VIN ON | Thresholds | (continued) |) |
|--|--------------|--------|------------|-------------|---|
|--|--------------|--------|------------|-------------|---|

| PVIN_ON[1:0] | PVIN_ON Threshold (V) | | |
|--------------|----------------------------------------------------------------|--|--|
| 11 | ON threshold by both PVIN and VCC conditions. See (35h) VIN_ON | | |

| PVIN_OFF[2:0] | PVIN_OFF Threshold (V) |
|---------------|---------------------------------------------------------------------|
| 000 | 4.2 |
| 001 | 9.5 |
| 010 | 8.5 |
| 011 | 7.5 |
| 100 | 6.5 |
| 101 | 5.5 |
| 110 | 4.2 |
| 111 | ON threshold by both PVIN and VDRV conditions. See (36h) VIN_OFF |

Table 7-2. PVIN_OFF Thresholds

Note

If *VIN_OFF* is programmed higher than *VIN_ON*, the TPS544C26 device rapidly switches between enabled and disabled while PVIN remains below *VIN_OFF*. Please set (35h) VIN_ON threshold always greater than (36h) VIN_OFF threshold.

7.3.2.4 Enable

The TPS544C26 device offers precise enable, disable threshold on EN pin. The power stage switching is held off until EN pin voltage rises above the logic high threshold (typically 1.2 V). The power stage switching is turned off after EN pin voltage drops below the logic low threshold (typically 1 V).

EN pin has an internal filter to avoid unexpected ON or OFF due to short glitches. The deglitch time is set to 0.2 μ s.

The recommended operating condition for EN pin is up to 5.3 V and the absolute maximum rating is 5.5 V. DO NOT connect the EN pin to PVIN pin directly.

The TPS544C26 device remains disabled state when EN pin floats. EN pin is internally pulled down to AGND through a 121-k Ω resistor.

7.3.3 Differential Remote Sense and Internal Feedback Divider

The TPS544C26 includes a fully integrated, internal, precision feedback divider and remote sense. Using both the selectable feedback divider and precision adjustable reference, output voltages up to 3.04 V can be obtained. The feedback divider can be programmed to divider ratios of 1:2 or 1:4 using the *PROTOCOL_ID* in register (C2h) PROTOCOL_ID_SVID.

The recommended operating VOUT range is dependent upon the feedback divider ratio configured by *PROTOCOL_ID* as follows:

| VOUT_CTRL | VOUT Control Method | VOUT Step | Internal FB Divider Ratio | Recommended VOUT Range (V) |
|------------|-------------------------|-------------------------------------|------------------------------|-------------------------------|
| 00b | SVID only | | | |
| 01b | SVID + I ² C | 5 mV (PROTOCOL_ID = 01b or 10b) | 1:2 | 0.25 to 1.52 |
| 10b or 11b | I ² C only | , | | |
| 00b | SVID only | | 1:4 | |
| 01b | SVID + I ² C | 10 mV (PROTOCOL_ID = 00b or 11b) | | 0.5 to 3.04 |
| 10b or 11b | I ² C only | | | |

Table 7-3. VOUT Step and Recommended VOUT Range



Setting VOUT lower than the recommended range can negatively affect VOUT regulation accuracy. Setting VOUT above the recommended range is not achievable due to internal hardware limitation.

Note

Do not to use extra external divider to set VOUT higher than the recommended range. Using external divider leads to higher switching frequency than the desired value set in register (33h) FREQUENCY_SWITCH. The switching frequency shift varies depending on the delta between internal VOUT setting and the actual VOUT setting determined by the external divider. The more delta on internal vs external VOUT, the higher switching frequency shift.

The TPS544C26 device offers true differential remote sense function which is implemented between VOSNS pin and GOSNS pin. The output of the differential remote sense amplifier is internally fed into the control loop and doesn't come out to a package pin.

Differential remote sense function compensates a potential voltage drop on the PCB traces thus helps maintain VOUT accuracy under steady state operation and load transient event. Connecting the VOSNS pin and GOSNS pin to the remote location allows sensing the output voltage at a remote location. The connections from VOSNS pin and GOSNS pin to the remote location must be a pair of PCB traces with at least 12 mil trace width, and must implement Kelvin sensing across a high bypass capacitor of 0.1 μ F or higher. The ground connection of the remote sensing signal must be connected to GOSNS pin. The VOUT connection of the remote sensing signal must be connected to GOSNS pin. The VOUT connection of the remote sensing signal must be connected to VOSNS pin. To maintain stable output voltage and minimize the ripple, the pair of remote sensing lines must stay away from any noise sources such as inductor and SW node, or high frequency clock lines. It is recommended to shield the pair of remote sensing lines with ground planes above and below.

The recommended GOSNS operating range (refer to AGND pin) is −100 mV to +100 mV. In case of local sense (no remote sensing), short GOSNS pin to AGND.

7.3.4 Set the Output Voltage and VID Table

The TPS544C26 device offers VOUT adjustment through either SVID interface (for example, VID related SVID commands) or I2C interface (for example, (A6h) VOUT_CMD register). To allow flexibility and also avoid conflict, the device utilizes VOUT_CTRL[1:0] bits in register (A0h) SYS_CFG_USER1 to select which interface or method controls the VOUT level during the soft-start and nominal operation target. Table 7-4 describes more details.

The VOUT_CTRL value is latched after the power conversion is enabled (EN=high). While the device is enabled, a write to VOUT_CTRL bits are acknowledged but the VOUT control method does not change until an EN toggle happens.

| | VOUT Start-up Nominal Operation | | | | | | |
|---------------|---------------------------------|-------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------|-------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| VOUT_ CTRL | Control Method | VOUT | VOUT Offset | VOUT | VOUT Offset | Maximum VOUT Limit | Further Restrictions |
| 00b | SVID only | Set by Vboot in I ² C register (C2h) PROTOCOL_ID_ SVID | Set by SVID register (33h) OFFSET. This offset is always zero before EN=high | Set by SVID commands (such as SetVID, SetWP) | Set by SVID register (33h) OFFSET | SVID register 09h-0Ah VIDoMAX | I ² C register (A6h) VOUT_CMD is always ignored (ACK response for a write but does nothing). I ² C register (A8h) I2C_OFFSET is de- activated (NACK response for a write) |
| 01Ь | SVID + I ² C | Set by Vboot in I ² C register (C2h) PROTOCOL_ID_ SVID | Set by I ² C register (A8h) I ² C_OFFSET | Set by SVID commands (such as SetVID, SetWP) | Set by I ² C register (A8h) I ² C_OFFSET. A new I ² C_OFFSET value does not take effect immediately. Instead, the new value takes effect on the next start- up | SVID register 09h-0Ah VIDoMAX | I ² C register (A6h) VOUT_CMD is always ignored (ACK response for a write but does nothing). SVID register (33h) OFFSET is ignored (ACK response for a write but does nothing) |

Table 7-4. VOUT Control Method

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| | Table 7-4. VOUT Control Method (continued) | | | | | | | |
|---------------|--------------------------------------------|-------------------------------------------------------|----------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------|-------------|--------------|----------------------------------------------------------------------------------------------------------------------------------------|--|
| VOUT | VOUT | | t-up | Nominal | Operation | Maximum VOUT | | |
| CTRL | Control Method | VOUT | VOUT VOUT Offset VOUT VOUT Offset | | VOUT Offset | Limit | Further Restrictions | |
| 10b or 11b | I ² C only | Set by I ² C register (A6h) VOUT_CMD | Set by I ² C register (A8h) I ² C_OFFSET | Set by I ² C register (A6h) VOUT_CMD. A new VOUT_CMD value takes effect immediately. | | 17E in hex | SVID SetVID/SetWP command and SVID register (33h) OFFSET are always ignored (ACK response for a write but does nothing) | |

With VOUT_CTRL[1:0] = 00b or 01b (VOUT controlled by SVID), the initial output voltage can be set by the *Vboot* during initial power up, with the range from 0.75 V to 1.8 V (see Table 7-5). Vboot value can be adjusted through a write into the Vboot filed in I²C register (C2h) PROTOCOL_ID_SVID. Upon the acknowledge of the I²C write, the new Vboot value is automatically copied into SVID (26h) Vboot register. With a successful I²C (15h) STORE_USER_ALL command, this new value is saved into NVM. During next power-on sequence, TPS544C26 loads the saved Vboot value from NVM into both I²C Vboot field and SVID (26h) Vboot register. Once the soft-start ramp finishes, the output voltage can be changed by sending SetVID or SetWP command to the device, or sending a new SVID OFFSET value to the device.

With VOUT_CTRL[1:0] = 10b or 11b (VOUT controlled by I^2C), the initial output voltage can be set by the register (*A6h*) VOUT_CMD during initial power up. The available VOUT_CMD range is 0.25 V to 1.52 V for PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV), and 0.50 V to 3.04 V for PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV). Once the soft-start ramp finishes, the output voltage can be changed by sending new value to I^2C register (A6h) VOUT_CMD, or sending a new (A8h) I^2C_OFFSET value to the device. Upon the acknowledge of a I^2C write into I^2C register (A6h) VOUT_CMD or (A8h) I^2C_OFFSET , the new value takes effect immediately. With a successful I^2C (15h) STORE_USER_ALL command, this new value is saved into NVM. During next power-on sequence, TPS544C26 loads the saved value from NVM and use that value for the soft-start.

| Vboot in (C2h) PROTOCOL_ID_SVID | VID code ¹ (Hex) | Vboot (V) | PROTOCOL_ID in (C2h) PROTOCOL_ID_SVID |
|------------------------------------|-----------------------------|-----------|----------------------------------------------------------|
| 0000b | 00h | 0 | |
| 0001b | 65h | 0.75 | |
| 0010b | 6Fh | 0.80 | |
| 0011b | 79h | 0.85 | |
| 0100b | 83h | 0.90 | |
| 0101b | 8Dh | 0.95 | |
| 0110b | 97h | 1.00 | Must set PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV) |
| 0111b | A1h | 1.05 | |
| 1000b | ABh | 1.10 | |
| 1001b | AFh | 1.20 | |
| 1010b | C9h | 1.25 | |
| 1011b | DDh | 1.35 | |
| 1100b | FBh | 1.50 | |
| 1101b | 6Fh | 1.60 | |
| 1110b | 79h | 1.70 | Must set PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV) |
| 1111b | 83h | 1.80 | |

Table 7-5. Vboot Settings

1. VID code is not directly visiable to customer but shows up in I2C register (A7h) VID_SETTING and SVID register (31h) VID_SETTING.



TPS544C26 always follows below VID table when setting output voltage, no matter through SVID interface or I²C interface. When setting output voltage, aligning the VOUT value with PROTOCOL_ID (5 mV or 10 mV) accordantly is important. An incorrect selection on the VOUT and PROTOCOL_ID value can result in a NACK response for the write into (C2h) PROTOCOL_ID_SVID register. For example, a configuration of Vboot = 1.8 V and PROTOCOL_ID = 01b (VOUT step 5 mV) results in a NACK response. Another example with VOUT_CTRL[1:0] = 10b or 11b (VOUT controlled by I²C), setting VOUT_CMD to 2.5 V requires PROTOCOL_ID = 00b or 11b (VOUT step 10 mV) and thus requires Vboot to be one of the 3 options of 1.6 V, 1.7 V and 1.8 V. Even the Vboot value does not affect VOUT level for VOUT_CTRL[1:0] = 10b or 11b selection, a suitable Vboot value is needed to pass the error check on Vboot and PROTOCOL_ID fields.

| | | | | | | ···· | | | | | |
|-------------------|--------------------------|---------------------------|-------------------|--------------------------|---------------------------|-------------------|--------------------------|---------------------------|-------------------|--------------------------|---------------------------|
| VID code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step | VID Code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step | VID Code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step | VID Code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step |
| 00 | 0.000 | 0.00 | 40 | 0.565 | 1.13 | 80 | 0.885 | 1.77 | C0 | 1.205 | 2.41 |
| 01 | 0.250 | 0.50 | 41 | 0.570 | 1.14 | 81 | 0.890 | 1.78 | C1 | 1.210 | 2.42 |
| 02 | 0.255 | 0.51 | 42 | 0.575 | 1.15 | 82 | 0.895 | 1.79 | C2 | 1.215 | 2.43 |
| 03 | 0.260 | 0.52 | 43 | 0.580 | 1.16 | 83 | 0.900 | 1.80 | C3 | 1.220 | 2.44 |
| 04 | 0.265 | 0.53 | 44 | 0.585 | 1.17 | 84 | 0.905 | 1.81 | C4 | 1.225 | 2.45 |
| 05 | 0.270 | 0.54 | 45 | 0.590 | 1.18 | 85 | 0.910 | 1.82 | C5 | 1.230 | 2.46 |
| 06 | 0.275 | 0.55 | 46 | 0.595 | 1.19 | 86 | 0.915 | 1.83 | C6 | 1.235 | 2.47 |
| 07 | 0.280 | 0.56 | 47 | 0.600 | 1.20 | 87 | 0.920 | 1.84 | C7 | 1.240 | 2.48 |
| 08 | 0.285 | 0.57 | 48 | 0.605 | 1.21 | 88 | 0.925 | 1.85 | C8 | 1.245 | 2.49 |
| 09 | 0.290 | 0.58 | 49 | 0.610 | 1.22 | 89 | 0.930 | 1.86 | C9 | 1.250 | 2.50 |
| 0A | 0.295 | 0.59 | 4A | 0.615 | 1.23 | 8A | 0.935 | 1.87 | CA | 1.255 | 2.51 |
| 0B | 0.300 | 0.60 | 4B | 0.620 | 1.24 | 8B | 0.940 | 1.88 | СВ | 1.260 | 2.52 |
| 0C | 0.305 | 0.61 | 4C | 0.625 | 1.25 | 8C | 0.945 | 1.89 | CC | 1.265 | 2.53 |
| 0D | 0.310 | 0.62 | 4D | 0.630 | 1.26 | 8D | 0.950 | 1.90 | CD | 1.270 | 2.54 |
| 0E | 0.315 | 0.63 | 4E | 0.635 | 1.27 | 8E | 0.955 | 1.91 | CE | 1.275 | 2.55 |
| 0F | 0.320 | 0.64 | 4F | 0.640 | 1.28 | 8F | 0.960 | 1.92 | CF | 1.280 | 2.56 |
| 10 | 0.325 | 0.65 | 50 | 0.645 | 1.29 | 90 | 0.965 | 1.93 | D0 | 1.285 | 2.57 |
| 11 | 0.330 | 0.66 | 51 | 0.650 | 1.30 | 91 | 0.970 | 1.94 | D1 | 1.290 | 2.58 |
| 12 | 0.335 | 0.67 | 52 | 0.655 | 1.31 | 92 | 0.975 | 1.95 | D2 | 1.295 | 2.59 |
| 13 | 0.340 | 0.68 | 53 | 0.660 | 1.32 | 93 | 0.980 | 1.96 | D3 | 1.300 | 2.60 |
| 14 | 0.345 | 0.69 | 54 | 0.665 | 1.33 | 94 | 0.985 | 1.97 | D4 | 1.305 | 2.61 |
| 15 | 0.350 | 0.70 | 55 | 0.670 | 1.34 | 95 | 0.990 | 1.98 | D5 | 1.310 | 2.62 |
| 16 | 0.355 | 0.71 | 56 | 0.675 | 1.35 | 96 | 0.995 | 1.99 | D6 | 1.315 | 2.63 |
| 17 | 0.360 | 0.72 | 57 | 0.680 | 1.36 | 97 | 1.000 | 2.00 | D7 | 1.320 | 2.64 |
| 18 | 0.365 | 0.73 | 58 | 0.685 | 1.37 | 98 | 1.005 | 2.01 | D8 | 1.325 | 2.65 |
| 19 | 0.370 | 0.74 | 59 | 0.690 | 1.38 | 99 | 1.010 | 2.02 | D9 | 1.330 | 2.66 |
| 1A | 0.375 | 0.75 | 5A | 0.695 | 1.39 | 9A | 1.015 | 2.03 | DA | 1.335 | 2.67 |
| 1B | 0.380 | 0.76 | 5B | 0.700 | 1.40 | 9B | 1.020 | 2.04 | DB | 1.340 | 2.68 |
| 1C | 0.385 | 0.77 | 5C | 0.705 | 1.41 | 9C | 1.025 | 2.05 | DC | 1.345 | 2.69 |
| 1D | 0.390 | 0.78 | 5D | 0.710 | 1.42 | 9D | 1.030 | 2.06 | DD | 1.350 | 2.70 |
| 1E | 0.395 | 0.79 | 5E | 0.715 | 1.43 | 9E | 1.035 | 2.07 | DE | 1.355 | 2.71 |
| 1F | 0.400 | 0.80 | 5F | 0.720 | 1.44 | 9F | 1.040 | 2.08 | DF | 1.360 | 2.72 |
| 20 | 0.405 | 0.81 | 60 | 0.725 | 1.45 | A0 | 1.045 | 2.09 | E0 | 1.365 | 2.73 |
| 21 | 0.410 | 0.82 | 61 | 0.730 | 1.46 | A1 | 1.050 | 2.10 | E1 | 1.370 | 2.74 |
| 22 | 0.415 | 0.83 | 62 | 0.735 | 1.47 | A2 | 1.055 | 2.11 | E2 | 1.375 | 2.75 |

Table 7-6. VID Table for Output Voltage

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| | Table 7-6. VID Table for Output Voltage (continued) | | | | | | | | | | |
|-------------------|-----------------------------------------------------|---------------------------|-------------------|--------------------------|---------------------------|-------------------|--------------------------|---------------------------|-------------------|--------------------------|---------------------------|
| VID code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step | VID Code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step | VID Code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step | VID Code (Hex) | VOUT (V) 5-mV Step | VOUT (V) 10-mV Step |
| 23 | 0.420 | 0.84 | 63 | 0.740 | 1.48 | A3 | 1.060 | 2.12 | E3 | 1.380 | 2.76 |
| 24 | 0.425 | 0.85 | 64 | 0.745 | 1.49 | A4 | 1.065 | 2.13 | E4 | 1.385 | 2.77 |
| 25 | 0.430 | 0.86 | 65 | 0.750 | 1.50 | A5 | 1.070 | 2.14 | E5 | 1.390 | 2.78 |
| 26 | 0.435 | 0.87 | 66 | 0.755 | 1.51 | A6 | 1.075 | 2.15 | E6 | 1.395 | 2.79 |
| 27 | 0.440 | 0.88 | 67 | 0.760 | 1.52 | A7 | 1.080 | 2.16 | E7 | 1.400 | 2.80 |
| 28 | 0.445 | 0.89 | 68 | 0.765 | 1.53 | A8 | 1.085 | 2.17 | E8 | 1.405 | 2.81 |
| 29 | 0.450 | 0.90 | 69 | 0.770 | 1.54 | A9 | 1.090 | 2.18 | E9 | 1.410 | 2.82 |
| 2A | 0.455 | 0.91 | 6A | 0.775 | 1.55 | AA | 1.095 | 2.19 | EA | 1.415 | 2.83 |
| 2B | 0.460 | 0.92 | 6B | 0.780 | 1.56 | AB | 1.100 | 2.20 | EB | 1.420 | 2.84 |
| 2C | 0.465 | 0.93 | 6C | 0.785 | 1.57 | AC | 1.105 | 2.21 | EC | 1.425 | 2.85 |
| 2D | 0.470 | 0.94 | 6D | 0.790 | 1.58 | AD | 1.110 | 2.22 | ED | 1.430 | 2.86 |
| 2E | 0.475 | 0.95 | 6E | 0.795 | 1.59 | AE | 1.115 | 2.23 | EE | 1.435 | 2.87 |
| 2F | 0.480 | 0.96 | 6F | 0.800 | 1.60 | AF | 1.120 | 2.24 | EF | 1.440 | 2.88 |
| 30 | 0.485 | 0.97 | 70 | 0.805 | 1.61 | B0 | 1.125 | 2.25 | F0 | 1.445 | 2.89 |
| 31 | 0.490 | 0.98 | 71 | 0.810 | 1.62 | B1 | 1.130 | 2.26 | F1 | 1.450 | 2.90 |
| 32 | 0.495 | 0.99 | 72 | 0.815 | 1.63 | B2 | 1.135 | 2.27 | F2 | 1.455 | 2.91 |
| 33 | 0.500 | 1.00 | 73 | 0.820 | 1.64 | B3 | 1.140 | 2.28 | F3 | 1.460 | 2.92 |
| 34 | 0.505 | 1.01 | 74 | 0.825 | 1.65 | B4 | 1.145 | 2.29 | F4 | 1.465 | 2.93 |
| 35 | 0.510 | 1.02 | 75 | 0.830 | 1.66 | B5 | 1.150 | 2.30 | F5 | 1.470 | 2.94 |
| 36 | 0.515 | 1.03 | 76 | 0.835 | 1.67 | B6 | 1.155 | 2.31 | F6 | 1.475 | 2.95 |
| 37 | 0.520 | 1.04 | 77 | 0.840 | 1.68 | B7 | 1.160 | 2.32 | F7 | 1.480 | 2.96 |
| 38 | 0.525 | 1.05 | 78 | 0.845 | 1.69 | B8 | 1.165 | 2.33 | F8 | 1.485 | 2.97 |
| 39 | 0.530 | 1.06 | 79 | 0.850 | 1.70 | B9 | 1.170 | 2.34 | F9 | 1.490 | 2.98 |
| 3A | 0.535 | 1.07 | 7A | 0.855 | 1.71 | BA | 1.175 | 2.35 | FA | 1.495 | 2.99 |
| 3B | 0.540 | 1.08 | 7B | 0.860 | 1.72 | BB | 1.180 | 2.36 | FB | 1.500 | 3.00 |
| 3C | 0.545 | 1.09 | 7C | 0.865 | 1.73 | BC | 1.185 | 2.37 | FC | 1.505 | 3.01 |
| 3D | 0.550 | 1.10 | 7D | 0.870 | 1.74 | BD | 1.190 | 2.38 | FD | 1.510 | 3.02 |
| 3E | 0.555 | 1.11 | 7E | 0.875 | 1.75 | BE | 1.195 | 2.39 | FE | 1.515 | 3.03 |
| 3F | 0.560 | 1.12 | 7F | 0.880 | 1.76 | BF | 1.200 | 2.40 | FF | 1.520 | 3.04 |

Table 7-6. VID Table for Output Voltage (continued)

7.3.5 Startup and Shutdown

Startup

The startup sequence includes three sequential periods. During the first period, the device does initialization which includes building up internal LDOs and references, register value initialization, pin strap detection, enabling digital interface, and so forth. The initialization, which is not gated by EN pin voltage, starts as long as VCC/VDRV pin voltage is above the VCC_OK UVLO rising threshold (3.15-V typical). The length of this period is about 200 µs for TPS544C26 device. The I²C communication including both read and write operations is allowed after finishing the initialization.

Once the EN pin voltage crosses above EN high threshold (typically 1.2 V) the device moves to the second period, power-on delay. The power-on delay is programmable in TPS544C26 through register (60h) TON_DELAY with minimum 0.5-ms delay and maximum 2-ms delay.

The V_{OUT} soft-start is the third period. A soft-start ramp, which is an internal signal, starts when the chosen power-on delay finishes. The soft-start time can be selected in register (61h) TON_RISE with options of 1

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ms, 2 ms, 4 ms, 8 ms, and 16 ms. When starting up without pre-bias on the output, the VOUT ramps up from 0 V to either the selected Vboot value or the programmabled VOUT_CMD value (depending on the VOUT_CTRL setting) to avoid the inrush current by the output capacitor charging, and also minimize VOUT overshoot. The VOUT ramping up slew rate is determined by VOUT step (set by PROTOCOL_ID in register (C2h) PROTOCOL_ID_SVID, Vboot and TON_RISE values, and the actual soft-start time can vary from the selected TON RISE value. Table 7-7 shows more details.

For the startup with a pre-biased output the device limits current from being discharged from the prebiased output voltage by preventing the low-side FET from forcing the SW node low until after the first PWM pulse turns on the high-side FET. After the increasing reference voltage exceeds the feedback voltage which is internally divided down from (VOSNS-GOSNS) level, the high-side SW pulses start. This enables a smooth startup with a pre-biased output.

Once VOUT reaches the regulation value and VRRDY delay expires, the converter asserts VRRDY pin and becomes ready for SVID commands. The VRRDY delay can be programmed in (A0h) SYS_CFG_USER1 register and the default value is set to 0 ms to meet SVID communication requirement.

| VOUT_CTR L | VOUT Control Method | VOUT Step | Soft-start Slew Rate (V/ms) | Actual Soft-start Time (ms) |
|---------------|---------------------------|---------------|--------------------------------|---------------------------------------------------------|
| 00b | SVID only | 5 mV or 10 mV | Vboot / TON_RISE | TON_RISE |
| 01b | SVID + I ² C | 5 mV or 10 mV | Vboot / TON_RISE | (1 + I ² C_OFFSET / Vboot) × TON_RISE |
| 10b or 11b | I ² C only | 5 mV | 1.1 V / TON_RISE | (VOUT_CMD + I ² C_OFFSET) / 1.1 V × TON_RISE |
| 10b or 11b | I ² C only | 10 mV | 1.8 V / TON_RISE | (VOUT_CMD + I ² C_OFFSET) / 1.1 V × TON_RISE |

Table 7-7. Soft-start Slew Rate and the Actual Soft-start Time

Shutdown

The TPS544C26 device also offers programmable soft-stop feature through I2C register (65h) TOFF_FALL with 0.5 ms, 1 ms, 2 ms, and 4 ms options. The soft-stop feature force a controlled decrease of the output voltage from regulation to 200 mV. Once Vout is discharged to 200 mV level the power stage stops switching and goes to tri-state. There can be negative inductor current forced during the TOFF_FALL time to discharge the output voltage. This feature can be enabled or disabled through I2C. Configuring EN_SOFT_STOP bit in register (A0h) SYS_CFG_USER1 to value "0" disables the soft-stop feature and automatically sets TOFF_DELAY to 0 ms.

In the case of Soft-stop is enabled, after a stop condition is received and the selected TOFF_DELAY delay expires, the TPS544C26 device enters the soft-stop operation during which the control loop actively controls the discharge slew rate of the output voltage. The power stage continues switching while the internal reference ramps down linearly. The discharge slew rate during this phase is determined by the selected boot up voltage (not the current output voltage) and the selected TOFF_FALL time. Once Vout is discharged to 200 mV level the power stage stops switching and goes to tri-state. The Vout discharge continues but the discharge slew rate is controlled by the load current. With this discharge operation, the TPS544C26 device controls the soft-stop slew rate rather the total soft-stop time, thus the total VOUT discharge time (a.k.a soft-stop time) can vary from the register (65h) TOFF_FALL value. Another word, The TOFF_FALL time is utilized to set the internal reference DAC ramp-down time from the regulation level to 0 mV. For example, under heavy load condition, the total soft-stop time likely becomes longer than the programmed TOFF_FALL value. Under light load, the total soft-stop time likely becomes longer than the programmed TOFF_FALL value. Table Soft-stop Slew Rate and the Actual Soft-stop Time shows more details.

In the case of soft-stop feature is disabled through the *EN_SOFT_STOP* bit in (A0h) SYS_CFG_USER1 register, both high-side and low-side FET drivers are turned off immediately at the time when a stop condition is received (as programmed by the (02h) ON_OFF_CONFIG command), and the output voltage discharge slew rate is controlled by the external load.



| VOUT_CTR L | VOUT Control Method | VOUT Step | Soft-stop Slew Rate (V/ms) | Actual Soft-stop Time (ms) |
|---------------|---------------------------|---------------|-------------------------------|-----------------------------------------------------------------------------------|
| 00b | SVID only | 5 mV or 10 mV | Vboot / TOFF_FALL | (Current VOUT - 0.2 V) / Vboot × TOFF_FALL + t_{DELAY} ⁽¹⁾ |
| 01b | SVID + I ² C | 5 mV or 10 mV | Vboot / TOFF_FALL | (Current VOUT - 0.2 V) / Vboot × TOFF_FALL + t _{DELAY} ⁽¹⁾ |
| 10b or 11b | I ² C only | 5 mV | 1.1 V / TOFF_FALL | (Current VOUT - 0.2 V) / 1.1 V × TOFF_FALL + t_{DELAY} (1) |
| 10b or 11b | I ² C only | 10 mV | 1.8 V / TOFF_FALL | (Current VOUT - 0.2 V) / 1.8 V × TOFF_FALL + t_{DELAY} (1) |

Table 7-8. Soft-stop Slew Rate and the Actual Soft-stop Time

(1) Power stage switching ends at VOUT = 200 mV. t_{DELAY} is determined by output capacitance and the load current.

7.3.6 Dynamic Voltage Slew Rate

TPS544C26 device offers (AFh) DVS_CFG register to set SetVID-Fast slew rate during dynamic voltage scaling.

SetVID command sets the new target voltage. During the output voltage transition, due to the quick charge or discharge to output capacitors, the power stage sees extra inrush current. This inrush current plus load current can trigger overcurrent protection when there is no sufficient room from OCL or NOC setting. For example, the positive inductor current during VOUT step-up transition goes higher than nominal operation. If the LS valley OCL threshold is set relatively low and doesn't allow the extra inrush current, the inductor current is potentially limited by the cycle-by-cycle overcurrent limit feature, thus the actual step-up slew rate is lower than the desired value. Similar situation can happen to VOUT step-down transition with no load condition. The negative inductor current is not allowed to go more negative than the Negative OC threshold. Thus, triggering NOC operation during VOUT step-down transition results that the actual step-down slew rate is lower than the desired value.

7.3.7 Adaptive Voltage Positioning (Droop) and DC Load Line (DCLL)

TPS544C26 device supports adaptive voltage positioning (AVP) through DC Load Line (DCLL) setting in the (ADh) COMP3 register. Use a non-zero DC load line reduces output voltage set-point as a function of the load current, with a controlled slope. This feature is optional and the DCLL setting usually matches what the processor suggests. If a processor doesn't utilize Droop, setting DCLL to 0 m Ω is recommended to avoid violating the VOUT tolerance band spec of the processor.

The DC load line provides two main benefits:

- Reducing the output voltage set-point, reduces the power consumption of the system, when the load current is high.
- Adaptive voltage positioning increases the allowable undershoot and overshoot during load transient events. Below figure compares example output voltage specifications for systems with zero load line and non-zero load line. The nominal setting for the output voltage is chosen to be higher, to allow the entire transient window as margin for transient overshoot and undershoot.

7.3.8 Loop Compensation

The TPS544C26 device provides several options for tuning the output voltage feedback and response to transients. Register (A9h) COMP1_MAIN, (AAh) COMP2_MAIN and (ADh) COMP3 configure the control loop compensation through these fields:

- DC Load Line: Selects the DC shift in output voltage corresponding to increased output current. See (ADh) COMP3 for available options.
- AC Gain: The gain of the integration and AC paths can be selected independently. The AC and integration
 gains both affect the small-signal bandwidth of the converter. The higher AC Gain, the faster the control loop
 responds to an output voltage error or a change on the current sense signal. Too high AC Gain results in less
 noise immunity (a.k.a higher jitter). See (A9h) COMP1_MAIN for available options.



- AC Load Line (ACLL): Selects the AC response to an output voltage error. Lower ACLL configuration directly improves the load transient performance (less V_{OUT} deviation). However, the control loop becomes noise sensitive too low ACLL configuration. The ACLL also affects the settling and response time following a load transient event. See (A9h) COMP1_MAIN for available options.
- Integration Gain: To maintain a good VOUT regulation over load, the control loop includes an integration stage. Integration Gain selects the gain of the integration stage which affects the loop response to an output voltage error. Given the integration time constant is several times of switching cycle time, the Integration Gain affects the loop gain in middle frequency range. The gain of the integration and AC paths can be selected independently. The integration and AC gains both affect the small-signal bandwidth of the converter. See (AAh) COMP2 MAIN for available options.
- Integration Time Constant: The Integration Time Constant affects the settling and response time following an output voltage error. See (AAh) COMP2_MAIN for available options.
- Ramp Amplitude: A ramp based on PVIN/V_{OUT}/f_{SW} information is generated inside the IC to improve jitter performance. Smaller ramp settings result in faster response to load transient event, but also lead to increased off-time jitter. Likewise, large ramp settings result in lower frequency jitter, but becomes slightly slower to respond to an output voltage deviation. The ramp setting also affects the small-signal bandwidth of the converter. See (AAh) COMP2_MAIN for available options.

7.3.9 Set Switching Frequency

TPS544C26 device provides programmable operation mode including the forced CCM operation for tight output voltage ripple and auto-skipping Eco-mode for high light-load efficiency. The TPS544C26 device allows users to select the switching frequency through (33h) FREQUENCY_SWITCH register and operation mode through FCCM bit in (A0h) SYS_CFG_USER1. The available switching frequency options are 600 kHz, 800 kHz, 1 MHz and 1.2 MHz.

The FCCM bit is set during initial power-on and latched after the power conversion is enabled (EN=high). While the device is enabled, a write to FCCM bit is acknowledged but the operation mode does not change until an EN toggle happens.

| (33h) FREQUENCY_SWITCH (Hex) | f _{SW} (kHz) |
|------------------------------|-----------------------|
| 00 | 600 |
| 01 | 800 |
| 02 | 1000 |
| 03 | 1200 |

 Table 7-9. Switching Frequency Options

7.3.10 Switching Node (SW)

The SW pins connect to the switching node of the power conversion stage. The SW pins act as the return path for the high-side gate driver. During nominal operation, the voltage swing on SW normally traverses from below ground to above the input voltage. Parasitic inductance in the PVIN to PGND loop (including the component from the PCB layout and also the component inside the package) and the output capacitance (COSS) of both power FETs form a resonant circuit that can produce high frequency (> 100 MHz) ringing on this node. The voltage peak of this ringing, if not controlled, can be significantly higher than the input voltage. TPS544C26 high-side gate driver is fine tuned to minimize the peak ringing amplitude so that a RC snubber on SW node is usually not needed. However, it is highly recommended for the user to measure the voltage stress across either the high-side or low-side FET and ensure that the peak ringing amplitude does not exceed the absolute maximum rating limit listed in the Absolute Maximum Ratings table.

7.3.11 Overcurrent Limit and Low-side Current Sense

For a synchronous buck converter, the inductor current increases at a linear rate determined by the input voltage, the output voltage, and the output inductor value during the high-side MOSFET on-time (ON time). During the low-side MOSFET on-time (OFF time), this inductor current decreases linearly per slew rate determined by the output voltage and the output inductor value. The inductor during the OFF time, even with a negative slew rate, usually flows from the device SW node to the load the device which is said to be sourcing



current and the output current is declared to be positive. This section describes the overcurrent limit feature based on the positive low-side current. The next section describes the overcurrent limit feature based on the negative low-side current.

The positive overcurrent limit (OCL) feature in the TPS544C26 device is implemented to clamp low-side valley current on a cycle-by-cycle basis. The inductor current is monitored during the OFF time by sensing the current flowing through the low-side MOSFET. When the sensed low-side MOSFET current remains above the selected OCL threshold, the low-side MOSFET stays ON until the sensed current level becomes lower than the selected OCL threshold. This operation extends the OFF time and pushes the next ON time (where the high-side MOSFET turns on) out. As a result, the OCL bit in (7Bh) STATUS IOUT is set, also the average output current sourced by the device is reduced. As long as the load pulls a heavy load where the sensed low-side valley current exceeds the selected OCL threshold, the device continuously operates in this clamping mode which extends the current OFF time and pushes the next ON time out. The device does not implement a fault response circuit directly tied to the overcurrent limit circuit, instead, the VOUT Tracking UVF function is utilized to shuts the device down under an overcurrent fault. During an overcurrent event, the current sunk by the load (I_{OUT}) exceeds the current sourced by the device to the output capacitors, thus, the output voltage tends to decrease. Eventually, when the output voltage falls below the selected undervoltage fault threshold, the VOUT Tracking UVF comparator detects and shuts down the device after the UVF Response Delay (programmable in (45h) VOUT UV FAULT RESPONSE register). The device then responds to the Tracking UVF trigger per bit[3] RESTART selection in (45h) VOUT UV FAULT RESPONSE register. With the RESTART bit unset (value "0"), the device latches OFF both high-side and low-side drivers. The latch is cleared with a reset of VCC or by toggling the EN pin. With the RESTART bit set (value "1"), the device enters hiccup mode and re-starts automatically after a hiccup sleep time of 56 ms, without limitation on the number of restart attempts. In other words, the response to an overcurrent fault is set by the programmed UVF response.

If an OCL condition happens during a soft-start ramp the device still operates with the cycle-by-cycle current limit based on the sensed low-side valley current. This operation can limit the energy charged into the output capacitors thus the output voltage likely ramps up slower than the desired soft-start slew rate. During the soft-start, the VOUT Tracking UVF comparator is disabled thus the device does not respond to a UVF event. Upon the completion of the soft-start, the VOUT Tracking UVF comparator is enabled, then the device starts responding to the UVF event.

The OCL feature in the device is implemented by detecting the low-side valley current through analog circuitries and has no relationship with the integrated Analog-to-Digital converter (ADC). The telemetry analog-front-end gets an input from the low-side current sense circuit and average low-side MOSFET current from the start to the end of each low-side MOSFET on time. By this method, the telemetry sub-system reports the load current (IOUT) which is the average value of the inductor current but not peak or valley values.

7.3.12 Negative Overcurrent Limit

The TPS544C26 device is a synchronous Buck converter, thus the current can flow from the device to the load or from the load into the device through SW node. When current is flowing from the device SW node to the load the device is said to be sourcing current and the output current declared to be positive. When current is flowing into the device SW node from the load, the device is said to be sinking current and the current is declared to be negative.

The device offers a programmable, cycle-by-cycle negative overcurrent (NOC) limit through (B4h) IOUT_NOC_LIMIT register. The available NOC thresholds which scale with ICC_MAX setting (see ICC_MAX) are shown in Table 7-10. Similar with the positive overcurrent limit, the inductor current is monitored during the low-side MOSFET ON period. To prevent too large negative current and a damage of low-side MOSFET, the device turns off the low-side MOSFET after the detected on the low-side MOSFET exceeds the selected NOC limit. And then the high-side FET is turned on for an on-time determined by PVIN, SEL_NOC_TON bit (see (ADh) COMP3) and f_{SW} setting).

The NOC operation usually happens after an overvoltage event but can also happen during VOUT step-down transition with fast slew rate.



| SEL NOCI1:01 | Negative Overcurrent Limits (A) | | | | |
|--------------|---------------------------------|----------------|--|--|--|
| SEL_NOC[1:0] | ICC_MAX ≥ 15 A | ICC_MAX ≤ 10 A | | | |
| 00 | -21 | -11.3 | | | |
| 01 | -16 | -8.7 | | | |
| 10 | -12.8 | -7.2 | | | |
| 11 | -10.8 | -6.2 | | | |

Table 7-10. Negative Overcurrent Limits

7.3.13 Zero-Crossing Detection

TPS544C26 device implements an internal circuit for the zero inductor-current detection during skip-mode operation. The fixed Z-C detection threshold is set to a slightly positive value such as 300 mA to compensate the delay time of the Z-C detection circuit and avoid too-late detection. Depending on the inductor value, frequency, VIN and Vout conditions, this can result diode conduction for a short period.

7.3.14 Input Overvoltage Protection

The TPS544C26 device actively monitors the PVIN input voltage. When the PVIN voltage level is above the over-voltage threshold, TPS544C26 device stops switching and pulls VRRDY signal low. Two options are provided for PVIN OV rising threshold in (55h) VIN_OV_FAULT_LIMIT register while the PVIN OV falling threshold is always 13.5V.

Once the PVIN over-voltage fault is triggered, the device latches off until EN pin is toggled or PVIN is reset.

7.3.15 Output Overvoltage and Undervoltage Protection

The TPS544C26 device monitors the output voltage (VOSNS – GOSNS) to provide overvoltage (OV) and undervoltage (UV) protection. The Tracking OVF and Tracking UVF thresholds both track to the VOUT setting (commanded by either SVID SetVID command or I²C (A6h) VOUT_CMD) but can be selected independently.

VOUT Tracking UVF

The Table 7-11 shows the available tracking UVF thresholds. When the output voltage (VOSNS – GOSNS) drops below the VOUT setting by the value configured in (44h) VOUT_UV_FAULT_LIMIT register, the tracking UVF comparator detects and an internal UVF Response Delay counter selected in (45h) VOUT_UV_FAULT_RESPONSE register begins. At the same time, the UVF bit in (7Ah) STATUS_VOUT register is set. When the UVF Response Delay expires, the device responds to the UV fault per bit[3] *RESTART* selection in (45h) VOUT_UV_FAULT_RESPONSE register. With the *RESTART* bit unset (value "0"), the device latches OFF both high-side and low-side drivers. The latch is cleared with a reset of VCC or by re-toggling the EN pin. With the *RESTART* bit set (value "1"), the device enters hiccup mode and re-starts automatically after a hiccup sleep time of 56 ms, without limitation on the number of restart attempts.

The tracking UVF function is enabled only after the soft-start period completes.

During the UVF Response Delay, if the output voltage (VOSNS – GOSNS) rises above the UVF threshold, thus not qualified for a UVF event, the UVF response delay timer resets to zero. When the VOUT drops below the UVF threshold again, the UVF response delay timer re-starts from zero.

The TPS544C26 device also offers tracking UV Warning (UVW) function. The Table 7-12 shows the available tracking UVW thresholds. When the output voltage (VOSNS – GOSNS) drops lower than the VOUT setting by the value configured in (43h) VOUT_UV_WARN_LIMIT register, the tracking UVW comparator detects and the UVW bit in (7Ah) STATUS_VOUT register is set. There is no purpose delay for UVW event.

| SEL_UVF[1:0] | VOUT Tracking UVF Threshold (mV) |
|--------------|----------------------------------|
| 00 | -150 |
| 01 | -200 |

Table 7-11. VOUT Tracking UV Fault Thresholds



| Table 7-11. VOUT Tracking UV Fault Thresholds (continued) | | | | |
|-----------------------------------------------------------|----------------------------------|--|--|--|
| SEL_UVF[1:0] | VOUT Tracking UVF Threshold (mV) | | | |
| 10 | -200 | | | |
| 11 | -300 | | | |

Table 7-12. VOUT Tracking UV Warning Thresholds

| SEL_UVW[1:0] | VOUT Tracking UVW Threshold (mV) |
|--------------|----------------------------------|
| 00 | -100 |
| 01 | -150 |
| 10 | -200 |
| 11 | -300 |

VOUT Tracking OVF

The Table 7-13 shows the available tracking OVF thresholds. When the output voltage (VOSNS - GOSNS) rises higher than the VOUT setting by the value configured in (40h) VOUT OV FAULT LIMIT register, the tracking OVF comparator detects and the device responds to the OV fault immediately per bit[3] RESTART selection in (41h) VOUT OV FAULT RESPONSE register. At the same time, the OVF bit in (7Ah) STATUS_VOUT register is set. With the RESTART bit unset (value "0"), the device latches OFF the high-side MOSFET driver and turns on the low-side MOSFET. The low-side MOSFET is kept ON until the sensed low-side negative current reaches the selected negative overcurrent (NOC) limit (see (B4h) IOUT NOC LIMIT register). Upon reaching the NOC limit, the low-side MOSFET is turned off, and the high-side MOSFET is turned on, for an on-time determined by PVIN, SEL_NOC_TON bit (see (ADh) COMP3) and f_{SW} setting. After the high-side MOSFET turns off the low-side MOSFET turns on again and the negative current on low-side MOSFET is monitored to compare with the selected NOC limit. The device operates in this cycle until the output voltage is fully discharged. Then the device has high-side MOSFET latched OFF and low-side MOSFET latched ON. The latch is cleared with a reset of VCC or by toggling the EN pin. With the RESTART bit set (value "1"), the device still discharge output voltage by the NOC operation. However, the device activates hiccup mode and re-starts automatically after a hiccup sleep time of 56 ms, without limitation on the number of restart attempts. The hiccup sleep time counter starts right after the OVF trigger.

The tracking OVF function is enabled only after the soft-start period completes.

The TPS544C26 device also offers tracking OV Warning (OVW) function. The Table 7-14 shows the available tracking OVW thresholds. When the output voltage (VOSNS – GOSNS) rises higher than the VOUT setting by the value configured in (42h) VOUT_OV_WARN_LIMIT register, the tracking OVW comparator detects and the OVW bit in (7Ah) STATUS_VOUT register is set. There is no purpose delay for OVW event.

| SEL_OVF[1:0] | VOUT Tracking OVF Threshold (mV) | | |
|--------------|----------------------------------|--|--|
| 00 | +100 | | |
| 01 | +150 | | |
| 10 | +200 | | |
| 11 | +300 | | |

| Table 7-14. VOUT Tracking OV Wari | ning Thresholds |
|-----------------------------------|-----------------|
|-----------------------------------|-----------------|

| SEL_OVW[1:0] | VOUT Tracking OVW Threshold (mV) |
|--------------|----------------------------------|
| 00 | +100 |
| 01 | +150 |
| 10 | +200 |
| 11 | +300 |



VOUT Fixed OVF

In parallel with VOUT tracking OVF the TPS544C26 device offers Fixed OVF feature. The Fixed OVF comparator implments a constant reference which is configured in (B4h) IOUT_NOC_LIMIT register and the reference level does not track with the VOUT setting. The Fixed OVF comparator is activated to monitor the output voltage (VOSNS – GOSNS) all the time including power conversion off period (EN = low) and soft-start period. Once the VOUT Fixed OVF is triggered, the OVF bit in (7Ah) STATUS_VOUT register is set, and the device enters NOC operation immediately no matter the power conversion is enabled or not. The device operates in NOC operation to fully discharge the output voltage. Then the device has high-side MOSFET latched OFF and low-side MOSFET latched ON. The latch is cleared with a reset of VCC or by toggling the EN pin. A Fixed OVF event always leads to latch-off response and the selected OVF response in (41h) VOUT_OV_FAULT_RESPONSE register does not affect the response for a Fixed OVF event.

Given the Fixed OVF comparator is always activated the device provides alternate protection to high-side MOSFET damage cases. When the high-side MOSFET is damaged and short PVIN to the SW node, the output voltage (VOSNS – GOSNS) rises quickly. The TPS544C26 device can detect this kind of event and turn on low-side MOSFET to discharge the excess energy, thus protecting the load from damage.

In a case that the commanded VOUT is higher than the Fixed OVF threshold, the device triggers Fixed OV fault and enters the NOC operation immediately. If this scenario happens before soft-start, the device never initiate the soft-start ramp and enters latch-off directly. To avoid this situation, the Fixed OVF feature can be disabled through the bit[2] *EN_FIX_OVF* in (B4h) IOUT_NOC_LIMIT register.

| PROTOCOL_ID in (C2h) PROTOCOL_ID_SVID | SEL_FIX_OVF[1] in (B4h) IOUT_NOC_LIMIT | VOUT Fixed OVF Threshold (V) |
|----------------------------------------------|-------------------------------------------|------------------------------|
| PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV) | 0 | 1.5 |
| PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV) | 1 | 1.8 |
| PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV) | 0 | 2.4 |
| PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV) | 1 | 3.0 |

Table 7-15. VOUT Fixed OV Fault Thresholds

7.3.16 Overtemperature Protection

To have full coverage for a potential overtemperature event, the TPS544C26 device implements three overtemperature protection circuitries - two on the Controller die and one on the Power Stage (PS) die.

Programmable OTP by Monitoring the Controller Die Temperature

The on-die temperature sense circuit senses the controller die temperature. The sensed signal is fed into an internal ADC and converted to the Controller die temperature which is reported as (8Dh) READ_TEMPERATURE_1 through the Telemetry sub-system. This feature utilizes a digital comparator that compares the output of the IC TEMPERATURE telemetry to the fault threshold selected in (4Fh) OT_FAULT_LIMIT register. The device stops the SW switching when the sensed IC temperature goes beyond the selected threshold. The device response to a Programmable OTP event is described in (50h) OT_FAULT_RESPONSE.

Analog OTP by Monitoring the Controller Die Temperature

The sensed temperature signal is fed into an analog OTP circuit on the Controller die as well. An analog comparator is utilized to compare the output of the Controller die temperature sensing circuit to a fixed threshold (rising 166 °C typical). The device stops the SW switching when the sensed IC temperature goes beyond the fixed threshold. The device response to an Analog OTP event is always the same as the Programmable OTP.



Given the fixed threshold (166 °C typical) for the Analog OTP is higher than the highest setting (150 °C typical) in Programmable OTP, the Analog OTP is unlikely to trigger during the nominal operation.

Analog OTP by Monitoring the Power Stage Die Temperature

A temperature sensing circuit is implemented in the Power Stage (PS) die. This sensed is fed into an analog OTP circuit on the PS die. An analog comparator is utilized to compare the output of the PS die temperature sensing circuit to a fixed threshold (rising 166 °C typical). The device stops the SW switching when the sensed IC temperature goes beyond the fixed threshold. Once the PS die temperature falls 30 °C below the rising threshold, the device automatically restarts with an initiated soft-start. This Analog OTP is a non-latch protection.

7.3.17 VR Ready

The TPS544C26 device offers VRRDY output that asserts high when the converter output is within the target. The VRRDY output stays low when the switching is disabled either by EN pin or through I2C (01h) OPERATION command. The VRRDY function is activated after the soft-start ramp is completed. The VRRDY output is an open-drain output and must be pulled up externally through a pull-up resistor (usually 10 k Ω). The recommended VRRDY pull-up resistor value is 1 k Ω to 100 k Ω .

7.3.18 Catastrophic Fault Alert: CAT_FAULT#

The device has CAT_FAULT# output on pin 28 which alerts the system to potentially catastrophic power supply faults. The CAT_FAULT# output is an open-drain output and must be pulled up externally through a pullup resistor. The recommended CAT_FAULT# pull-up resistor value is 3.3 k Ω to 10 k Ω while pulling up to 3.3 V voltage source through a 4.99 k Ω resistor is commonly used. The CAT_FAULT# function is activated after VCC/VDRV pin voltage rises above VCC_OK UVLO rising threshold (3.15 V typical) regardless of by EN pin logic level.

Fault conditions which assert the CAT_FAULT# pin include:

- Over-voltage fault detected by Fixed VOUT OVF
- Over-voltage fault detected by Tracking VOUT OVF
- Under-voltage fault detected by Tracking VOUT UVF, including the UV fault caused by an overcurrent event
- Over-temperature fault (based on the threshold set through I2C in (4Fh) OT_FAULT_LIMIT register)
- Powerstage OT or VDRV_UV faults (Either fault asserts PS_FLT status bit in (80h) STATUS_MFR register)

Once asserted low by a fault event CAT_FAULT# pin latches low until a reset of PVIN or an EN toggle.

7.3.19 Telemetry

The telemetry sub-system in the controller core supports the following measurements:

- Input voltage (direct measurement)
- Input current (direct measurement)
- Output voltage (direct measurement)
- Output current (direct measurement)
- Controller die temperature (direct measurement)
- Input Power (Calculation, the product of the input voltage and the input current)

The ADC output is a single conversion of each measurement without rolling window averaging for fast refresh rate of these key system parameter. All above parameters are measured sequentially while the Input current and Output current are measured more often than the others. This sequence design allows each IIN or IOUT telemetry value to be updated within 95 µs, while each of the rest of telemetry value to be updated within 190 µs.

Input Power Telemetry (VIN/IIN/PIN)

The input voltage sense telemetry senses the voltage level on pin 4 VINSENM. The device offers internal divider to minimize the external component count and save solution size. The VIN reporting range is limited from 8 V to 16 V to improve the reporting resolution. For any VIN value less than 8 V, the VIN telemetry reports 8 V. For any

VIN value higher than 16 V, the VIN telemetry reports 16 V. For example, the READ_VIN reports 8 V for a VIN = 5 V condition. The VIN conversion equation is:

$$VIN = READ_VIN \times 0.03125 + 8$$

Where

- VIN is the voltage level seen on pin 4 VINSENM
- READ VIN is the I²C (88h) READ VIN register value in decimal

The input current sense telemetry senses the differntial voltage level across pin 3 VINSENP and pin 4 VINSENM. A high accuracy sensing resistor in series with the input bus is commonly used for this feature. Together with the setting in (B3h) PIN SENSE_RES register, the ADC converts the sensed differential voltage to input current in amp. The device offers internal gain stage to minimize the external component count and save solution size. Given the sensed differential voltage is in millivolts range and to avoid impact from the switching noise on the input bus, a ceramic bypass capacitor is required on each pin (pin 3 VINSENP and pin 4 VINSENM) referring to PGND and the recommended value is at least 100 pF with X7R temperature characterisitic. The IIN conversion equation is:

$$IIN = READ_{IIN} \times \frac{IIN_{MAX}}{256}$$

Where

- IIN is the input current level flowing through the choosen IIN sensing resistor
- READ IIN is the I²C (89h) READ IIN register value in decimal
- IIN MAX is a maximum input current value selected in I²C (B3h) PIN SENSE RES register

The input power reported in (97h) READ_PIN register is a simple calculation, which is the product of the measured raw input voltage and the measured raw input current. The calculation does not use the register value in (88h) READ VIN and (89h) READ IIN. The PIN conversion equation is:

$$PIN = READ_PIN \times \frac{PIN_MAX}{255}$$

Where

- PIN is the calculated input power value
- READ PIN is the I²C (97h) READ PIN register value in decimal
- PIN MAX is a maximum input power value selected in I²C (6Bh) PIN OP WARN LIMIT register

When input power feature is not used, follow below connection for pin 3 VINSENP and pin 4 VINSENM so that the device can report the input voltage level on PVIN node:

- 1. Short pin 3 VINSENP to pin 4 VINSENM,
- Place a 0.1 µF ceramic bypass capacitor on pin 4 VINSENM referring to AGND, 2.
- 3. Connect pin 4 VINSENM to PVIN node of TPS544C26 device.

VOUT and IOUT Telemetry

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The output voltage sense telemetry senses the differential voltage across VOSNS to GOSNS pin. The conversion equation for VOUT is related with VOUT step (5 mV or 10 mV) which is defined by PROTOCOL ID bits in I²C (C2h) PROTOCOL ID SVID register.

The VOUT conversion equation for 5 mV step is:

$$VOUT = READ_VOUT \times 0.00625 + 0.125$$

The VOUT conversion equation for 10 mV step is:

 $VOUT = READ_VOUT \times 0.0125 + 0.250$

Where

VOUT is the sensed output voltage (VOSNS-GOSNS)

(3)

(2)

31

Submit Document Feedback

(1)

(4)



• READ_VOUT is the I²C (8Bh) READ_VOUT register value in decimal

The output current sense telemetry senses the average of low-side FET current from the start to the end of each low-side FET on time which provides the average inductor current. To achieve high accuracy and wide report range, the device automatically sets the current sense gain based on ICC_MAX setting in (C0h) ICC_MAX register. When the ICC_MAX is equal or greater than 15 A, the current sense gain is set to a smaller value to achieve wide report range. When the ICC_MAX is equal or less than 10 A, the current sense circuit uses a higher gain to get a significant amplitude and achieve good accuracy. The change of gain setting does not affect the positive overcurrent limit (OCL) threshold but affect the negative overcurrent (NOC) threshold. The IOUT conversion equation is:

$$IOUT = READ_IOUT \times \frac{ICC_MAX}{255}$$

(6)

Where

- IOUT is the DC output current flowing from the output capacitors to the load
- READ_IOUT is the I²C (8Ch) READ_IOUT register value in decimal
- ICC_MAX is a full-scale value for IOUT selected in I²C (C0h) ICC_MAX register

IC Temperature Telemetry

The die temperature sense telemetry senses the controller die temperature. The power stage (PS) die implementes its own over-temperature protection and the PS die temperature is not reported through temetry sub-system. The IC Temperature conversion equation is:

$$\Gamma EMP = READ_TEMPERATURE_1 - 40$$

(7)

Where

- TEMP is the controller die temperature
- READ_TEMPERATURE_1 is the I²C (8Dh) READ_TEMPERATURE_1 register value in decimal

7.3.20 I²C Interface General Description

The TPS544C26 device offers both I^2C interface and SVID interface for programming and telemetry report. The device supports a group of I^2C registers which is listed in . The device also supports a subset of the SVID registers listed in .

For I²C interface, the TPS544C26 device supports minimum 50 kHz and maximum 1 MHz operating frequency range, with the support of the Standard-mode, Fast-mode, and Fast-mode Plus bus timing requirements.

The high threshold of I²C SCL and SDA pin is 0.585 V typical, and the low threshold of I2C SCL and SDA pin is 0.515 V typical.

The TPS544C26 device contains nonvolatile memory that is used to store user-accessible configurations. The settings programmed into the device are not automatically saved into this nonvolatile memory. The (15h) STORE_USER_ALL command must be used to commit the current I²C settings to nonvolatile memory as device defaults. For example, after importing a group of settings from a user specific configuration file the (15h) STORE_USER_ALL command must be used to save the settings into the nonvolatile memory. The settings that are capable of being stored in nonvolatile memory are noted in their detailed descriptions.

Note

Per I²C Standard, the packet error checking (PEC) feature is not supported by TPS544C26. A command with PEC can result in unexpected communication error.

7.3.20.1 Setting the I²C Address

The TPS544C26 device offers selectable 7-bit I²C address either through a resistor from the I²C_ADDR pin (pin 29) to AGND, or programmable by writing an 7-bit address value into the (A2h) I²C_ADDR register.

As the default configuration, a resistor from the I²C_ADDR pin (pin 29) to AGND sets the pre-configured 7-bit I²C address (0x70 to 0x7F) in the memory map. Up to 16 different addresses can be set, allowing 16 devices



with unique addresses in a single system. TI recommends $\pm 1\%$ tolerance resistors with a typical temperature coefficient of $\pm 100 \text{ ppm/}^{\circ}\text{C}$

As an alternative method, the I²C address of a TPS544C26 device can be programmed by writing an address value into (A2h) I2C_ADDR register. This register supports the full range from 00h to 7Fh (7-bit, '0000000' to '1111111'). And, an override bit has to be set to '1' so that TPS544C26 device ignores the pin 29 detection and straightly go to (A2h) I²C_ADDR register for I²C address. This method allows much more flexibility on the address selections. This override bit locates in (A0h) SYS_CFG_USER1 register bit[0].

For the programmed address to take effect, below actions have to be taken:

- 1. Write the desired I²C address value to bit[6:0] in the (A2h) I2C_ADDR register.
- 2. Set the OVRD_I2C_ADDR bit in the (A0h) SYS_CFG_USER1 register.
- 3. Store the new values to EEPROM by writing "1" to bit[0] in (15h) STORE_USER_ALL register. The whole store process takes 150 ms to finish.
- 4. Wait sufficient time for the store action to finish. Power cycle the device. During the power-on, the address programmed to the (A2h) I2C_ADDR register takes effect.

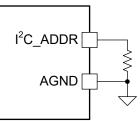


Figure 7-1. I2C Address Pin-strapping

| Table 7-16. I2C_ | ADDR pin re | sistor selected values |
|------------------|-------------|------------------------|
|------------------|-------------|------------------------|

| R _{ADDR} (kΩ) | (A2h) I ² C_ADDR (Bin) | (A2h) I ² C_ADDR (Hex) | | |
|------------------------|-----------------------------------|-----------------------------------|--|--|
| SHORT | 1110000 | 70 | | |
| 5.62 | 1110001 | 71 | | |
| 9.53 | 1110010 | 72 | | |
| 14 | 1110011 | 73 | | |
| 21 | 1110100 | 74 | | |
| 30.1 | 1110101 | 75 | | |
| 36.5 | 1110110 | 76 | | |
| 43.2 | 1110111 | 77 | | |
| 51.1 | 1111000 | 78 | | |
| 61.9 | 1111001 | 79 | | |
| 75 | 1111010 | 7A | | |
| 88.7 | 1111011 | 7B | | |
| 105 | 1111100 | 7C | | |
| 127 | 1111101 | 7D | | |
| 150 | 111110 | 7E | | |
| FLOAT | 1111111 | 7F | | |

For example, using 9.53 k Ω selects 1110010b (72h) as the 7-bit I²C address. Then the 8-bit I²C address is 11100100b (E4h), which is the 7-bit address followed by the write bit 0b.

| Table | 7-17. | l ² C | 8-bit | Address |
|-------|-------|------------------|-------|---------|
|-------|-------|------------------|-------|---------|

| Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|------------------------------------|-------|-------|-------|-------|-------|-----------|-------|
| 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 |
| 7 bits set by address pin resistor | | | | | | Write bit | |



7.3.20.2 I²C Write Protection

The TPS544C26 device offers write protection feature through (B1h) REG_LOCK register. After power-on, the user accessible registers with write access are by default under "write protected" state, meaning the response to a write is NACK. The device always acknowledges a read command and responds the data byte accordantly. Only after writing the correct passcodes (multiple writes in the right order) into this REG_LOCK register, the user accessible registers are "unlocked" and the device acknowledges the next write commands. (B1h) REG_LOCK shows more details.

7.3.20.3 I²C Registers With Special Handling

In most cases the effect of an l^2C write to a register is immediate: Once the write is performed, the value becomes available for use in the system. There are a few exceptions with special handling for preserving the integrity of the system.

Prevent write when the SW switching is enabled

A write to the following list of registers is prevented and the system response is to NACK writes to these registers when the SW switching is enabled. For example, before importing the user specific configuration, disabling the SW switching is required to successfully import a new value to these registers.

- (16h) RESTORE_USER_ALL
- (60h) TON DELAY
- (61h) TON RISE
- (64h) TOFF_DELAY
- (65h) TOFF_FALL
- (BDh) EXT_CAPABILITY_VIDOMAX_H
- (BEh) VIDO_MAX_L

When ON_OFF_CONFIG is set to *Always On*, the values from the NVM restore for these registers will be NACKed and will never become effective. Even the NVM restore during power-on initialization is affected by this kind of configuration.

Register update waits until the SW switching is disabled

When a write to one of these registers is accepted (ACKed), one or more bit-fields in this register are allowed to take effect immediately only if the SW switching is disabled. If the SW switching is enabled, the previous value for those bit-fields continues to be used by the system, and the new value for those bit-fields is kept ready inside the IC but only become effective the next time when the SW switching is disabled. A readback attempt will be accepted (ACKed) and return the most recent ACKed value.

- (A0h) SYS_CFG_USER1 register, FCCM bit
- (A0h) SYS_CFG_USER1 register, VOUT_CTRL field
- (A0h) SYS CFG USER1 register, EN SOFT STOP bit
- (A0h) SYS CFG USER1 register, VRRDY DELAY field
- (A1h) SVID ADDR
- (C2h) PROTOCOL_ID_SVID register, ALL_CALL_SEL field
- (A8h) I²C_OFFSET, but only when VOUT_CTRL field is set to "01b"

When ON_OFF_CONFIG is set to *Always On*, the values from the NVM restore can be kept in the staging area and never become effective. Even the NVM restore during power-on initialization is affected by this kind of configuration.

Register update waits for a power cycling or a manual restore

When a write to one of these register is accepted (ACKed), one or more bit-fields in the register are not allowed to take effect at all. The new value takes effect only if the value is stored into NVM first and then retrieved from NVM after the device is powered on.

- (A0h) SYS_CFG_USER1 register, OVRD_SVID_ADDR bit
- (A0h) SYS_CFG_USER1 register, OVRD_I2C_ADDR bit



• (A2h) I²C_ADDR register, I²C_ADDR filed

The sequence of events, for the contents of those fields to take effect is as follows:

- 1. The user writes the desired value to the register,
- 2. The user executes an NVM store command ((15h) STORE_USER_ALL),
- 3. The part is power-cycled.

7.4 Device Functional Modes

7.4.1 Forced Continuous-Conduction Mode

When the operation mode is set to FCCM, the controller operates in continuous conduction mode (CCM) during light-load conditions. During CCM, the switching frequency maintained to an almost constant level over the entire load range which is suitable for applications requiring tight control of the switching frequency at the cost of lower efficiency.

When FCCM is selected, the TPS544C26 device operates at CCM during the whole soft-start period as well as the nominal operation.

7.4.2 Auto-Skip Eco-mode[™] Light Load Operation

When the operation mode is set to DCM, the device automatically reduces the switching frequency at light-load conditions to maintain high efficiency. This section describes the operation in detail.

As the output current decreases from heavy load condition, the inductor current also decreases until the rippled valley of the inductor current touches zero level. Zero level is the boundary between the continuous-conduction and discontinuous-conduction modes. The synchronous MOSFET turns off when this zero inductor current is detected. As the load current decreases further, the converter runs into discontinuous-conduction mode (DCM). The on-time is maintained to a level approximately the same as during continuous-conduction mode operation so that discharging the output capacitor with a smaller load current to the level of the reference voltage requires more time. The transition point to the light-load operation IOUT(LL) (for example: the threshold between continuous-conduction mode) is calculated as shown in below equation.

$$I_{OUT(LL)} = \frac{1}{2 \times L \times f_{SW}} \times \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{V_{IN}}$$
(8)

Where

• f_{SW} is the switching frequency

TI recommends sing low ESR capacitors (such as ceramic capacitor) for skip-mode.

7.4.3 Powering the Device From a 12-V Bus

The device works well when powering from a 12-V bus with a single V_{IN} configuration. As a single V_{IN} configuration, the internal LDO is powered by the 12-V bus and generates 4.5-V output to bias the internal analog circuitry and also powers up the gate drives. The V_{IN} input range under this configuration is 4 V to 16 V for up to 35-A load current. Figure 7-2 shows an example for this single V_{IN} configuration.

 V_{IN} and EN are the two signals to enable the part. For start-up sequence, any sequence between the V_{IN} and EN signals can power the device up correctly.



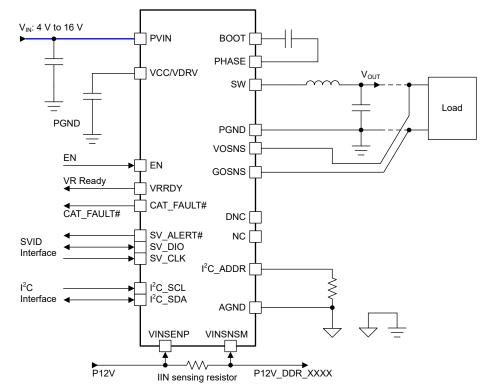


Figure 7-2. Single V_{IN} Configuration With 12-V Bus

7.4.4 Powering the Device From a Split-rail Configuration

When an external bias that is at a different level from the main V_{IN} bus, is applied to the VCC/VDRV pin, the device can be configured to split rail by utilizing both the main V_{IN} bus and the VCC bias. Connecting a valid bias rail to the VCC/VDRV pin overrides the internal VCC LDO, saving power loss on that linear regulator. This configuration helps improve overall system-level efficiency but requires a valid VCC bias. A 5.0 V rail is the common choice for VCC bias. With a stable VCC bias, the V_{IN} input range under this configuration can be as low as 2.7 V and up to 16 V.

The noise of the external bias affects the internal analog circuitry. To ensure a proper operation, a clean, low-noise external bias, and a local decoupling capacitor from the VCC pin to PGND pin are required. Figure 7-3 shows an example for this split rail configuration.

The VCC external bias current during nominal operation varies with the bias voltage level and the switching frequency. For example, by setting the device to skip mode, the VCC pin draws less and less current from the external bias when the switching frequency decreases under light load conditions. The typical VCC external bias current under FCCM operation is listed in the *Electrical Characteristics* table to help the user prepare the capacity of the external bias.

Under split rail configuration, PVIN, VCC bias, and EN are the signals to enable the part. For the start-up sequence, it is recommended that the external bias is applied on the VCC/VDRV pin earlier than PVIN rail. A practical start-up sequence example is the external 5 V bias is applied first, then the 12 V bus is applied on PVIN, and then EN signal goes high.



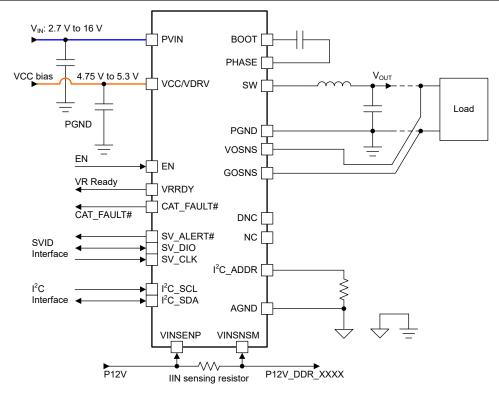


Figure 7-3. Split Rail Configuration With External VCC Bias

7.5 Programming

7.5.1 Supported I²C Registers

The Supported I²C and Default Values Table lists the implemented registers and also the default for the bit behavior and register values.

| Register address | Register Name | R/W | NVM | Default Value (Hex) | Default Behavior | |
|---------------------|------------------------|-----|-----|------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------|--|
| 01h | OPERATION | R/W | NO | 00h | OPERATION OFF | |
| 02h | ON_OFF_CONFIG | R/W | YES | 40h | Turn ON/OFF by EN pin only | |
| 03h | CLEAR_FAULTS | W | NO | N/A | Clear all faults | |
| 15h | STORE_USER_ALL | W | NO | N/A | Stores all current storable register settings into NVM | |
| 16h | RESTORE_USER_ALL | W | NO | N/A | Restores all storable register settings from NVM | |
| 33h | FREQUENCY_SWITCH | R/W | YES | 01h | Switching frequency is set to 800 kHz | |
| 35h | VIN_ON | R/W | YES | 03h | ON threshold is determined by both PVIN and VCC conditions. Both PVIN > 2.55 V and VCC > 3.8 V conditions have to be satisfied to enable the power conversion. | |
| 36h | VIN_OFF | R/W | YES | 07h | OFF threshold is determined by both PVIN and VCC conditions. Either PVIN ≤ 2.3 V or VDRV ≤ 3.4 V disable the power conversion. | |
| 40h | VOUT_OV_FAULT_LIMIT | R/W | YES | 02h | VOUT Tracking OV Fault threshold = +200 mV | |
| 41h | VOUT_OV_FAULT_RESPONSE | R/W | YES | 00h | Latch-off after a fault | |
| 42h | VOUT_OV_WARN_LIMIT | R/W | YES | 01h | VOUT Tracking OV Warning threshold = +150 mV | |
| 43h | VOUT_UV_WARN_LIMIT | R/W | YES | 01h | VOUT Tracking UV Warning threshold = -150 mV | |
| 44h | VOUT_UV_FAULT_LIMIT | R/W | YES | 02h | VOUT Tracking UV Fault threshold = −200 mV | |
| 45h | VOUT_UV_FAULT_RESPONSE | R/W | YES | 02h | Latch-off after a fault, and the response delay before disabling the power conversion is 64 μs | |
| 46h | IOUT_OC_FAULT_LIMIT | R/W | YES | 09h | Low-side valley current limiting threshold = 35 A | |
| 4Fh | OT_FAULT_LIMIT | R/W | YES | 07h | Programmable OT Fault threshold = 150 °C | |

Table 7-18. Supported I²C and Default Values

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Table 7-18. Supported I²C and Default Values (continued)

| Register address | Register Name | R/W | NVM | Default Value (Hex) | Default Behavior | |
|---------------------|-------------------------|-----|-----|---------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|
| 50h | OT_FAULT_RESPONSE | R/W | YES | 00h | Latch-off after a fault | |
| 51h | OT_WARN_LIMIT | R/W | YES | 06h | Programmable OT Warning threshold = 125 °C | |
| 55h | VIN_OV_FAULT_LIMIT | R/W | YES | 01h | PVIN OV Fault threshold = 18.5 V | |
| 60h | TON_DELAY | R/W | YES | 00h | 0.5 ms delay when a start condition is received (as programmed by the ON_OFF_CONFIG register) until the output voltage starts to rise | |
| 61h | TON_RISE | R/W | YES | 00h | 1 ms from when the output starts to rise until the output voltage has entered the regulation band | |
| 64h | TOFF_DELAY | R/W | YES | 00h | 0 ms from when a stop condition is received (as programmed by the ON_OFF_CONFIG register) until the unit starts the soft-stop operation | |
| 65h | TOFF_FALL | R/W | YES | 00h | 0.5 ms from the end of the turn-off delay time until the internal reference DAC is commanded to 0 mV | |
| 6Bh | PIN_OP_WARN_LIMIT | R/W | YES | 03h | Maximum PIN (input power) threshold = 360 W | |
| 7Ah | STATUS_VOUT | R/W | NO | N/A | Current status | |
| 7Bh | STATUS_IOUT | R/W | NO | N/A | Current status | |
| 7Ch | STATUS_INPUT | R/W | NO | N/A | Current status | |
| 7Dh | STATUS_TEMPERATURE | R/W | NO | N/A | Current status | |
| 80h | STATUS_MFR_SPECIFIC | R/W | NO | N/A | Current status | |
| 88h | READ_VIN | R | NO | N/A | Measured input voltage on pin 4 VINSENM | |
| 89h | READ_IIN | R | NO | N/A | Measured input current over the external sensing resistor | |
| 8Bh | READ_VOUT | R | NO | N/A | Measured output voltage | |
| 8Ch | READ_IOUT | R | NO | N/A | Measured output current | |
| 8Dh | READ_TEMPERATURE_1 | R | NO | N/A | Measured Controller die temperature | |
| 97h | READ_PIN | R | NO | N/A | Calculated input power, the product of the measured input voltage and input current | |
| A0h | SYS_CFG_USER1 | R/W | YES | 10h | Operation mode under light load condition is DCM VOUT is controlled by SVID bus only Soft-stop feature is enabled VR Ready delay = 0 ms I ² C address is set by pin 29 pin strap detection | |
| A2h | I ² C_ADDR | R/W | YES | N/A | Bit[7] = 0b, reserved for TI usage I ² C address saved in NVM is 77h. However, after initial power-on, the effective I ² C address shown in this field is determined by the resistor on pin 29 | |
| A3h | SVID_ADDR | R/W | YES | 00h | Device address for SVID communication is set to 00h | |
| A4h | IMON_CAL | R/W | YES | 78h | IMON gain calibration = 0% IMON offset calibration = 0 A | |
| A5h | IIN_CAL | R/W | YES | 78h | IIN gain calibration = 0% IIN offset calibration = 0 A | |
| A6h | VOUT_CMD | R/W | YES | ABh Default VOUT setting saved in VOUT_CMD is 1.1V. T VOUT_CMD does not control VOUT unless VOUT_C 10b or 11b | | |
| A7h | VID_SETTING | R | NO | N/A | After initial power-on, this register shows a value reflecting the last commanded VOUT either from SVID bus or I^2C bus | |
| A8h | I ² C_OFFSET | R/W | YES | 00h | I ² C OFFSET = 0 mV | |
| A9h | COMP1_MAIN | R/W | YES | 4Ah | AC Gain = 2 AC Load Line = 7 | |
| AAh | COMP2_MAIN | R/W | YES | 19h | Integration gain = 2 Integration time constant = 4.25 μs Ramp Amplitude = 60 mV | |



Table 7-18. Supported I²C and Default Values (continued)

| Register address | Register Name | R/W | NVM | Default Value (Hex) | Default Behavior | |
|---------------------|--------------------------|--------|-----|------------------------|---------------------------------------------------------------------------------------------------------------------------------|--|
| ABh | COMP1_ALT | R/W | YES | 23h | This register is not activated in the TPS544C26 device and affects nothing. | |
| ACh | COMP2_ALT | R/W | YES | A2h | This register is not activated in the TPS544C26 device and affects nothing. | |
| | COMP3 | | | | Bit[7] = 0b, reserverd for TI usage | |
| | | | | | Force DCM during soft-start enable/disable bit = disabled | |
| | | | | | On-time during NOC (Negative OC) operation = longer | |
| ADh | | R/W | YES | 02h | ton_NOC | |
| | | | | | L _{OUT} (output inductor value) for current sensing circuit = 100 nH | |
| | | | | | DC Load Line = $0.75 \text{ m}\Omega$ | |
| AFh | DVS_CFG | R/W | YES | 06h | Dynamic voltage change fast slew rate configuration = 10 mV/µs | |
| | DVID_OFFSET | | | | DVID Up positive DAC offset = 0 mV | |
| B0h | | R/W | YES | 00h | DVID Down positive DAC offset = 0 mV | |
| B1h | REG_LOCK | w | YES | N/A | The user-accessible registers (not including B1h) are "write protected" and by default. User can still read back from registers | |
| B3h | PIN_SENSE_RES | R/W | YES | 05h | Input power sense resistor is $0.5 \text{ m}\Omega$. This also sets the Maximum IIN to 40 A with IIN_LSB = 0.15625 A | |
| | IOUT_NOC_LIMIT | | | | VOUT Fixed OV Fault threshold = 1.5 V | |
| D4h | | R/W | YES | 054 | VOUT Fixed OV Fault enable/disable bit = enabled | |
| B4h | | FC/ VV | TES | 05h | Negative OC limit = -15 A when ICC_MAX ≥ 15 A or -7.5 A | |
| | | | | | when ICC_MAX < 10 A | |
| B5h | USER_DATA_01 | R/W | YES | 00h | Bit[7:4]: For user to store manufacturer specific information | |
| B6h | USER_DATA_02 | R/W | YES | 00h | Bit[7:5]: For user to store manufacturer specific information | |
| BAh | STATUS1_SVID | R/W | YES | N/A | A direct copy of the bits of SVID STATUS_1 register | |
| BBh | STATUS2_SVID | R/W | YES | N/A | A direct copy of the bits of SVID STATUS_2 register | |
| BCh | CAPABILITY | R | NO | FBh | A direct copy of the bits of SVID CAPABILITY register | |
| BDh | EXT_CAPABILITY_VIDOMAX_H | R/W | YES | 04h | A direct copy of the bits of SVID VIDOMAX_H_CAPA register | |
| BEh | VIDOMAX_L | R/W | YES | B6h | 9-bit VIDoMAX = 1.155 V | |
| C0h | ICC_MAX | R/W | YES | 05h | ICC_MAX = 30 A | |
| C1h | TEMP_MAX | R/W | YES | 06h | TEMP_MAX = 125 °C while controls SVID "ThermAlert" bit | |
| | PROTOCOL_ID_SVID | | | | PROTOCOL_ID_SVID = 07h (VR13, VOUT step 5 mV) | |
| C2h | | R/W | YES | 63h | Vboot = 1.1 V | |
| | | | | | Respond to SVID All-call address both 0Eh and 0Fh | |
| C6h | VENDOR_ID | R | NO | 22h | SVID VENDOR_ID = 22h. This vendor ID is assigned to Texas Instruments by Intel, to identify the VR vendor. | |
| C8h | PRODUCT_ID | R | NO | 13h | TPS544C26 Product ID = 13h | |
| C9h | PRODUCT_REV_ID | R | NO | 02h | TPS544C26 current device revision = PG2.1 | |



7.5.2 Support of Intel SVID Interface

The TPS544C26 device supports Intel SVID interface (VR13 Mode). Details are described in this section.

The SVID address for a TPS544C26 device can be programmabled in (A3h) SVID_ADDR register, allowing address value from 00h to 0Dh.

The TPS544C26 device supports VR13 Mode SVID registers and also VIDoMAX register. The table below summarizes the SVID register initialization performed by TPS544C26 at each power-on. Any writeable register can be changed by the SVID host after initialization. Refer to the Intel documentation for more detailed description of the individual register functionality.

| Register Address | Register Name | R/W | Source or Behavior |
|------------------|------------------|-----|-------------------------------------------------------------------|
| 00h | VENDOR_ID | R | 22h |
| 01h | PROD_ID | R | Per I ² C register (C8h) PRODUCT_ID |
| 02h | PROD_REV | R | Per I ² C register (C9h) PROD_REV_ID |
| 05h | PROTOCOL_ID | R | Per I ² C register (C2h) PROTOCOL_ID_SVID[7:6] |
| 06h | CAPABILITY | R | FBh |
| 09h | VIDOMAX_H_CAPA | R | Per I ² C register (BDh) EXT_CAPABILITY_VIDOMAX_H[7:0] |
| 0Ah | VIDOMAX_L | R | Per I ² C register (BEh) VIDO_MAX_L[7:0] |
| 0Bh | VIN_FULLSCALE_H | R | 06h |
| 0Ch | VIN_FULLSCALE_L | R | 40h |
| 0Dh | VOUT_FULLSCALE_H | R | 0Ch |
| 0Eh | VOUT_FULLSCALE_L | R | 80h |
| 0Fh | ALLCALL_ACT | R/W | Per I ² C register (C2h) PROTOCOL_ID_SVID[1:0] |
| 10h | STATUS1 | R | Current status |
| 11h | STATUS2 | R | Current status |
| 12h | TEMPERATURE | R | Current status |
| 15h | IOUT_H | R | Current status |
| 16h | VOUT_H | R | Current status |
| 17h | VR_TEMP | R | Current status |
| 19h | IIN_H | R | Current status |
| 1Ah | VIN_H | R | Current status |
| 1Bh | PIN_H | R | Current status |
| 1Ch | STATUS2_LASTREAD | R | Current status |
| 20h | ICC_IN_MAX | R | FFh |
| 21h | ICC_MAX | R | Per I ² C register (C0h) ICC_MAX[2:0] |
| 22h | TEMP_MAX | R | Per I ² C register (C1h) TEMP_MAX[2:0] |
| 24h | SR_FAST | R | Per I ² C register (AFh) DVS_CFG[2:0] |
| 25h | SR_SLOW | R | Programmed by SVID register (2Ah) SLOW_SR_SEL_HC |
| 26h | VBOOT | R | Per I ² C register (C2h) PROTOCOL_ID_SVID[5:2] |
| 2Ah | SLOW_SR_SEL_HC | R/W | 02h |
| 2Bh | PS4_EXIT_LAT | R | 85h |
| 2Eh | PIN_MAX | R | Per I ² C register (6Bh) PIN_OP_WARN_LIMIT |
| 30h | VID_MAX | R/W | FFh |
| 31h | VID_SETTING | R | Current status |
| 32h | PWR_STATE | R | 00h |
| 33h | OFFSET | R/W | 00h |
| 34h | MULTI_VR_CONFIG | R/W | 01h |
| 3Ah | WP0 | R/W | 00h |
| 3Bh | WP1 | R/W | 00h |
| 3Ch | WP2 | R/W | 00h |
| 3Dh | WP3 | R/W | 00h |

Table 7-19. SVID Register Support (VR13 Mode)



Table 7-19. SVID Register Support (VR13 Mode) (continued)

| Register Address | Register Name | R/W | Source or Behavior |
|------------------|---------------|-----|--------------------|
| 56h | DIGOUT_STATUS | R | Current status |

The table below summarizes the SVID commands supported by TPS544C26.Refer to the Intel documentation for more detailed description of the individual command functionality.

Table 7-20. Supported SVID Command

| Command Code | Command | Supported by TPS544C26 |
|--------------|--------------|------------------------|
| 01h | SetVID_Fast | Yes |
| 02h | SetVID_Slow | Yes |
| 03h | SetVID_Decay | Yes |
| 04h | SetPS | Yes |
| 05h | SetRegAddr | Yes |
| 06h | SetRegData | Yes |
| 07h | GetReg | Yes |
| 09h | SetWP | Yes |

7.6 Register Maps

7.6.1 (01h) OPERATION

| CMD Address | 01h | | |
|--------------------|--------------------------|--|--|
| Write Transaction: | Write Byte | | |
| Read Transaction: | Read Byte | | |
| Format: | Unsigned Binary (1 byte) | | |
| NVM Back-up: | No | | |
| Updates: | On-the-fly | | |

The OPERATION command is used to enable or disable power conversion.

Return to Supported I²C and Default Values.

Figure 7-4. (01h) OPERATION Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------|---|----------|---|---|---|---|---|
| R/W | R | R | R | R | R | R | R |
| ON_OFF | | Reserved | | | | | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7 | ON_OFF | R/W | Ob | Enable/disable power conversion. Note that there can be several other requirements that must be satisfied before the power conversion can begin (for example, input voltages above UVLO thresholds). 0b: Disable power conversion. 1b: Enable power conversion. |
| 6:0 | Reserved | R | d000000b | Not used and always set to 0. |

Table 7-21. Register Field Descriptions





7.6.2 (02h) ON_OFF_CONFIG

| Register Address | 02h | | |
|--------------------|--------------------------|--|--|
| Write Transaction: | Write Byte | | |
| Read Transaction: | Read Byte | | |
| Format: | Unsigned Binary (1 byte) | | |
| NVM Back-up: | EEPROM | | |
| Updates: | On-the-fly | | |

The ON_OFF_CONFIG command configures the combination of enable pin input and serial bus commands needed to enable/disable power conversion. This includes how the unit responds when power is applied to PVIN.

Return to Supported I²C and Default Values.

Figure 7-5. (02h) ON_OFF_CONFIG Register Map

| | | | · · · = · | _ | J | | | |
|-----|---------------|-----|-----------|----------|----------|---|---|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| R/W | R/W | R/W | R | R | R | R | R | |
| | ON_OFF_CONFIG | | | Reserved | | | | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|---------------|--------|--------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:5 | ON_OFF_CONFIG | R/W | NVM | These bits determine the on-off mechanism as follow: 000b: Power conversion is always ON 001b: Turn power conversion ON/OFF by I ² C Operation Command only 010b: Turn power conversion ON/OFF by EN pin only 011b: The power conversion is not turned ON until commanded by the EN pin and OPERATION command. The power conversion can be turned OFF either commanded by the EN pin or OPERATION command 100b to 111b: Reserved. The device always acknowledges a write with this value but does not change the operation state. |
| 4:0 | Reserved | R | 00000b | Not used and always set to 0. |

Table 7-22. Register Field Descriptions

Attempts to write ON_OFF_CONFIG to any value other than those explicitly listed above will be considered invalid/unsupported data and cause the TPS544C26 to respond by flagging the appropriate status bits, and notifying the host according to the PMBus 1.3.1 Part II specification, section 10.9.3.



7.6.3 (03h) CLEAR_FAULTS

| CMD Address | 03h | |
|--------------------|------------|--|
| Write Transaction: | Send Byte | |
| Read Transaction: | N/A | |
| Format: | Data-less | |
| NVM Back-up: | No | |
| Updates: | On-the-fly | |

CLEAR_FAULTS is a command used to clear any fault bits that have been set. CLEAR_FAULTS is a write-only command with no data. Writing a "1" into bit[0] of this command clears all bits in all status registers. The bit clears itself after the write.

The CLEAR_FAULTS command does not cause a unit that has latched off for a fault condition to restart. If the fault is still present when the bit is cleared, the fault bit is immediately set again.

Return to Supported I²C and Default Values.

Figure 7-6. (03h) CLEAR_FAULTS Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|---|----------|---|---|---|---|---|---|--|
| W | W | W | W | W | W | W | W | |
| | Reserved | | | | | | | |



7.6.4 (15h) STORE_USER_ALL

| CMD Address | 15h |
|--------------------|----------------------------------------------------------------|
| Write Transaction: | Send Byte |
| Read Transaction: | N/A |
| Format: | Data-less |
| NVM Back-up: | No |
| Updates: | Not recommended for on-the-fly-use, but not explicitly blocked |

The STORE_USER_ALL command instructs the TPS544C26 device to copy the entire contents of the Operating Memory to the matching locations in the non-volatile User Store Memory. Any items in Operating Memory that do not have matching locations in the User Store Memory are ignored. Writing a "1" into bit[0] of this command executes the store operation. The bit clears itself after the write.

User must wait for at least 150 msec from executing this command before power can be turned off to make sure a successful write to NVM is executed. NVM store operation is not recommended while the output is enabled, although the user is not explicitly prevented from doing so, as interruption can result in a corrupted NVM. I²C commands issued during this time will be ignored. Following issuance of NVM store operations, TI recommends disabling regulation and waiting a minimum of 125 ms before continuing.

Return to Supported I²C and Default Values.

Figure 7-7. (15h) STORE_USER_ALL Register Map

| | | <u> </u> | | | <u> </u> | | | |
|---|----------|----------|---|---|----------|---|---|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| W | W | W | W | W | W | W | W | |
| | Reserved | | | | | | | |



7.6.5 (16h) RESTORE_USER_ALL

| CMD Address | 16h |
|--------------------|----------------------------------------------------------------------------|
| Write Transaction: | Send Byte |
| Read Transaction: | N/A |
| Format: | Data-less |
| NVM Back-up: | No |
| Updates: | Conversion Disable: on-the-fly. Conversion Enable: hardware update blocked |

The RESTORE_USER_ALL command instructs the the TPS544C26 device to copy the entire contents of the non-volatile User Store Memory to the matching locations in the Operating Memory. Any items in Operating Memory that do not have matching locations in the User Store Memory are ignored (for example the STATUS registers). This operation overwrite any value set through a pin detection after the last power-cycle, such as the I²C address set through the I²C_ADDR pin.

Writing a "1" into bit[0] of this command executes the restore operation. When acknowledged, the I²C serial interface is disabled while the restore takes place and all frames will be NACKed during that time. The bit clears itself after the write.

Note

Using the RESTORE_USER_ALL command while the SW switching is enabled is not allowed, meaning a NACK response is provided by the device. RESTORE_USER_ALL command can be executed after the SW switching is disabled.

Return to Supported I²C and Default Values.

Figure 7-8. (16h) RESTORE_USER_ALL Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|---|----------|---|---|---|---|---|---|--|
| W | W | W | W | W | W | W | W | |
| | Reserved | | | | | | | |



7.6.6 (33h) FREQUENCY_SWITCH

| CMD Address | 33h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |
| | |

FREQUENCY_SWITCH sets the switching frequency of the active device.

Return to Supported I²C and Default Values.

Figure 7-9. (33h) FREQUENCY_SWITCH Register Map

| | | <u> </u> | , | - | <u> </u> | | |
|---|---|----------|-----|---|----------|-----|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R/W | R/W |
| | | SEL | FSW | | | | |

| Table 7-23. | Register Field | d Descriptions |
|-------------|-----------------------|----------------|
| | rtogiotor i ion | |

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|--------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:2 | Reserved | R | 00000b | Not used and always set to 0. |
| 1:0 | SEL_FSW | R/W | NVM | 00b: switching frequency is set to 0.6 MHz 01b: switching frequency is set to 0.8 MHz 10b: switching frequency is set to 1.0 MHz 11b: switching frequency is set to 1.2 MHz |



7.6.7 (35h) VIN_ON

| CMD Address | 35h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The VIN_ON command sets the value of the PVIN input voltage, in Volts, at which the unit starts power conversion.

Return to Supported I²C and Default Values.

Figure 7-10. (35h) VIN_ON Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|---|---|---|---|---|-----|------|
| R | R | R | R | R | R | R/W | R/W |
| Reserved | | | | | | | I_ON |

LEGEND: R/W = Read/Write; R = Read only

Table 7-24. Register Field Descriptions

| Bit | Field | Access | Reset | Description | | |
|-----|----------|--------|---------|------------------------------------------------------------------------------|--|--|
| 7:2 | Reserved | R | 000000b | Not used and always set to 0. | | |
| 1:0 | PVIN_ON | R/W | NVM | 00b: ON threshold is PVIN = 10 V. | | |
| | | | | 01b: ON threshold is PVIN = 9 V | | |
| | | | | 10b: ON threshold is PVIN = 8 V | | |
| | | | | 11b: ON threshold is determined by both PVIN and VCC conditions. When this | | |
| | | | | option is selected, both PVIN > 2.55 V and VCC > 3.8 V conditions have to be | | |
| | | | | satisfied to enable the power conversion. | | |

Note that the PVIN_UVF condition in (7Ch) STATUS_INPUT register is masked until the sensed input voltage exceeds the VIN_ON threshold for the first time following a power-on reset. The EN pin toggles and NVM store or restore operations do not reset this masking.



7.6.8 (36h) VIN_OFF

| CMD Address | 36h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The VIN_OFF command sets the value of the PVIN input voltage, in Volts, at which the unit must stop power conversion. If the power conversion enable conditions as defined by (02h) ON_OFF_CONFIG are met and PVIN is less than the selected VIN_OFF threshold, the power conversion turns off and the PVIN_UVF bit in (7Ch) STATUS_INPUT is set.

Return to Supported I²C and Default Values.

| Figure 7-11. (36h) VIN_OFF Register Map | | | | | | | | | |
|-----------------------------------------|---|----------|---|----------|-----|-----|-----|--|--|
| 7 6 5 4 3 2 1 0 | | | | | | | | | |
| R | R | R | R | R | R/W | R/W | R/W | | |
| | | Reserved | | PVIN OFF | | | | | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description | | | |
|-----|----------|--------|--------|-------------------------------------------------------------------------------------------|--|--|--|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. | | | |
| 2:0 | PVIN_OFF | R/W | NVM | 000b: OFF threshold is PVIN = 4.2 V | | | |
| | | | | 001b: OFF threshold is PVIN = 9.5 V | | | |
| | | | | 010b: OFF threshold is PVIN = 8.5 V | | | |
| | | | | 011b: OFF threshold is PVIN = 7.5 V | | | |
| | | | | 100b: OFF threshold is PVIN = 6.5 V | | | |
| | | | | 101b: OFF threshold is PVIN = 5.5 V | | | |
| | | | | 110b: OFF threshold is PVIN = 4.2 V | | | |
| | | | | 111b: OFF threshold is determined by both PVIN and VDRV conditions. When | | | |
| | | | | this option is selected, either PVIN \leq 2.3 V or VDRV \leq 3.4 V disables the power | | | |
| | | | | conversion. | | | |

Table 7-25. Register Field Descriptions

While it is possible to set (36h) VIN_OFF threshold greater than (35h) VIN_ON threshold, it is not advisable and can produce rapid enabling and disabling of conversion and undesirable operation. Please set (35h) VIN_ON threshold always greater than (36h) VIN_OFF threshold.



7.6.9 (40h) VOUT_OV_FAULT_LIMIT

| CMD Address | 40h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The VOUT_OV_FAULT_LIMIT command sets the value of the output voltage sensed at the (VOSNS – GOSNS) pins that causes an output overvoltage fault. SEL_OVF bits set an overvoltage fault threshold relative to the current VOUT setting that is commanded by either SVID SetVID command or I²C (A6h) VOUT_CMD. The VOUT Tracking OVF function is activated after the soft-start ramp completes.

Following an overvoltage fault condition, the device responds according to (41h) VOUT_OV_FAULT_RESP. Due to the lack of an I²C alert pin, the TPS544C26 device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-12. (40h) VOUT_OV_FAULT_LIMIT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|------|-----|---|---|-----|-----|
| R | R | R | R | R | R | R/W | R/W |
| | | SEL_ | OVF | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-26. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|---------|-----------------------------------------------------------------------------------------------------------------------------------|
| 7:2 | Reserved | R | 000000b | Not used and always set to 0. |
| 1:0 | SEL_OVF | R/W | NVM | Sets the overvoltage fault threshold. 00b: VOUT Tracking OVF threshold = +100 mV 01b: VOUT Tracking OVF threshold = +150 mV |
| | | | | 10b: VOUT Tracking OVF threshold = +200 mV 11b: VOUT Tracking OVF threshold = +300 mV |



7.6.10 (41h) VOUT_OV_FAULT_RESPONSE

| CMD Address | 41h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The VOUT_OV_FAULT_RESPONSE command instructs the device on what action to take in response to an output overvoltage fault. Upon triggering the tracking overvoltage fault (a.k.a VOUT Tracking OVF), the TPS544C26 device responds according to the *RESTART* bit in this register, and the following actions are taken:

- Set the OVF bit in the (7Ah) STATUS_VOUT register.
- Enter continuous Negative Overcurrent (NOC) operation immediately, and the delay from the VOUT Tracking OVF detection circuit is minimized (less than 1 μs).
- Due to the lack of an I²C alert pin, the TPS544C26 device does not have a way to notify the host.

The selected Tracking OVF response in this VOUT_OV_FAULT_RESP register does not affect the response for a Fixed OVF event.

Return to Supported I²C and Default Values.

Figure 7-13. (41h) VOUT_OV_FAULT_RESPONSE Register Map

| | <u>v</u> | | | | <u> </u> | | |
|---|----------|-------|---|---------|----------|----------|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R/W | R | R | R |
| | Rese | erved | | RESTART | | Reserved | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-27. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:4 | Reserved | R | 0000b | Not used and always set to 0. |
| 3 | RESTART | R/W | NVM | VOUT Tracking OVF response selection 0b: Latch-off after the fault. A VCC power cycle or EN toggle can restart the power conversion. 1b: Automatically restart after a delay of 56 ms, without limitation on the number of restart attempts. |
| 2:0 | Reserved | R | 000b | Not used and always set to 0. |



7.6.11 (42h) VOUT_OV_WARN_LIMIT

| CMD Address | 42h | |
|--------------------|--------------------------|---|
| Write Transaction: | Write Byte | ļ |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | İ |
| NVM Backup: | EEPROM | İ |
| Updates: | On-the-fly | l |

The VOUT_OV_WARN_LIMIT command sets the value of the output voltage sensed at the (VOSNS – GOSNS) pins that causes an output voltage high warning. This value is typically less than the output overvoltage fault threshold. The SEL_OVW bits set an overvoltage warning threshold relative to the current VOUT setting that is commanded by either SVID SetVID command or I^2C (A6h) VOUT_CMD.

When the sensed output voltage exceeds the VOUT Tracking OVW threshold, the OVW bit in the (7Ah) STATUS_VOUT register is set. Due to the lack of an I^2C alert pin, the TPS544C26 device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-14. (42h) VOUT_OV_WARN_LIMIT Register Map

| | | <u> </u> | | | | | |
|---|------|----------|---|---|---|-----|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R/W | R/W |
| | SEL_ | OVW | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-28. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|---------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:2 | Reserved | R | 000000b Not used and always set to 0. | |
| 1:0 | SEL_OVW | R/W | NVM | Sets the overvoltage warning threshold. 00b: VOUT Tracking OVW threshold = +100 mV 01b: VOUT Tracking OVW threshold = +150 mV 10b: VOUT Tracking OVW threshold = +200 mV 11b: VOUT Tracking OVW threshold = +300 mV |



7.6.12 (43h) VOUT_UV_WARN_LIMIT

| CMD Address | 43h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The VOUT_UV_WARN_LIMIT command sets the value of the output voltage sensed at the (VOSNS – GOSNS) pins that causes an output voltage low warning. This value is typically less negative than the output undervoltage fault threshold. The SEL_UVW bits set an undervoltage warning threshold relative to the current VOUT setting that is commanded by either SVID SetVID command or I^2C (A6h) VOUT_CMD.

When the sensed output voltage falls below the VOUT Tracking UVW threshold, the UVW bit in the (7Ah) STATUS_VOUT register is set. Due to the lack of an I²C alert pin, the TPS544C26 device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-15. (43h) VOUT_UV_WARN_LIMIT Register Map

| | | 0 (| / – | | U | • | |
|---|---|------|-----|---|---|-----|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R/W | R/W |
| | | SEL_ | UVW | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-29. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|---------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:2 | Reserved | R | 000000b Not used and always set to 0. | |
| 1:0 | SEL_UVW | R/W | NVM | Sets the undervoltage warning threshold. 00b: VOUT Tracking UVW threshold = -100 mV 01b: VOUT Tracking UVW threshold = -150 mV 10b: VOUT Tracking UVW threshold = -200 mV 11b: VOUT Tracking UVW threshold = -300 mV |



7.6.13 (44h) VOUT_UV_FAULT_LIMIT

| CMD Address | 44h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The VOUT_UV_FAULT_LIMIT command sets the value of the output voltage sensed at the (VOSNS – GOSNS) pins that causes an output undervoltage fault. The SEL_UVF bits set an undervoltage fault threshold relative to the current VOUT setting that is commanded by either SVID SetVID command or I²C (A6h) VOUT_CMD. The VOUT Tracking UVF function is activated after the soft-start ramp completes.

When the undervoltage fault condition is triggered, the device responds according to (45h) VOUT_UV_FAULT_RESPONSE. Due to the lack of an I²C alert pin, the TPS544C26 device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-16. (44h) VOUT_UV_FAULT_LIMIT Register Map

| | | | <u> </u> | | | | | |
|---|----------|---|----------|---|---|---|------|-----|
| 7 | | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | | R | R | R | R | R | R/W | R/W |
| | Reserved | | | | | | SEL_ | UVF |

| Bit | Field | Access | Reset | Description | |
|-----|----------|--------|---------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|
| 7:2 | Reserved | R | 000000b | 000000b Not used and always set to 0. | |
| 1:0 | SEL_UVF | R/W | NVM | Sets the undervoltage fault threshold. 00b: VOUT Tracking UVF threshold = -150 mV 01b: VOUT Tracking UVF threshold = -200 mV 10b: VOUT Tracking UVF threshold = -200 mV 11b: VOUT Tracking UVF threshold = -300 mV | |



7.6.14 (45h) VOUT_UV_FAULT_RESPONSE

| CMD Address | 45h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The VOUT_UV_FAULT_RESPONSE command instructs the device on what action to take in response to an output undervoltage fault. Upon triggering the tracking undervoltage fault (a.k.a VOUT Tracking UVF), the TPS544C26 device responds according to the *RESTART* bit in this register, and the following actions are taken:

- Set the UVF bit in the (7Ah) STATUS VOUT register.
- Start the UVF Response Delay selected in this register. During the UVF Response Delay, if the output voltage (VOSNS – GOSNS) rises above the UVF threshold, thus not qualified for a UVF event, the UVF response delay timer resets to zero. When the VOUT drops below the UVF threshold again, the UVF response delay timer re-starts from zero.
- Due to the lack of an I²C alert pin, the TPS544C26 device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-17. (45h) VOUT_UV_FAULT_RESPONSE Register Map

| | J· | | | | J | | |
|---|------|-------|---|---------|----------|---------|----------|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R/W | R | R/W | R/W |
| | Rese | erved | | RESTART | Reserved | RESPONS | SE_DELAY |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|--------------------|--------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:4 | Reserved | R | 0000b | Not used and always set to 0. |
| 3 | RESTART | R/W | NVM | VOUT Tracking UVF response selection 0b: Latch-off after the fault. A VCC power cycle or EN toggle can restart the power conversion. 1b: Automatically restart after a delay of 56 ms, without limitation on the number of restart attempts. |
| 2 | Reserved | R | 0b | Not used and always set to 0. |
| 1:0 | RESPONSE _DELAY | R/W | NVM | VOUT Tracking UVF Response Delay selection 00b: UVF Response Delay = 2 μs 00b: UVF Response Delay = 16 μs 00b: UVF Response Delay = 64 μs 00b: UVF Response Delay = 256 μs |

Table 7-31. Register Field Descriptions



7.6.15 (46h) IOUT_OC_FAULT_LIMIT

| CMD Address | 46h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM or Pin Detection |
| Updates: | On-the-fly |

The IOUT_OC_FAULT_LIMIT command sets the value of the output current that causes the overcurrent detector to indicate an overcurrent fault condition. The thresholds selected here are compared to the sensed low-side valley current. See Overcurrent Limit and Low-side Current Sense for more details.

Return to Supported I²C and Default Values.

Figure 7-18. (46h) IOUT_OC_FAULT_LIMIT Register Map

| | | U (| _ / _ _ | | | • | |
|---|------|-------|----------------|-----|------|-----|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R/W | R/W | R/W | R/W |
| | Rese | erved | | | SEL_ | OCL | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:4 | Reserved | R | 0000b | Not used and always set to 0. |
| 3:0 | SEL_OCL | R/W | NVM | These bits select the I _{OUT} valley current limiting threshold. 0000b: Overcurrent limit (low-side valley sensing) = 10 A 0001b: Overcurrent limit (low-side valley sensing) = 12 A 0010b: Overcurrent limit (low-side valley sensing) = 15 A 0011b: Overcurrent limit (low-side valley sensing) = 19 A 0100b: Overcurrent limit (low-side valley sensing) = 20 A 0101b: Overcurrent limit (low-side valley sensing) = 25 A 0110b: Overcurrent limit (low-side valley sensing) = 26 A 0111b: Overcurrent limit (low-side valley sensing) = 30 A 1000b: Overcurrent limit (low-side valley sensing) = 33 A 1001b: Overcurrent limit (low-side valley sensing) = 35 A 1010b: Overcurrent limit (low-side valley sensing) = 39 A 1011b to 1111b: Overcurrent limit (low-side valley sensing) = 39 A |

Table 7-32. Register Field Descriptions



7.6.16 (4Fh) OT_FAULT_LIMIT

| CMD Address | 4Fh | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The OT_FAULT_LIMIT command sets the temperature of the unit, at which, it indicates an overtemperature fault condition. The unit of this command is degrees Celsius. This feature utilizes a digital comparator that compares the output of the IC TEMPERATURE telemetry to the fault threshold selected in this register.

The device response to an overtemperature event is described in (50h) OT_FAULT_RESPONSE.

Return to Supported I²C and Default Values.

| | | | <u> </u> | | <u> </u> | | |
|---|---|----------|----------|---------|----------|-----|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R/W | R/W | R/W |
| | | Reserved | | SEL_OTF | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-33. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|--------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. |
| 2:0 | SEL_OTF | R/W | NVM | These bits select the OT fault threshold which is compared with the output of the IC TEMP telemetry. 000b: OTF threshold = 115 °C 001b: OTF threshold = 120 °C 010b: OTF threshold = 125 °C 011b: OTF threshold = 130 °C 100b: OTF threshold = 135 °C 101b: OTF threshold = 140 °C 110b: OTF threshold = 145 °C 111b: OTF threshold = 150 °C |



7.6.17 (50h) OT_FAULT_RESPONSE

| CMD Address | 50h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The (50) OT_FAULT_RESPONSE command instructs the device on what action to take in response to an overtemperature fault. Upon triggering the overtemperature fault, the device responds per the *RESTART* bit in this register, and sets the *OTF_PROG* bit in the (7Dh) STATUS_TEMPERATURE register. Due to the lack of an I²C alert pin, the device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-20. (50h) OT FAULT RESPONSE Register Map

| | = | 3 | | | | | |
|---|------|-------|---|---------|---|----------|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R/W | R | R | R |
| | Rese | erved | | RESTART | | Reserved | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:4 | Reserved | R | 0000b | Not used and always set to 0. |
| 3 | RESTART | R/W | NVM | This bit selects the response to a programmable OT fault condition 0b: Latch-off after the fault. A VCC power cycle or EN toggle can restart the power conversion. 1b: Automatically restart after a delay of 56 ms, without limitation on the number of restart attempts. |
| 2:0 | Reserved | R | 000b | Not used and always set to 0. |

Table 7-34. Register Field Descriptions



7.6.18 (51h) OT_WARN_LIMIT

| CMD Address | 51h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The OT_WARN_LIMIT command sets the temperature of the unit, at which, it indicates an overtemperature warning alarm. The unit of this command is degrees Celsius. This feature utilizes a digital comparator that compares the output of the IC TEMPERATURE telemetry to the warning threshold selected in this register.

Upon triggering the overtemperature fault, the device sets the *OTW_PROG* bit in the (7Dh) STATUS_TEMPERATURE register. Due to the lack of an I²C alert pin, the TPS544C26 device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-21. (51h) OT_WARN_LIMIT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----------|---|---------|-----|-----|-----|
| R | R | R | R | R | R/W | R/W | R/W |
| | • | Reserved | | SEL_OTW | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-35. Register Field Descriptions

| Field | Access | Reset | Description |
|----------|----------|------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Reserved | R | 00000b | Not used and always set to 0. |
| SEL_OTW | R/W | NVM | These bits select the OT warning threshold which is compared with the output of the IC TEMP telemetry. 000b: OTW threshold = 85 °C 001b: OTW threshold = 95 °C 010b: OTW threshold = 100 °C 011b: OTW threshold = 105 °C 100b: OTW threshold = 110 °C 101b: OTW threshold = 115 °C 110b: OTW threshold = 125 °C 111b: OTW threshold = 135 °C |
| | Reserved | Reserved R | Reserved R 00000b |



7.6.19 (55h) VIN_OV_FAULT_LIMIT

| CMD Address | 55h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The VIN_OV_FAULT_LIMIT command sets the PVIN voltage, in volts, when a VIN_OV_FAULT is declared. The response to a detected VIN_OV_FAULT is latch-off always. (55h) VIN_OV_FAULT_LIMIT is typically used to stop switching in the event of excessive input voltage, which can result in over-stress damage to the power FETs due to ringing on the SW node. Upon triggering the PVIN overvoltage fault, the device sets the PVIN_OVF bit in the (7C) STATUS_INPUT register.

Due to the lack of an I²C alert pin, the device does not have a way to notify the host.

Return to Supported I²C and Default Values.

Figure 7-22. (55h) VIN_OV_FAULT_LIMIT Register Map

| | | 0 (| / | | I | | |
|---|---|-----|---|---|---|---|----------|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R | R/W |
| | • | | | | | | PVIN_OVF |

LEGEND: R/W = Read/Write; R = Read only

Table 7-36. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|---------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:1 | Reserved | R | 000000b | Not used and always set to 0. |
| 0 | PVIN_OVF | R/W | NVM | This bit selects the PVIN_OVF rising threshold. The falling threshold is always 13.5 V. 0b: PVIN_OVF rising threshold = 16.9 V 1b: PVIN_OVF rising threshold = 18.6 V |



7.6.20 (60h) TON_DELAY

| CMD Address | 60h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The TON_DELAY command sets the time, in milliseconds, from when a start condition is received (as programmed by the (02h) ON_OFF_CONFIG command) until the output voltage starts to rise.

Return to Supported I²C and Default Values.

Figure 7-23. (60h) TON_DELAY Register Map

| | | U | · · · | - 0 | | | |
|---|---|-------|-------|-----|---|-----|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R/W | R/W |
| | | TON_I | DELAY | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-37. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|---------------|--------|---------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:2 | Reserved | R | 000000b | Not used and always set to 0. |
| 1:0 | TON_DELA Y | R/W | NVM | These bits select the turn-on delay options before enabling the SW switching. 00b: TON_DELAY time = 0.5 ms 01b: TON_DELAY time = 1 ms 10b: TON_DELAY time = 1.5 ms 11b: TON_DELAY time = 2 ms |



7.6.21 (61h) TON_RISE

| CMD Address | 61h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM or Pin Detection |
| Updates: | On-the-fly |

The TON_RISE command sets the time, in milliseconds, from when the output starts to rise until the voltage has entered the regulation band, which effectively sets the slew rate of the reference DAC during the soft-start period. Note that the soft-start time is equal to TON_RISE selection only when the output voltage is controlled by SVID bus. The soft-start time varies from the TON_RISE selection when I²C_OFFSET is involved or (A6h) VOUT_CMD is used for boot up. See section Startup and Table 7-7 for more details.

Return to Supported I²C and Default Values.

Figure 7-24. (61h) TON_RISE Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----------|---|----------|-----|-----|-----|
| R | R | R | R | R | R/W | R/W | R/W |
| | | Reserved | | TON_RISE | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-38. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|--------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. |
| 2:0 | TON_RISE | R/W | NVM | These bits select the soft-start time options. 000b: TON_RISE time = 1 ms 001b: TON_RISE time = 2 ms 010b: TON_RISE time = 4 ms 011b: TON_RISE time = 8 ms 100b to 111b: TON_RISE time = 16 ms |



7.6.22 (64h) TOFF_DELAY

| CMD Address | 64h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The TOFF_DELAY command sets the time, in milliseconds, from when a stop condition is received (as programmed by the (02h) ON_OFF_CONFIG command) until the device starts the soft-stop operation. When the soft-stop feature is disabled through the *EN_SOFT_STOP* bit in (A0h) SYS_CFG_USER1 register, the TOFF_DELAY time is automatically set to 0 ms, thus the device stops switching (tri-state power FETs) immediately when a stop condition is received.

Return to Supported I²C and Default Values.

Figure 7-25. (64h) TOFF_DELAY Register Map

| 7 R | 0 D | D D | 4 B | 3 D | 2 | D/M | DAV |
|--------|--------|--------|-------------|--------------|---|-----|-----|
| ĸ | ĸ | ĸ | R/W TOFF | R/W DELAY | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-39. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------------|--------|---------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:2 | Reserved | R | 000000b | Not used and always set to 0. |
| 1:0 | TOFF_DEL AY | R/W | NVM | These bits select the turn-off delay options before starting soft-stop operation. When soft-stop feature is disabled the TOFF_DELAY is automatically set to 0 ms. 00b: TOFF_DELAY time = 0 ms 01b: TOFF_DELAY time = 1 ms 10b: TOFF_DELAY time = 1.5 ms 11b: TOFF_DELAY time = 2 ms |



7.6.23 (65h) TOFF_FALL

| CMD Address | 65h | | | |
|--------------------|--------------------------|--|--|--|
| Write Transaction: | Write Byte | | | |
| Read Transaction: | Read Byte | | | |
| Format: | Unsigned Binary (1 byte) | | | |
| NVM Backup: | EEPROM | | | |
| Updates: | On-the-fly | | | |

The TOFF_FALL command sets the time, in milliseconds, from the end of the turn-off delay time until the reference DAC is commanded to 0 mV. This command is used with the TPS544C26 device whose output can sink enough current to cause the output voltage to decrease at a controlled rate, which effectively sets the slew rate of the reference DAC during the soft-off period. The VOUT fall time is actually not equal to TOFF_FALL value since the device stops SW switching once the output voltage is discharged to 200 mV, and the fall time is more for setting the reference DAC slew rate. See Shutdown and Table 7-8 for more details.

Return to Supported I²C and Default Values.

Figure 7-26. (65h) TOFF_FALL Register Map

| | | J | - () - | | | | |
|---|---|------|---------|---|---|-----|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R/W | R/W |
| | | TOFF | _FALL | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-40. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|-----------|--------|---------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:2 | Reserved | R | 000000b | Not used and always set to 0. |
| 1:0 | TOFF_FALL | R/W | NVM | These bits select the soft-stop time option before disabling the SW switching and tri-state the power FETs. 00b: TOFF_FALL time = 0.5 ms 01b: TOFF_FALL time = 1 ms 10b: TOFF_FALL time = 2 ms 11b: TOFF_FALL time = 4 ms |



7.6.24 (6Bh) PIN_OP_WARN_LIMIT

| CMD Address | 6Bh | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |
| | | |

The PIN_OP_WARN_LIMIT command sets the value of the input power, in watts, that causes a warning that the input power is high. The PIN_MAX value which is the maximum input power threshold is always the same as PIN_OP_WARN_LIMIT value. This feature utilizes a digital comparator that compares the output of the PIN telemetry to the fault threshold selected in this register.

In response to the PIN_OP_WARN_LIMIT being exceeded, the device sets the PIN_OPW bit in the (7Ch) STATUS_INPUT register.

Return to Supported I²C and Default Values.

Figure 7-27. (6Bh) PIN_OP_WARN_LIMIT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----------|---|---------|-----|-----|-----|
| R | R | R | R | R | R/W | R/W | R/W |
| | | Reserved | | PIN_OPW | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-41. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|--------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. |
| 2:0 | PIN_OPW | R/W | NVM | These bits select the PIN_OPW and PIN_MAX thresholds. 000b: PIN_OPW = PIN_MAX = 510 W 001b: PIN_OPW = PIN_MAX = 480 W 010b: PIN_OPW = PIN_MAX = 420 W 011b: PIN_OPW = PIN_MAX = 360 W 100b: PIN_OPW = PIN_MAX = 300 W 101b: PIN_OPW = PIN_MAX = 240 W 110b: PIN_OPW = PIN_MAX = 180 W 111b: PIN_OPW = PIN_MAX = 120 W |



7.6.25 (7Ah) STATUS_VOUT

| CMD Address | 7Ah | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | No | |
| Updates: | On-the-fly | |

The STATUS_VOUT command returns one data byte with contents as follows. All supported bits can be cleared either by CLEAR_FAULTS, or individually by writing a "1" to the (7Ah) STATUS_VOUT register in their position. If a fault condition is still present when the corresponding bit is cleared, the fault bit is immediately set again.

Return to Supported I²C and Default Values.

Figure 7-28. (7Ah) STATUS_VOUT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|----------|----------|----------|---|---|---|---|
| R/W | R/W | R/W | R/W | R | R | R | R |
| VOUT_OVF | VOUT_OVW | VOUT_UVW | VOUT_UVF | 0 | 0 | 0 | 0 |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Bit Field Access Reset Description | | | | | |
|-----|------------------------------------|-----|-------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|
| 7 | VOUT_OVF | R/W | Ob | 0b: Latched flag indicating a VOUT OV fault has <i>not</i> occurred.1b: Latched flag indicating either a VOUT Fixed OV fault or a VOUT Tracking OV fault has occurred. | | |
| 6 | VOUT_ OVW | R/W | Ob | 0b: Latched flag indicating a VOUT Tracking OV warn has <i>not</i> occurred. 1b: Latched flag indicating a VOUT Tracking OV warn has occurred. | | |
| 5 | VOUT_ UVW | R/W | Ob | 0b: Latched flag indicating a VOUT Tracking UV warn has <i>not</i> occurred. 1b: Latched flag indicating a VOUT Tracking UV warn has occurred. | | |
| 4 | VOUT_UVF | R/W | 0b | 0b: Latched flag indicating a VOUT Tracking UV fault has <i>not</i> occurred.1b: Latched flag indicating a VOUT Tracking UV fault has occurred. | | |
| 3:0 | Not supported | R | 0000b | Not supported and always set to 0. | | |

Table 7-42. Register Field Descriptions



7.6.26 (7Bh) STATUS_IOUT

| CMD Address | 7Bh |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | No |
| Updates: | On-the-fly |

The STATUS_IOUT command returns one data byte with contents as follows. All supported bits can be cleared either by CLEAR_FAULTS, or individually by writing a "1" to the (7Bh) STATUS_IOUT register in their position. If a fault condition is still present when the corresponding bit is cleared, the fault bit is immediately set again.

Return to Supported I²C and Default Values.

Figure 7-29. (7Bh) STATUS_IOUT Register Map

| | | | · · · | _ | • • | | |
|----------|-----------|---|-------|---|-----|---|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R/W | R/W | R | R | R | R | R | R |
| IOUT_OCL | IOUT_OCUV | 0 | 0 | 0 | 0 | 0 | 0 |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description | | | |
|-----|------------------|--------|---------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|
| 7 | IOUT_OCL | R | 0b | 0b: Latched flag indicating low-side valley OC limit has <i>not</i> occurred.1b: Latched flag indicating low-side valley OC limit has occurred. | | | |
| 6 | IOUT_OCU V | R/W | Ob | 0b: Latched flag indicating both low-side valley OC limit and VOUT Tracking UV fault have <i>not</i> occurred. 1b: Latched flag indicating both low-side valley OC limit and VOUT Tracking UV fault have occurred. | | | |
| 5:0 | Not supported | R | 000000b | Not supported and always set to 0. | | | |

Table 7-43. Register Field Descriptions



7.6.27 (7Ch) STATUS_INPUT

| CMD Address | 7Ch |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | No |
| Updates: | On-the-fly |

The STATUS_INPUT command returns one data byte with contents as follows. All supported bits can be cleared either by CLEAR_FAULTS, or individually by writing a "1" to the (7Ch) STATUS_INPUT register in their position. If a fault condition is still present when the corresponding bit is cleared, the fault bit is immediately set again.

Return to Supported I²C and Default Values.

Figure 7-30. (7Ch) STATUS_INPUT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|---|---|----------|---|---|---|---------|
| R/W | R | R | R/W | R | R | R | R/W |
| PVIN_OVF | 0 | 0 | PVIN_UVF | 0 | 0 | 0 | PIN_OPW |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|------------------|--------|-------|-----------------------------------------------------------------------------------------------------------------------------------|
| 7 | PVIN_OVF | R/W | 0b | 0b: Latched flag indicating a PVIN OV fault has <i>not</i> occurred. 1b: Latched flag indicating a PVIN OV fault has occurred. |
| 6:5 | Not supported | R | 00b | Not supported and always set to 0. |
| 4 | PVIN_UVF | R/W | 0b | 0b: Latched flag indicating a PVIN UV fault has <i>not</i> occurred. 1b: Latched flag indicating a PVIN UV fault has occurred. |
| 3:1 | Not supported | R | 000b | Not supported and always set to 0. |
| 0 | PIN_OPW | R/W | 0b | 0b: Latched flag indicating a PIN OP event has <i>not</i> occurred. 1b: Latched flag indicating a PIN OP event has occurred. |

Table 7-44. Register Field Descriptions



7.6.28 (7Dh) STATUS_TEMPERATURE

| CMD Address | 7Dh |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | No |
| Updates: | On-the-fly |

The STATUS_TEMPERATURE command returns one data byte with contents as follows. All supported bits can be cleared either by CLEAR_FAULTS, or individually by writing a "1" to the (7Dh) STATUS_TEMPERATURE register in their position. If a fault condition is still present when the corresponding bit is cleared, the fault bit is immediately set again.

Return to Supported I²C and Default Values.

Figure 7-31. (7Dh) STATUS TEMPERATURE Register Map

| | | | , | - | | - | |
|----------|----------|---|---|---|---|---|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R/W | R/W | R | R | R | R | R | R |
| OTF_PROG | OTW_PROG | 0 | 0 | 0 | 0 | 0 | 0 |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|------------------|--------|---------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7 | OTF_PROG | R/W | Ob | 0b: Latched flag indicating an OT fault has <i>not</i> occurred. 1b: Latched flag indicating an OT fault has occurred on the Controller die. Note: A digital comparator on the Controller die is utilized to compare the output of the IC TEMP telemetry to the fault threshold selected in (4Fh) OT_FAULT_LIMIT register. This bit has no relationship with the overtemperature detection implemented on the Power Stage (PS) die. |
| 6 | OTW_PRO G | R/W | Ob | 0b: Latched flag indicating an OT warn has <i>not</i> occurred. 1b: Latched flag indicating an OT warn has occurred on the Controller die. Note: A digital comparator on the Controller die is utilized to compare the output of the IC TEMP telemetry to the warning threshold selected in (51h) OT_WARN_LIMIT register. This bit has no relationship with the overtemperature detection implemented on the Power Stage (PS) die. |
| 5:0 | Not supported | R | 000000b | Not supported and always set to 0. |

Table 7-45. Register Field Descriptions



7.6.29 (80h) STATUS_MFR_SPECIFIC

| CMD Address | 80h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | No | |
| Updates: | On-the-fly | |

The STATUS_MFR_SPECIFIC command returns one data byte with contents as follows. All supported bits, except *DCM* bit, can be cleared either by CLEAR_FAULTS, or individually by writing a "1" to the (80h) STATUS_MFR_SPECIFIC register in their position. If a fault condition is still present when the corresponding bit is cleared, the fault bit is immediately set again.

Bit[7] DCM is a LIVE bit updated by the analog detection circuit, which continuously monitors the output of the zero-cross comparator. During CCM operation, this bit shows a value of "0". Once the device enters DCM operation this bit is set showing a value of "1".

Return to Supported I²C and Default Values.

Figure 7-32. (80h) STATUS_MFR_SPECIFIC Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|------------|----------|-----------------|-----------------|-----|-------------------|----------|
| R | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| DCM | OTF_ANALOG | PS_FAULT | PS_COMM_W RN | RESTORE_ER R | NOC | PS_OTF_ANAL OG | VDRV_UVF |

LEGEND: R/W = Read/Write; R = Read only

| | Table 7-46. Register Field Descriptions | | | | | | | | |
|-----|-----------------------------------------|--------|-------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|--|--|
| Bit | Field | Access | Reset | Description | | | | | |
| 7 | DCM | R/W | 0b | A LIVE bit updated by the analog detection circuit, which continuously monitors the output of the zero-cross comparator. 0b: Un-latched flag indicating the the device is under CCM operation. 1b: Un-latched flag indicating the the device is under DCM operation. | | | | | |
| 6 | OTF_ANAL OG | R/W | Ob | 0b: Latched flag indicating an OT fault has <i>not</i> occurred.1b: Latched flag indicating an OT fault has occurred on the Controller die.Note: An analog comparator on the Controller die is utilized to compare the outputof the IC temperature sensing circuit to a fixed threshold (166 °C typical). This bithas no relationship with the overtemperature detection implemented on the PowerStage (PS) die. | | | | | |
| 5 | PS_FAULT | R/W | 0b | 0b: Latched flag indicating <i>no</i> fault has occurred on Power Stage (PS) die. 1b: Latched flag indicating at least one fault has occurred on the PS die. | | | | | |
| 4 | PS_COMM_ WRN | R/W | Ob | 0b: Latched flag indicating <i>no</i> error has occurred for the communications between the Controller and PS die. 1b: Latched flag indicating a communications error has occurred between the Controller and PS die. Note: A VCC reset (power cycle) is recommended when this bit is set. | | | | | |
| 3 | RESTORE_ ERR | R/W | 0b: | Ob: Latched flag indicating <i>no</i> error has occurred during the initial restore from NVM operation (copy the entire contents of the non-volatile User Store Memory to the matching locations in the Operating Memory). 1b: Latched flag indicating an error has occurred during the initial restore from NVM operation. Note: The restore operation mentioned here refers to the one-time restore operation during the initial power-on. This bit doesn't validate the RESTORE_USER_ALL operation. A VCC reset (power cycle) is recommended when this bit is set. | | | | | |

Table 7-46. Register Field Descriptions



| Table 7 16 | Pogistor Fig | d Descriptio | ne (continued) |
|-------------|--------------|----------------|----------------|
| Table 7-46. | Register Fie | ela Descriptio | ns (continued) |

| Bit | Field | Access | Reset | Description | |
|-----|----------|--------|-------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|
| 2 | NOC | R/W | 0b | 0b: Latched flag indicating no NOC operation has occurred. | |
| | | | | 1b: Latched flag indicating at least one cycle of NOC operation has occurred. | |
| 1 | PS_OTF_A | R/W | 0b | 0b: Un-latched flag indicating an OT fault has <i>not</i> occurred. | |
| | NALOG | | | 1b: Un-latched flag indicating an OT fault has occurred on the Power Stage (PS) | |
| | | | | die. | |
| | | | | Note: An analog comparator on the Power Stage die is utilized to compare the output of the IC temperature sensing circuit to a fixed threshold (166 °C typical). This bit has no relationship with the overtemperature detection implemented on the Controller die. | |
| 0 | VDRV_UVF | R/W | 0b | 0b: Latched flag indicating a VDRV UV fault has <i>not</i> occurred. | |
| | | | | 1b: Latched flag indicating a VDRV UV fault has occurred. | |



7.6.30 (88h) READ_VIN

| CMD Address | 88h | | | |
|--------------------|--------------------------|--|--|--|
| Write Transaction: | N/A | | | |
| Read Transaction: | Read Byte | | | |
| Format: | Unsigned Binary (1 byte) | | | |
| NVM Backup: | No | | | |
| Update Rate: | 190 µs | | | |
| Supported Range: | 8 V – 16 V | | | |
| | | | | |

The READ_VIN command returns input voltage in Volts. See Telemetry for more details.

Return to Supported I²C and Default Values.

Figure 7-33. (88h) READ_VIN Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | |
|----------|---|---|---|---|---|---|---|--|--|
| R | R | R | R | R | R | R | R | | |
| READ_VIN | | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-47. Register Field Descriptions

| Bit | Field | Access | Reset | Description | |
|-----|---------------|--------|------------------|---------------------------------------------------------------------------|--|
| 7:0 | READ_ VIN_ | R | Input voltage | Input voltage (on pin 4 VINSENM) reading. See Telemetry for more details. | |



7.6.31 (89h) READ_IIN

| CMD Address | 89h |
|--------------------|--------------------------------------|
| Write Transaction: | N/A |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | No |
| Update Rate: | 95 µs |
| Supported Range: | 0 A to 40 A (if PIN_SENSE_RES = 05h) |

The READ_IIN command returns the measured input current in Amperes. See Telemetry for more details.

Return to Supported I²C and Default Values.

Figure 7-34. (89h) READ_IIN Register Map

| | | U | · · / | | | | | |
|----------|---|---|-------|---|---|---|---|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| R | R | R | R | R | R | R | R | |
| READ_IIN | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-48. Register Field Descriptions

| Bit | : | Field | Access | Reset | Description |
|-----|---|----------|--------|-------------------|---------------------------------------------------------------------------------------------|
| 7:0 | | READ_IIN | R | Current Status | Input current (over the external sensing resistor) reading. See Telemetry for more details. |



7.6.32 (8Bh) READ_VOUT

| CMD Address | 8Bh | |
|--------------------|-------------------------------------------------------------|---|
| Write Transaction: | N/A | ļ |
| Read Transaction: | Read Byte | l |
| Format: | Unsigned Binary (1 byte) | ļ |
| NVM Backup: | No | l |
| Update Rate: | 190 µs | ļ |
| Supported Range | VOUT 5 mV step: up to 1.6 V VOUT 10 mV step: up to 3.2 V | |

The READ_VOUT command returns the actual, measured output voltage (VOSNS-GOSNS) in Volts. See Telemetry for more details.

Return to Supported I²C and Default Values.

| | Figure 7-35. (8Bh) READ_VOUT Register Map | | | | | | | | |
|---|-------------------------------------------|---|---|---|---|---|---|--|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | |
| R | R | R | R | R | R | R | R | | |
| | READ_VOUT | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-49. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|---------------|--------|-------------------|---------------------------------------------------------|
| 7:0 | READ_ VOUT | R | Current Status | Output voltage reading. See Telemetry for more details. |



7.6.33 (8Ch) READ_IOUT

| CMD Address | 8Ch |
|--------------------|---------------------------------|
| Write Transaction: | N/A |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | No |
| Update Rate: | 95 µs |
| Supported Range: | 0 A to 40 A (if ICC_MAX = 40 A) |

The READ_IOUT command returns the measured output current in Amperes. See Telemetry for more details.

Return to Supported I²C and Default Values.

Figure 7-36. (8Ch) READ_IOUT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----------|---|---|---|---|---|---|---|
| R | R | R | R | R | R | R | R |
| READ_IOUT | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-50. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|---------------|--------|-------------------|---------------------------------------------------------|
| 7:0 | READ_ IOUT | R | Current Status | Output current reading. See Telemetry for more details. |



7.6.34 (8Dh) READ_TEMPERATURE_1

| CMD Address | 8Dh | | | |
|--------------------|--------------------------|--|--|--|
| Write Transaction: | N/A | | | |
| Read Transaction: | Read Byte | | | |
| Format: | Unsigned Binary (1 byte) | | | |
| NVM Backup: | No | | | |
| Update Rate: | 190 µs | | | |
| Supported Range: | –40°C to 150°C | | | |
| | | | | |

The READ_TEMPERATURE_1 command returns the Controller die temperature in degrees Celsius. See Telemetry for more details.

Return to Supported I²C and Default Values.

Figure 7-37. (8Dh) READ_TEMPERATURE_1 Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|--------------------|---|---|---|---|---|---|---|--|
| R | R | R | R | R | R | R | R | |
| READ_TEMPERATURE_1 | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-51. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------------------------|--------|-------------------|--------------------------------------------------------------------|
| 7:0 | READ_TEM PERATURE _1 | R | Current Status | Controller die temperture reading. See Telemetry for more details. |



7.6.35 (97h) READ_PIN

| CMD Address | 97h |
|--------------------|-----------------------------------|
| Write Transaction: | N/A |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | No |
| Update Rate: | 95 µs |
| Supported Range: | 0 W to 510 W (if PIN_OPW = 510 W) |

The READ_PIN command returns the measured input power, in watts. See Telemetry for more details.

Return to Supported I²C and Default Values.

Figure 7-38. (97h) READ_PIN Register Map

| | | | <u> </u> | | • | | |
|----------|---|---|----------|---|---|---|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R | R | R |
| READ_PIN | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-52. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-------------------|------------------------------------------------------|
| 7:0 | READ_PIN | R | Current Status | Input power reading. See Telemetry for more details. |



7.6.36 (A0h) SYS_CFG_USER1

| Register Address | A0h |
|--------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Back-up: | EEPROM |
| Updates: | On-the-fly. Note that many of the fields in this register either require the output to be disabled to take effect or require (15h) STORE_USER_ALL then VCC reset. |

The SYS_CFG_USER1 command contains miscellaneous bits for the device configuration.

Return to Supported I²C and Default Values.

Figure 7-39. (A0h) SYS_CFG_USER1 Register Map

| | | | | | - J | | |
|------|-----------|-----|------------------|-------|------------|--------------------|-------------------|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| FCCM | VOUT_CTRL | | EN_SOFT_STO P | VRRDY | _DELAY | OVRD_SVID_A DDR | OVRD_I2C_AD DR |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|-----------------------------------|--------|-------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7 | FCCM ⁽¹⁾ | R/W | NVM | 0b: Discontinuous conduction mode (DCM) operation at light loads.1b: Forced continuous conduction mode (FCCM) operation at light loads. |
| 6:5 | VOUT_CTRL ⁽¹⁾ | R/W | NVM | 00b: Output voltage and offset are programmed through the SVID interface. Writes to I²C register (A6h) VOUT_CMD are always accepted but do not change the output voltage. Writes to (A8h) I²C_OFFST are always NACKed. 01b: Output voltage is programmed through the SVID interface and offset is programmed through the I²C interface (A8h) I²C_OFFST. Writes to SVID (33h) OFFSET register are always accepted but do not change the output voltage. 10b: Output voltage and offset are controlled via I²C register (A6h) VOUT_CMD and (A8h) I2C_OFFST, respectively. Writes to SVID (33h) OFFSET register or SetVID commands are always accepted but do not change the output voltage. 11b: Same as 10b. |
| 4 | EN_SOFT_STOP ⁽¹⁾ | R/W | NVM | 0b: The SW switching is turned off immediately (ignores TOFF_FALL (soft-stop) and TOFF_DELAY is automatically set to 0 ms). 1b: The SW switching is turned off after going through TOFF_DELAY and TOFF_FALL (soft-stop). |
| 3:2 | VRRDY_DELAY ⁽¹⁾ | R/W | NVM | Program the rising edge delay time from soft start complete to VRRDY pin going high: 00b: 0 ms 01b: 0.5 ms 10b: 1.0 ms 11b: 2.0 ms |
| 1 | OVRD_SVID_ADD R ⁽²⁾ | R/W | NVM | This bit is reserved for future usage. |
| 0 | OVRD_I2C_ADDR (2) | R/W | NVM | 0b: I ² C address is determined by pin-strapping on the I ² C_ADDR pin.1b: I ² C address is determined by NVM backup. |

Table 7-53. Register Field Descriptions

(1) Writes are always accepted and the data is updated; however, in order for this bit to take effect, the device's swtiching must be disabled, including the (02h) ON_OFF_CONFIG register cannot be set to "Always on" behavior.

(2) Writes are always accepted and the data is updated; however, in order for this bit to take effect, send a (15h) STORE_USER_ALL to store the new value to NVM then reset the VCC.



7.6.37 (A2h) I²C_ADDR

| Register Address | A2h |
|--------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Back-up: | EEPROM |
| Updates: | Update the I ² C_ADDR value, set the OVRD_I2C_ADDR bit, Section 7.6.4 then VCC reset are all required for the device to respond to a new I ² C address. |

The I²C_ADDR command reads the I²C device address when the address is determined by pin-strapping. When the $OVRD_I2C_ADDR$ bit is set the device address is set by the value written into this register. Update the I²C_ADDR value, set the OVRD_I2C_ADDR bit, execute (15h) STORE_USER_ALL then VCC reset are all required for the device to respond to a new I²C address

Return to Supported I²C and Default Values.

Figure 7-40. (A2h) I²C_ADDR Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|-----------------------|-----|-----|-----|-----|-----|-----|
| R | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| Reserved | I ² C_ADDR | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-54. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|-----------------------|--------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7 | Reserved | R | 0b | Reserved for TI usage. |
| 6:0 | I ² C_ADDR | R/W | NVM | These bits set the I ² C address. By default, the address is set through the resistor on the I ² C_ADDR pin as described in Setting the I ² C Address. The I ² C address can be changed through these bits together using the OVRD_I2C_ADDR bit. The OVRD_I2C_ADDR bit must be set to "1", stored to NVM and the VCC resets before the TPS544C26 will respond to the programmed new address. |



7.6.38 (A3h) SVID_ADDR

| CMD Address | A3h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The SVID_ADDR command sets the SVID address for the device.

Return to Supported I²C and Default Values.

Figure 7-41. (A3h) SVID_ADDR Register Map

| | | - | | | | | |
|---|------|-------|---|-----|-------|------|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R/W | R/W | R/W | R/W |
| | Rese | erved | | | SVID_ | ADDR | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-------|-------------------------------|
| 7:4 | Reserved | R | 0000b | Not used and always set to 0. |
| 3:0 | SVID_ADD | R/W | NVM | 0000b: SVID address = 00h |
| | R | | | 0001b: SVID address = 01h |
| | | | | 0010b: SVID address = 02h |
| | | | | 0011b: SVID address = 03h |
| | | | | 0100b: SVID address = 04h |
| | | | | 0101b: SVID address = 05h |
| | | | | 0110b: SVID address = 06h |
| | | | | 0111b: SVID address = 07h |
| | | | | 1000b: SVID address = 08h |
| | | | | 1001b: SVID address = 09h |
| | | | | 1010b: SVID address = 0Ah |
| | | | | 1011b: SVID address = 0Bh |
| | | | | 1100b: SVID address = 0Ch |
| | | | | 1101b: SVID address = 0Dh |
| | | | | 1110b: Reserved |
| | | | | 1111b: Reserved |

Table 7-55. Register Field Descriptions



7.6.39 (A4h) IMON_CAL

| CMD Address | A4h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Back-up: | EEPROM |
| Updates: | On-the-fly |

The IMON_CAL command contains 2 fields (Gain and Offset) for READ_IOUT (IMON) calibration.

Return to Supported I²C and Default Values.

Figure 7-42. (A4h) IMON_CAL Register Map

| | | U | . , | _ 0 | | | |
|-----|--------|---------|-----|-----|--------|--------|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| | IMON_G | AIN_CAL | | | IMON_O | FS_CAL | |

LEGEND: R/W = Read/Write; R = Read only

| Rit | Field | ٨٥٥٥٩٩ | | Iable 7-56. Register Field Descriptions Bit Field Access Reset Description | | | | | | | | | | |
|-------------------|---------------------------|---------------|--------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|--|--|--|--|--|--|--|
| Bit 7:4 | Field IMON_GAIN_CAL | Access R/W | Reset NVM | DescriptionDescriptionThese bits contains the READ_IOUT (IMON) gain calibration. This field gives flexibility to change the gain of nominal reporting by -3.5% to $+4\%$.0000b: IMON Gain Adjustment = -3.5% 0001b: IMON Gain Adjustment = -3.5% 0011b: IMON Gain Adjustment = -2.5% 0011b: IMON Gain Adjustment = -2.0% 0101b: IMON Gain Adjustment = -2.0% 0101b: IMON Gain Adjustment = -2.0% 0101b: IMON Gain Adjustment = -1.5% 0101b: IMON Gain Adjustment = -1.5% 0101b: IMON Gain Adjustment = -0.5% 0111b: IMON Gain Adjustment = -0.5% 0111b: IMON Gain Adjustment = $+0.5\%$ 1000b: IMON Gain Adjustment = $+0.5\%$ 1001b: IMON Gain Adjustment = $+1.0\%$ 1010b: IMON Gain Adjustment = $+1.5\%$ 1010b: IMON Gain Adjustment = $+2.0\%$ 1100b: IMON Gain Adjustment = $+2.5\%$ 1100b: IMON Gain Adjustment = $+3.0\%$ 1110b: IMON Gain Adjustment = $+3.5\%$ 1110b: IMON Gain Adjustment = $+3.5\%$ 1110b: IMON Gain Adjustment = $+3.5\%$ 1111b: IMON Gain Adjustment = $+3.5\%$ 1111b: IMON Gain Adjustment = $+3.5\%$ 1111b: IMON Gain Adjustment = $+4.0\%$ | | | | | | | | | | |

Table 7-56. Register Field Descriptions



| Bit | Field | Access | Reset | gister Field Descriptions (continued) Description |
|-----|--------------|--------|-------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 3:0 | IMON_OFS_CAL | R/W | NVM | These bits contains the READ_IOUT (IMON) offset calibration. This field gives flexibility to change the nominal reporting by -2.0 A to 1.75 A. However, special attention is needed when setting the offset adjustment to a negative value. The calculation from the combination of ADC conversion and calibration register input is not clamped at zero. When the calculated value of (ADC conversion result + calibration offset value) goes negative, the final reporting value rolls over to a large positive value (decreased from the maximum limit). For example, for a case of real $I_{OUT} = 0.5$ A, IMON offset adjutment = -1.0 A, ICC_MAX = 30 A, the final reporting value is not clamped at 0 A, instread, the reporting value shows +29.5 A. TI suggests using the calibration offset value) never goes negative, especially at minimum load case. 0000b - 0111b: Negative offset adjustment but NOT recommended to use if the minimum load case. 0000b - 0111b: Negative offset adjustment but NOT recommended to use if the minimum load (IOUT) is 0 A. Contact TI for details in case of negative offset adjustment needed. 1000b: IMON Offset Adjustment = $+0.25$ A 1010b: IMON Offset Adjustment = $+0.25$ A 1010b: IMON Offset Adjustment = $+0.25$ A 1100b: IMON Offset Adjustment = $+1.25$ A 1100b: IMON Offset Adjustment = $+1.25$ A 1110b: IMON Offset Adjustment = $+1.25$ A |



7.6.40 (A5h) IIN_CAL

| CMD Address | A5h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Back-up: | EEPROM |
| Updates: | On-the-fly |

The IIN_CAL command contains 2 fields (Gain and Offset) for READ_IIN calibration.

Return to Supported I²C and Default Values.

Figure 7-43. (A5h) IIN_CAL Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|--------|--------|-----|-----|--------|-------|-----|
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| | IIN_GA | IN_CAL | | | IIN_OF | S_CAL | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|--------------|--------|-------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:4 | IIN_GAIN_CAL | R/W | NVM | These bits contains the READ_IIN gain calibration. This field gives flexibility to change the gain of nominal reporting by -3.5% to $+4\%$. 0000b: IIN Gain Adjustment = -3.5% 0001b: IIN Gain Adjustment = -3.0% 0010b: IIN Gain Adjustment = -2.5% 0011b: IIN Gain Adjustment = -2.0% 0100b: IIN Gain Adjustment = -1.5% 0101b: IIN Gain Adjustment = -1.5% 0101b: IIN Gain Adjustment = -0.5% 0111b: IIN Gain Adjustment = -0.5% 0111b: IIN Gain Adjustment = $+0.5\%$ 1000b: IIN Gain Adjustment = $+1.5\%$ 1001b: IIN Gain Adjustment = $+1.5\%$ 1011b: IIN Gain Adjustment = $+2.5\%$ 1101b: IIN Gain Adjustment = $+2.5\%$ 1101b: IIN Gain Adjustment = $+2.5\%$ 1101b: IIN Gain Adjustment = $+3.0\%$ 1110b: IIN Gain Adjustment = $+3.5\%$ 1111b: IIN Gain Adjustment = $+3.5\%$ |

Table 7-57. Register Field Descriptions



| | Table 7-57. Register Field Descriptions (continued) | | | | | | | | | |
|-----|-----------------------------------------------------|--------|-------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|--|--|--|
| Bit | Field | Access | Reset | Description | | | | | | |
| 3:0 | IIN_OFS_CAL | R/W | NVM | These bits contains the READ_IIN offset calibration. This field gives flexibility to change the nominal reporting by -2.0 A to 1.75 A. However, special attention is needed when setting the offset adjustment to a negative value. The calculation from the combination of ADC conversion and calibration register input is not clamped at zero. When the calculated value of (ADC conversion result + calibration offset value) goes negative, the final reporting value rolls over to a large positive value (decreased from the maximum limit). For example, for a case of real $I_{IN} = 0.5$ A, IIN offset adjutment = -1.0 A, IIN_MAX = 32 A, the final reporting value is not clamped at 0 A, instread, the reporting value shows +31.5 A. TI suggests using the calibration offset value) never goes negative, especially at minimum IIN case. 0000b - 0111b: Negative offset adjustment but NOT recommended to use if the minimum IIN is 0 A. Contact TI for details in case of negative offset adjustment needed. 1000b: IIN Offset Adjustment = $+0.25$ A 1010b: IIN Offset Adjustment = $+0.75$ A 1100b: IIN Offset Adjustment = $+1.00$ A 1101b: IIN Offset Adjustment = $+1.25$ A 1100b: IIN Offset Adjustment = $+1.25$ A 1100b: IIN Offset Adjustment = $+1.25$ A 111b: IIN Offset Adjustment = $+1.75$ A 111b: IIN Offset Adjustment = $+1.75$ A 111b: IIN Offset Adjustment = $+1.75$ A | | | | | | |



7.6.41 (A6h) VOUT_CMD

| Register Address | A6h |
|--------------------|-----------------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | VID, either 5 mV/LSB or 10 mV/LSB |
| NVM Back-up: | EEPROM |
| Updates: | On-the-fly |

If the VOUT_CTRL bits in (A0h) SYS_CFG_USER1 are set to 10b, VOUT_CMD causes the device to set its output voltage to the commanded value. Output voltage changes due to VOUT_CMD occur at ¼ of the fast slew rate which is selected in (AFh) DVS_CFG register.

The VOUT step (LSB) is either 5 mV/LSB or 10 mV/LSB which is determined by *PROCOTOL_ID* bits in (C2h) PROTOCOL_ID_SVID register.

The device will NACK writes to VOUT_CMD during soft-start and soft-stop. The device will ACK writes to VOUT_COMMAND after soft-start has completed. After soft-start has completed, writes to VOUT_CMD are also allowed even if the output voltage is still transitioning to a previously programmed VOUT_CMD. The output voltage will immediately begin transitioning to the newly programmed VOUT_CMD at the ¹/₄ of the fast slew rate which is selected in (AFh) DVS_CFG register. The device does not wait for the prior transition to completed.

Return to Supported I²C and Default Values.

Figure 7-44. (A6h) VOUT_CMD Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|-----|----------|-----|-----|-----|-----|-----|-----|--|
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W | |
| | VOUT_CMD | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-58. Register Field Descriptions

| E | Bit | Field | Access | Reset | Description |
|---|-----|----------|--------|-------|------------------------------------------------------------------------------------------------------------|
| 7 | ':0 | VOUT_CMD | R/W | NVM | Sets the output voltage target via the I ² C interface. See Table 7-6 for the available values. |



7.6.42 (A7h) VID_SETTING

| CMD Address | A7h |
|--------------------|-----------------------------------|
| Write Transaction: | N/A |
| Read Transaction: | Read Byte |
| Format: | VID, either 5 mV/LSB or 10 mV/LSB |
| NVM Backup: | No |
| Update Rate: | 190 µs |
| Supported Range: | 8 V – 16 V |
| | |

The VID_SETTING command returns the last commanded VOUT level either from I²C or from SVID including Vboot. The reading in this register is "in sync" with the SVID (31h) VID_SETTING register. This register does not include any OFFSET contributions from either SVID or I²C space.

Return to Supported I²C and Default Values.

Figure 7-45. (A7h) VID_SETTING Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|-------------|---|---|---|---|---|---|---|--|
| R | R | R | R | R | R | R | R | |
| VID_SETTING | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-59. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|-----------------|--------|---------------------------|--------------------------------------------------------|
| 7:0 | VID_SETTI NG | R | Last commanded VOUT | These bits tells the last commanded VOUT (VID format). |



7.6.43 (A8h) I²C_OFFSET

| Register Address | A8h | |
|--------------------|------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | DIRECT | |
| NVM Back-up: | EEPROM | |
| Updates: | on-the-fly | |

The I²C_OFFSET is used to apply a fixed offset voltage to the output voltage command value. Output voltage changes due to I²C_OFFSET occur at ¼ of the fast slew rate which is selected in (AFh) DVS_CFG register..

The usage of I²C_OFFSET depends on the value of *VOUT_CTRL* in (A0h) SYS_CFG_USER1 register. See Table 7-4 for more details.

When the *PROTOCOL_ID* bits in (C2h) PROTOCOL_ID_SVID is 01b or 10b (VOUT step = 5 mV), the I^2C_OFFSET adds offset to the output voltage with the 0.5 mV/LSB. With a signed implementation, the offset can be programmed in a range of -64 mV to +63 mV.

When the *PROTOCOL_ID* bits in (C2h) PROTOCOL_ID_SVID is 00b or 11b (VOUT step = 10 mV), the I^2C_OFFSET adds offset to the output voltage with the 1.0 mV/LSB. With a signed implementation, the offset can be programmed in a range of -128 mV to +127 mV.

Return to Supported I²C and Default Values.

Figure 7-46. (A8h) I²C_OFFSET Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|-------------------------|-----|-----|-----|-----|-----|-----|-----|--|
| R | R/W | R/W | R/W | R/W | R/W | R/W | R/W | |
| I ² C_OFFSET | | | | | | | | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description | | | |
|-----|-------------------------|--------|-------|----------------------------------------------------------------------------------------------|--|--|--|
| 7:0 | I ² C_OFFSET | R/W | NVM | Output voltage offset with Direct format. | | | |
| | | | | VOUT step = 5 mV configuration: I ² C OFFSET is 0.5 mV/LSB, with a range of -64 | | | |
| | | | | mV to +63 mV. | | | |
| | | | | VOUT step = 10 mV configuration: I ² C OFFSET is 1.0 mV/LSB, with a range of | | | |
| | | | | -128 mV to +127 mV. | | | |

Table 7-60. Register Field Descriptions



7.6.44 (A9h) COMP1_MAIN

| CMD Address | A9h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Back-up: | EEPROM | |
| Updates: | On-the-fly | |

The COMP1_MAIN command contains 2 fields (AC Gain and AC Load Line) for the control loop compensation. See Loop Compensation for more details.

The AC_GAIN bits select the gain of the AC paths including the output voltage error and the load current step.

The AC Load Line (ACLL) bits set the AC response to an output voltage error.

Return to Supported I²C and Default Values.

Figure 7-47. (A9h) COMP1_MAIN Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|-----|------|-----|-----|-----|-----|-----|
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| | AC_ | GAIN | | | AC | LL | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|---------|--------|-------|---------------------------------------------------------------|
| 7:4 | AC_GAIN | R/W | NVM | These bits determine the AC gain setting. |
| | | | | 0000b: AC Gain = 0.3 |
| | | | | 0001b: AC Gain = 0.5 |
| | | | | 0010b: AC Gain = 1.0 |
| | | | | 0011b: AC Gain = 1.5 |
| | | | | 0100b: AC Gain = 2.0 |
| | | | | 0101b: AC Gain = 2.5 |
| | | | | 0110b: AC Gain = 3.0 |
| | | | | 0111b: AC Gain = 3.5 |
| | | | | 1000b: AC Gain = 4.0 |
| | | | | 1001b: AC Gain = 5.0 |
| | | | | 1010b: AC Gain = 6.0 |
| | | | | 1011b: AC Gain = 7.0 |
| | | | | 1100b to 1111b: Reserved. Do not set AC Gain to these values. |

Table 7-61. Register Field Descriptions



| | Table 7-61. Register Field Descriptions (continued) | | | | | | | | |
|-----|-----------------------------------------------------|--------|-------|-------------------------------------------------------|---|--|--|--|--|
| Bit | Field | Access | Reset | Description | | | | | |
| 3:0 | ACLL | R/W | NVM | These bits determine the AC Load Line (ACLL) setting. | | | | | |
| | | | | 0000b: ACLL = 0.5 | | | | | |
| | | | | 0001b: ACLL = 1.0 | | | | | |
| | | | | 0010b: ACLL = 1.5 | | | | | |
| | | | | 0011b: ACLL = 2.0 | | | | | |
| | | | | 0100b: ACLL = 2.5 | | | | | |
| | | | | 0101b: ACLL = 3.0 | | | | | |
| | | | | 0110b: ACLL = 3.5 | | | | | |
| | | | | 0111b: ACLL = 4.0 | | | | | |
| | | | | 1000b: ACLL = 5.0 | | | | | |
| | | | | 1001b: ACLL = 6.0 | | | | | |
| | | | | 1010b: ACLL = 7.0 | | | | | |
| | | | | 1011b: ACLL = 9.0 | | | | | |
| | | | | 1100b: ACLL = 10.0 | | | | | |
| | | | | 1101b: ACLL = 12.0 | l | | | | |
| | | | | 1110b: ACLL = 13.0 | | | | | |
| | | | | 1111b: ACLL = 15.0 | | | | | |



7.6.45 (AAh) COMP2_MAIN

| CMD Address | AAh | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Back-up: | EEPROM | |
| Updates: | On-the-fly | |

This COMP2_MAIN command contains 3 fields for configuring the internal integration circuit and the ramp generation circuit. See Loop Compensation for more details.

The INT_GAIN bits select the gain of the integration stage.

The INT_TIME bits set the time constant of the integration stage which affects the settling and response time following an output voltage error.

The RAMP bits select the amplitude of the internal-generated ramp.

Return to Supported I²C and Default Values.

Figure 7-48. (AAh) COMP2_MAIN Register Map

| | | J | <u> </u> | _ | 5 | | |
|----------|-----|-----|----------|-----|-----|------|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| INT_GAIN | | | INT_TIME | | | RAMP | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:6 | INT_GAIN | R/W | NVM | These bits selects the gain of the integration stage. 00b: integration stage gain = 2 01b: integration stage gain = 1.5 |
| | | | | 10b: integration stage gain = 1.3 10b: integration stage gain = 1 11b: integration stage gain = 0.5 |
| 5:3 | INT_TIME | R/W | NVM | These bits set the time constant of the integration stage which affects the settling and response time following an output voltage error. 000b: integration time constant = $0.25 \ \mu s$ 001b: integration time constant = $1.0 \ \mu s$ 010b: integration time constant = $3.0 \ \mu s$ 011b: integration time constant = $4.5 \ \mu s$ 100b: integration time constant = $6.25 \ \mu s$ 101b: integration time constant = $8.0 \ \mu s$ 110b: integration time constant = $10.0 \ \mu s$ 111b: integration time constant = $20.0 \ \mu s$ |
| 2:0 | RAMP | R/W | NVM | These bits select the amplitude of the internal-generated ramp. 000b: ramp amplitude = 40 mV 001b: ramp amplitude = 60 mV 010b: ramp amplitude = 80 mV 011b: ramp amplitude = 100 mV 100b: ramp amplitude = 120 mV 101b: ramp amplitude = 160 mV 110b: ramp amplitude = 200 mV 111b: ramp amplitude = 240 mV |

Table 7-62. Register Field Descriptions



7.6.46 (ABh) COMP1_ALT

| CMD Address | ABh | | | |
|--------------------|--------------------------|--|--|--|
| Write Transaction: | Write Byte | | | |
| Read Transaction: | Read Byte | | | |
| Format: | Unsigned Binary (1 byte) | | | |
| NVM Back-up: | EEPROM | | | |
| Updates: | On-the-fly | | | |

The COMP1_ALT command contains 2 *alternate* fields (AC Gain and AC Load Line) for the control loop compensation. This register is not activated in the TPS544C26 device and affects nothing.

Return to Supported I²C and Default Values.

Figure 7-49. (ABh) COMP1_ALT Register Map

| | | U | <u> </u> | _ 0 | | | |
|-----|-------|--------|----------|-----|------|------|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| | AC_GA | IN_ALT | | | ACLL | _ALT | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|-------------|--------|-------|-----------------------------------------------------------------|
| 7:4 | AC_GAIN_ALT | R/W | NVM | These bits determine the <i>alternate</i> AC gain setting. |
| | | | | 0000b: alternate AC Gain = 0.3 |
| | | | | 0001b: alternate AC Gain = 0.5 |
| | | | | 0010b: <i>alternate</i> AC Gain = 1.0 |
| | | | | 0011b: alternate AC Gain = 1.5 |
| | | | | 0100b: <i>alternate</i> AC Gain = 2.0 |
| | | | | 0101b: alternate AC Gain = 2.5 |
| | | | | 0110b: alternate AC Gain = 3.0 |
| | | | | 0111b: alternate AC Gain = 3.5 |
| | | | | 1000b: alternate AC Gain = 4.0 |
| | | | | 1001b: alternate AC Gain = 5.0 |
| | | | | 1010b: alternate AC Gain = 6.0 |
| | | | | 1011b: alternate AC Gain = 7.0 |
| | | | | 1100b to 1111b: Reserved. Do not set AC Gain to these values. |
| 3:0 | ACLL_ALT | R/W | NVM | These bits determine the alternate AC Load Line (ACLL) setting. |
| | | | | 0000b: alternate ACLL = 0.5 |
| | | | | 0001b: alternate ACLL = 1.0 |
| | | | | 0010b: alternate ACLL = 1.5 |
| | | | | 0011b: alternate ACLL = 2.0 |
| | | | | 0100b: alternate ACLL = 2.5 |
| | | | | 0101b: alternate ACLL = 3.0 |
| | | | | 0110b: alternate ACLL = 3.5 |
| | | | | 0111b: alternate ACLL = 4.0 |
| | | | | 1000b: alternate ACLL = 5.0 |
| | | | | 1001b: alternate ACLL = 6.0 |
| | | | | 1010b: alternate ACLL = 7.0 |
| | | | | 1011b: alternate ACLL = 9.0 |
| | | | | 1100b: alternate ACLL = 10.0 |
| | | | | 1101b: alternate ACLL = 12.0 |
| | | | | 1110b: alternate ACLL = 13.0 |
| | | | | 1111b: <i>alternate</i> ACLL = 15.0 |

Table 7-63. Register Field Descriptions



7.6.47 (ACh) COMP2_ALT

| CMD Address | ACh | ACh | | |
|--------------------|--------------------------|-----|--|--|
| Write Transaction: | Write Byte | | | |
| Read Transaction: | Read Byte | | | |
| Format: | Unsigned Binary (1 byte) | | | |
| NVM Back-up: | EEPROM | | | |
| Updates: | On-the-fly | | | |

This COMP2_ALT command contains 3 *alternate* fields for configuring the internal integration circuit and the ramp generation circuit. This register is not activated in the TPS544C26 device and affects nothing.

Return to Supported I²C and Default Values.

Figure 7-50. (ACh) COMP2_ALT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------|--------|-----|--------------|-----|-----|----------|-----|
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| INT_GA | NN_ALT | | INT_TIME_ALT | | | RAMP_ALT | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|--------------|--------|-------|-------------------------------------------------------------------------------------------------------------------------------------------|
| 7:6 | INT_GAIN_ALT | R/W | NVM | These bits selects the gain of the integration stage. |
| | | | | 00b: <i>alternate</i> integration stage gain = 2 |
| | | | | 01b: <i>alternate</i> integration stage gain = 1.5 |
| | | | | 10b: <i>alternate</i> integration stage gain = 1 |
| | | | | 11b: <i>alternate</i> integration stage gain = 0.5 |
| 5:3 | INT_TIME_ALT | R/W | NVM | These bits set the time constant of the integration stage which affects the settling and response time following an output voltage error. |
| | | | | 000b: <i>alternate</i> integration time constant = $0.25 \mu s$ |
| | | | | 001b: <i>alternate</i> integration time constant = $1.0 \ \mu s$ |
| | | | | 010b: <i>alternate</i> integration time constant = $3.0 \ \mu s$ |
| | | | | 011b: <i>alternate</i> integration time constant = $4.5 \mu s$ |
| | | | | 100b: <i>alternate</i> integration time constant = 6.25 μs |
| | | | | 101b: <i>alternate</i> integration time constant = 8.0 μs |
| | | | | 110b: <i>alternate</i> integration time constant = 10.0 μs |
| | | | | 111b: <i>alternate</i> integration time constant = 20.0 μs |
| 2:0 | RAMP_ALT | R/W | NVM | These bits select the amplitude of the internal-generated ramp. |
| | | | | 000b: <i>alternate</i> ramp amplitude = 40 mV |
| | | | | 001b: <i>alternate</i> ramp amplitude = 60 mV |
| | | | | 010b: <i>alternate</i> ramp amplitude = 80 mV |
| | | | | 011b: <i>alternate</i> ramp amplitude = 100 mV |
| | | | | 100b: <i>alternate</i> ramp amplitude = 120 mV |
| | | | | 101b: <i>alternate</i> ramp amplitude = 160 mV |
| | | | | 110b: <i>alternate</i> ramp amplitude = 200 mV |
| | | | | 111b: <i>alternate</i> ramp amplitude = 240 mV |

Table 7-64. Register Field Descriptions



7.6.48 (ADh) COMP3

| CMD Address | ADh | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The COMP3 command contains 4 fields for configuring the control loop.

The EN_SS_DCM bit sets the operation mode during the soft-start ramp. With value "1" on this bit, the device is forced to under DCM operation during the soft-start ramp. This bit doesn't control the operation mode after the soft-start ramp completes.

The SEL_NOC_TON bit selects the on-time reference for a NOC operation and thus determines the high-side FET conduction time during a NOC operation period. The on-time option selected here can help to avoid two undesired behaviors:

- For relatively low VOUT applications (such as VOUT = 1.1 V) using longer t_{ON_NOC} helps to prevent negative current run-away behavior. A NOC run-away behavior occurs when the inductor current moves more negatively during low-side FET conduction time than the movement during high-side conduction time. A NOC run-away behavior can lead to excessive stress on low-side FET and raise the concern of FET reliability.
- For applications with an extra large inductor current ripple (≥ 10 A) and the NOC threshold is set to a less negative value (for example NOC threshold = -7.5 A), the average current during the NOC operation is likely not that negative. This leads to insufficient discharge on VOUT and thus the load is stressed under the overvoltage condition for a longer period. To build sufficient negative current during the NOC operation, select the shorter t_{ON_NOC} to reduce the positive inductor current movement during the high-side on-time. A design example of this kind of case is VCCFA_EHV rail which can have the following configuration: PVIN = 12 V, VOUT = 1.8 V, f_{SW} = 1 MHz, L_{OUT} = 150 nH, ICC_MAX = 10 A, and NOC threshold = -7.5 A. To have sufficient discharge on VOUT, the design can either select the shorter t_{ON_NOC} or set ICC_MAX to 15 A so that the NOC threshold is more negative (such as -15 A).

These SEL_LO_CS bits select the L_{OUT} (output inductor value) for the current sensing circuit. The TPS544C26 IC utilizes the output inductor value entered here to build an accurate output from the current sense circuit. Please choose a value closest to the inductor that is used in a BOM. For any inductor value higher than 400 nH, set SEL_LO_CS to 11b. Selecting a value that is significantly different from the real inductor (for example, 400 nH used but 100 nH selected) can lead to an inaccurate current sense output which can cause unexpected control loop behavior and also an inaccurate READ_IOUT telemetry report.

The DCLL bits determine the DC load line setting. Select a DCLL value per the requirement from the processor or the load, otherwise, the load regulation can be out of expectation.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|----------|-----------|-----------------|-------|-------|-----|------|-----|--|
| R | R/W | R/W | R/W | R/W | R/W | R/W | R/W | |
| Reserved | EN_SS_DCM | SEL_NOC_TO N | SEL_L | .o_cs | | DCLL | | |

Return to Supported I²C and Default Values.

| Figure | 7-51. | (ADh) | COMP3 | Register | Map |
|--------|-------|-------|-------|----------|-----|
| | | (| | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-65. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-------|-------------------------------|
| 7 | Reserved | R | 0b | Not used and always set to 0. |



| Table 7-65. | Register Field | Descriptions | (continued) | |
|-------------|-----------------------|--------------|-------------|--|
| | | | | |

| Bit | Field | Access | Reset | Description |
|-----|-----------------|--------|-------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 6 | EN_SS_DC M | R/W | NVM | 0b: the operation during the soft-start ramp follows the configuration set by the <i>FCCM</i> bit in (A0h) SYS_CFG_USER1 register 1b: Forced DCM operation during the soft-start ramp |
| 5 | SEL_NOC_ TON | R/W | NVM | Select the on-time for NOC operation. See Table 7-66 for more details. |
| 4:3 | SEL_LO_C S | R/W | NVM | These bits select the L_{OUT} (output inductor value) for the current sensing circuit. 00b: L_{OUT} = 100 nH 01b: L_{OUT} = 200 nH 10b: L_{OUT} = 300 nH 11b: L_{OUT} = 400 nH |
| 2:0 | DCLL | R/W | NVM | These bits determine the DCLL setting. 000b: DCLL = 0 m Ω (VOUT maintains the regulation regardless of the load current) 001b: DCLL = 0.5 m Ω 010b: DCLL = 0.75 m Ω 011b: DCLL = 1.0 m Ω 100b: DCLL = 1.5 m Ω 101b: DCLL = 2.9 m Ω 110b: DCLL = 3.2 m Ω 111b: DCLL = 4.05 m Ω |

Table 7-66. High-side On Time During a NOC Operation

| PROTOCOL_ID in (C2h) PROTOCOL_ID_SVID | SEL_NOC_TON | Option | t _{on_Noc} (ns) |
|------------------------------------------|-------------|-----------------------------|-------------------------------------------------------------------------------|
| PROTOCOL_ID = 01b or 10b (VOUT | 1 | Shorter t _{ON_NOC} | Use: $t_{ON_NOC} = \frac{0.6 \text{ V}}{\text{PVIN} \times f_{SW}} $ (9) |
| step = 5 mV) | 0 | Longer t _{ON_NOC} | Use: $t_{ON_NOC} = \frac{1.6 \text{ V}}{\text{PVIN} \times f_{SW}} $ (10) |
| PROTOCOL_ID = 00b or 11b (VOUT | 1 | Shorter t _{ON_NOC} | Use: $t_{ON_NOC} = \frac{1.2 \text{ V}}{\text{PVIN} \times f_{SW}} $ (11) |
| step = 10 mV) | 0 | Longer t _{ON_NOC} | Use: $t_{ON_NOC} = \frac{3.2 V}{PVIN \times f_{SW}} $ (12) |



7.6.49 (AFh) DVS_CFG

| Register Address | AFh |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Back-up: | EEPROM |
| Updates: | on-the-fly |

The DVS_CFG sets the fast slew rate at which any output voltage changes per SVID SetVID-Fast command. This commanded rate of change does not apply when the unit is commanded to turn on or to turn off. The unit is $mV/\mu s$.

Return to Supported I²C and Default Values.

Figure 7-52. (AFh) DVS_CFG Register Map

| | | U | | | | | |
|---|----------|---|---|---|-----|---------|-----|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R | R/W | R/W | R/W |
| | Reserved | | | | | DVS_CFG | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-67. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|--------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. |
| 2:0 | DVS_CFG | R/W | | These bits select the Dynamic Voltage Scale (DVS) fast slew rate. Upon acknowledging a new value written into this register, the new slew rate value is loaded into SVID (24h) SR_FAST register immediately. See below table for details. |

Table 7-68. Dynamic Voltage Scale Fast Slew Rate Options

| DVS_CFG | DVS Fast Slew Rate (mV/µs) | | | | | |
|---------|---------------------------------------------|----------------------------------------------|--|--|--|--|
| DV3_CFG | PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV) | PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV) | | | | |
| 000 | 1.34 | 2.67 | | | | |
| 001 | 1.43 | 2.86 | | | | |
| 010 | 2.50 | 5.00 | | | | |
| 011 | 2.67 | 5.34 | | | | |
| 100 | 5.00 | 10.00 | | | | |
| 101 | 5.56 | 11.12 | | | | |
| 110 | 10.00 | 20.00 | | | | |
| 111 | 12.50 | 25.00 | | | | |



7.6.50 (B0h) DVID_OFFSET

| CMD Address | B0h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The DVID_OFFSET command contains 2 fields for configuring the DAC offset during a DVID transition. This Vout-referred offset is added only during a DVID transition (for example per SetVID or SetWP command). DVID_OFS_UP is used to compensate for delays in the feedback compensation network and reach the target value faster for DVID up scenario, and DVID_OFS_DOWN is implemented to prevent the output from ringing below the target for DVID down scenario. Note that:

- The offsets are used only when the selected DVID slew rate is Fast or Slow.
- The offsets are not used when the selected DVID slew rate is Decay nor for (A6h) VOUT_CMD changes via l²C.
- The offsets are not used during soft-start nor during soft-stop period.

Return to Supported I²C and Default Values.

Figure 7-53. (B0h) DVID_OFFSET Register Map

| | | | | | · · | | |
|----------|---|---|---|---------|--------|--------|--------|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R | R | R | R | R/W | R/W | R/W | R/W |
| Reserved | | | | DVID_OF | S_DOWN | DVID_C | DFS_UP |

LEGEND: R/W = Read/Write; R = Read only

Table 7-69. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|-------------------|--------|-------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:4 | Reserved | R | 0000b | Not used and always set to 0. |
| 3:2 | DVID_OFS_ DOWN | R/W | NVM | This positive offset is effectively a threshold: When the new VID target is lower than the current VOUT, the DAC starts counting down from its current value using the selected slew rate, and continues until the DAC reaches VID target + DVID_OFS_DOWN. At that point, the VOUT transition slew rate changes to ¼ of the selected slew rate until the actual VID target is reached. 00b: DVID_OFS_DOWN = 0 mV 01b: DVID_OFS_DOWN = 0 mV 10b: DVID_OFS_DOWN = 5 mV 10b: DVID_OFS_DOWN = 10 mV 11b: DVID_OFS_DOWN = 20 mV |
| 1:0 | DVID_OFS_ UP | R/W | NVM | This positive DAC offset is to be added when the new VID target is higher than the current VOUT. DVID_OFS_UP is added immediately to the current DAC count as the first step toward the new target, and as soon as the DAC count reaches the VID target, the DAC stops the ramp, and DVID_OFS_UP is no longer applied. 00b: DVID_OFS_UP = 0 mV 01b: DVID_OFS_UP = 5 mV 10b: DVID_OFS_UP = 10 mV 11b: DVID_OFS_UP = 20 mV |



7.6.51 (B1h) REG_LOCK

| CMD Address | B1h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | No |
| Updates: | On-the-fly |

The REG_LOCK command controls writing to the TPS544C26 device. The intent of this command is to provide protection against accidental changes. This command does NOT provide protection against deliberate or malicious changes to a configuration or operation of the device.

After power-on, the user accessible registers with write access are by default under "write protected" state, meaning the response to a write is NACK. The device always acknowledges a read command and responds the data byte accordantly. Only after writing the correct passcodes (multiple writes in the right order) into this REG_LOCK register, the user accessible registers are "unlocked" and the device acknowledges the next write commands. For a device under "unlock" state, the writable registers turn to "write protected" state again if one more write is sent to (B1h) REG_LOCK register, no matter with the correct passcode or wrong one. The user has to go through the complete passcode write combination to unlock the write protection again.

For a device under "unlock" state, VCC power cycling resets the device and the user accessible registers with write access are now under "write protected" state. A RESTORE_USER_ALL command does not change the state.

The expected response for a write into this REG_LOCK register is always NACK, no matter with a correct passcode or a wrong value. For security considerations, the passcodes are not listed in this datasheet. Please contact TI for more details.

All user accessible registers with write access are protected by this mechanism except below ones:

- (03h) CLEAR FAULTS
- (7Ah) STATUS VOUT
- (7Bh) STATUS IOUT
- (7Ch) STATUS INPUT
- (7Dh) STATUS TEMPERATURE
- (80h) STATUS MFR
- (A2h) I2C ADDR, bit[7] this bit is reserved for TI usage and always under write protection
- (B1h) REG_LOCK

Return to Supported I²C and Default Values.

Figure 7-54. (B1h) REG_LOCK Register Map

| | | U | · · · | | | | |
|---|---|---|-------|------|---|---|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| W | W | W | W | W | W | W | W |
| | | | Pass | code | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-70. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|----------|-----------------------------------------------------|
| 7:0 | Passcode | W | 0000000b | Write the passcodes to unlock the write protection. |



7.6.52 (B3h) PIN_SENSE_RES

| CMD Address | B3h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The PIN_SENSE_RES command selects the external input current/power sense resistor value and related configurations. The supported sensing resistor value ranges from 0.25 m Ω to 4 m Ω .

Return to Supported I²C and Default Values.

Figure 7-55. (B3h) PIN_SENSE_RES Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|---|---|---|---|-----|---------------|-----|
| R | R | R | R | R | R/W | R/W | R/W |
| Reserved | | | | | I | PIN_SENSE_RES | 3 |

LEGEND: R/W = Read/Write; R = Read only

Table 7-71. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|-------------------|--------|--------|-----------------------------------------------------------------------------------------------------------------------------|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. |
| 2:0 | PIN_SENSE _RES | R/W | NVM | These bits select the external sensing resistor used for input current/power measurement. See below table for more details. |

Table 7-72. Input Current/Power Sense Resistor Value and IIN_MAX

| PIN_SENSE_RES | R _{SENSE} used in a BOM (mΩ) | Internal Gain (V/V) | LIIN_MAX (A) | IIN LSB (A) |
|---------------|------------------------------------------|---------------------|--------------|-------------|
| 000 | 4 | 12.5 | 16 | 0.0625 |
| 001 | 3 | 12.5 | 21.3 | 0.0833 |
| 010 | 2 | 25 | 16 | 0.0625 |
| 011 | 1 | 20 | 40 | 0.15625 |
| 100 | 1 | 25 | 32 | 0.125 |
| 101 | 0.5 | 40 | 40 | 0.15625 |
| 110 | 0.5 | 50 | 32 | 0.125 |
| 111 | 0.25 | 50 | 64 | 0.250 |



7.6.53 (B4h) IOUT_NOC_LIMIT

| CMD Address | B4h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |

The IOUT_NOC_LIMIT command contains 3 fields for configuring the VOUT Fixed OVF and Neagive Overcurrent (NOC) limit selection.

The SEL_FIX_OVF bit sets the value of the output voltage measured at the (VOSNS – GOSNS) pins that causes an output overvoltage fault. The Fixed OVF function sets a constant overvoltage threshold that has no relationship to the current VOUT setting. The VOUT Fixed OVF is active as soon as the TPS544C26 device completes its power-on reset, even if the output conversion is disabled.

Following a Fixed OVF condition, the device always latches OFF high-side MOSFET and latches ON low-side MOSFET. The response setting in (41h) VOUT_OV_FAULT_RESP register does not affect the response for a Fixed OVF condition.

The VOUT Fixed OVF feature can be disabled through the *EN_FIX_OVF* bit.

The NOC threshold which scales with ICC_MAX setting (see (C0h) ICC_MAX) is selected by SEL_NOC field.

Return to Supported I²C and Default Values.

Figure 7-56. (B4h) IOUT_NOC_LIMIT Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|---|---|---|-------------|------------|------|-----|
| R | R | R | R | R/W | R/W | R/W | R/W |
| Reserved | | | | SEL_FIX_OVF | EN_FIX_OVF | SEL_ | NOC |

LEGEND: R/W = Read/Write; R = Read only

Table 7-73. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|-----------------|--------|-------|-----------------------------------------------------------------------------------------------------|
| 7:4 | Reserved | R | 0000b | Not used and always set to 0. |
| 3 | SEL_FIX_O VF | R/W | NVM | Select the VOUT Fixed OVF thresholds. See details on Table 7-74. |
| 2 | EN_FIX_OV F | R/W | NVM | 0b: Enable the VOUT Fixed OVF 1b: Disable the VOUT Fixed OVF |
| 1:0 | SEL_NOC | R/W | NVM | Select the Negative Overcurrent limits which scale with ICC_MAX setting. See details on Table 7-75. |

Table 7-74. VOUT Fixed OV Fault Thresholds

| PROTOCOL_ID in (C2h) PROTOCOL_ID_SVID | SEL_FIX_OVF[1] in (B4h) IOUT_NOC_LIMIT | VOUT Fixed OVF threshold (V) |
|----------------------------------------------|-------------------------------------------|------------------------------|
| PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV) | 0 | 1.5 |
| PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV) | 1 | 1.8 |
| PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV) | 0 | 2.4 |
| PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV) | 1 | 3.0 |



Table 7-75. Negative Overcurrent Limits

| SEL_NOC[1:0] | Negative Overcurrent Limits (A) | | | | |
|--------------|---------------------------------|----------------|--|--|--|
| | ICC_MAX ≥ 15 A | ICC_MAX ≤ 10 A | | | |
| 00 | -21 | -11.3 | | | |
| 01 | -16 | -8.7 | | | |
| 10 | -12.8 | -7.2 | | | |
| 11 | -10.8 | -6.2 | | | |



7.6.54 (B5h) USER_DATA_01

| CMD Address | B5h |
|--------------------|--------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | EEPROM |
| Updates: | On-the-fly |
| | |

The USER_DATA_01 command provides memory for users to store manufacturer specific information. User chooses the format and data value.

Return to Supported I²C and Default Values.

Figure 7-57. (B5h) USER_DATA_01 Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------------|-----|-----|-----|------|-------|---|---|
| R/W | R/W | R/W | R/W | R | R | R | R |
| USER_DATA_01 | | | | Rese | erved | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-76. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|------------------|--------|-------|-------------------------------------------------|
| 7:4 | USER_DAT A_01 | R | NVM | User to store manufacturer specific information |
| 3:0 | Reserved | R | 0000b | Not used and always set to 0. |



7.6.55 (B6h) USER_DATA_02

| CMD Address | B6h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The USER_DATA_02 command provides memory for users to store manufacturer specific information. User chooses the format and data value.

Return to Supported I²C and Default Values.

Figure 7-58. (B6h) USER_DATA_02 Register Map

| | | | | | • | | |
|-----|--------------|-----|---|---|----------|---|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| R/W | R/W | R/W | R | R | R | R | R |
| | USER_DATA_02 | | | | Reserved | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-77. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|------------------|--------|--------|-------------------------------------------------|
| 7:5 | USER_DAT A_02 | R/W | NVM | User to store manufacturer specific information |
| 4:0 | Reserved | R | 00000b | Not used and always set to 0. |



7.6.56 (BAh) STATUS1_SVID

| CMD Address | BAh | |
|--------------------|--------------------------|--|
| Write Transaction: | N/A | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |

The STATUS1_SVID command contains direct copies of the bits of SVID (10h) STATUS_1 register. When a bit in the SVID (10h) STATUS_1 register is cleared via the SVID bus, the corresponding bit in I^2C (BAh) STATUS1_SVID register also get cleared. There is no separate clear mechanism for the bits in BAh register via the I^2C bus.

Return to Supported I²C and Default Values.

Figure 7-59. (BAh) STATUS1_SVID Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------------------|----------|---|---|--------------|-------------|------------|------------|
| R | R | R | R | R | R | R | R |
| READ_STATUS 2 | Reserved | | | VID_DAC_High | IccMaxAlert | ThermAlert | VR_Settled |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|------------------|--------|-------------------|--------------------------------------------------------|
| 7 | READ_STA TUS2 | R | Current status | Defined by Intel. Refer to Intel document for details. |
| 6:4 | Reserved | R | 000b | Not supported and always set to 0. |
| 3 | VID_DAC_H igh | R | Current status | Defined by Intel. Refer to Intel document for details. |
| 2 | IccMaxAlert | R | Current status | Defined by Intel. Refer to Intel document for details. |
| 1 | ThermAlert | R | Current status | Defined by Intel. Refer to Intel document for details. |
| 0 | VR_Settled | R | Current status | Defined by Intel. Refer to Intel document for details. |

Table 7-78. Register Field Descriptions



7.6.57 (BBh) STATUS2_SVID

| CMD Address | BBh | |
|--------------------|--------------------------|--|
| Write Transaction: | N/A | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |

The STATUS2_SVID command contains direct copies of the bits of SVID (11h) STATUS_2 register. When a bit in the SVID (11h) STATUS_2 register is cleared via the SVID bus, the corresponding bit in I^2C (BBh) STATUS2_SVID register also get cleared. There is no separate clear mechanism for the bits in BBh register via the I^2C bus.

Return to Supported I²C and Default Values.

Figure 7-60. (BBh) STATUS2_SVID Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----------|---|--------------------|----------------|-----------------|---|
| R | R | R | R | R | R | R | R |
| | | Reserved | | SVID_OCL_LA TCH | SVID_frame_err | SVID_parity_err | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description | | | | |
|-----|---------------------|--------|-------------------|--------------------------------------------------------|--|--|--|--|
| 7:3 | Reserved | R | 00000b | Not supported and always set to 0. | | | | |
| 2 | SVID_OCL_ LATCH | R | Current status | Defined by Intel. Refer to Intel document for details. | | | | |
| 1 | SVID_frame _err | R | Current status | Defined by Intel. Refer to Intel document for details. | | | | |
| 0 | SVID_parity _err | R | Current status | Defined by Intel. Refer to Intel document for details. | | | | |

Table 7-79. Register Field Descriptions



7.6.58 (BCh) CAPABILITY

| CMD Address | BCh |
|--------------------|--------------------------|
| Write Transaction: | N/A |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |

The CAPABILITY command contains direct copies of the bits of SVID (06h) CAPABILITY register, which indicates telemetry capabilities of the part. This register is read-only.

Return to Supported I²C and Default Values.

Figure 7-61. (BCh) CAPABILITY Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------|------|-----|-----|-----|------|------|-------|
| R | R | R | R | R | R | R | R |
| IOUT | TEMP | PIN | VIN | IIN | POUT | VOUT | VR13+ |

LEGEND: R/W = Read/Write; R = Read only

Table 7-80. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|-------|--------|-------|-------------------------------------------------------------------|
| 7 | IOUT | R | 1b | 1b: IOUT telemetry is supported |
| 6 | TEMP | R | 1b | 1b: TEMP telemetry is supported |
| 5 | PIN | R | 1b | 1b: PIN telemetry is supported |
| 4 | VIN | R | 1b | 1b: VIN telemetry is supported |
| 3 | IIN | R | 1b | 1b: IIN telemetry is supported |
| 2 | POUT | R | 0b | 0b: POUT telemetry is NOT supported |
| 1 | VOUT | R | 1b | 1b: VOUT telemetry is supported |
| 0 | VR13+ | R | 1b | 1b: The output current telemetry is supported in the VR13+ format |



7.6.59 (BDh) EXT_CAPABILITY_VIDOMAX_H

| CMD Address | BDh |
|--------------------|---------------------------------------------------------------------------------------------------------------------------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Backup: | Bit[7:1]: No Bit[0]: Yes |
| Updates: | Bit[0] only: On-the-fly when the power conversion is disabled. A write is not allowed (NACK response) when the power conversion is enabled. |

The EXT_CAPABILITY_VIDOMAX_H command contains direct copies of the bits of SVID (09h) VIDOMAX_H_CAPA register except bit[0]. The lowest bit (bit[0]) is MSB of 9-bit VIDo_MAX value and the user can read and write into this bit. See more details in (BEh) VIDO_MAX_L register. The rest 7 bits in this register indicates the extended capabilities of the part. These 7 bits are read-only.

Return to Supported I²C and Default Values.

Figure 7-62. (BDh) EXT_CAPABILITY_VIDOMAX_H Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|----------|------|------|---------|----------|----------|-------------|
| R | R | R | R | R | R | R | R/W |
| PsysWarn | IMON_CAL | DFDS | DFDV | HI_PRES | lccInMax | Reserved | VIDo_MAX[8] |

LEGEND: R/W = Read/Write; R = Read only

Table 7-81. Register Field Descriptions

| Bit | Field | Access | Reset | Description | |
|-----|-----------------|--------|-------|-----------------------------------------------------------------------------|--|
| 7 | PsysWarn | R | 0b | 0b: PsysWarn is NOT supported | |
| 6 | IMON_CAL | R | 0b | 0b: SVID IMON_CAL is NOT supported | |
| 5 | DFDS | R | 0b | 0b: DFDS function is NOT supported | |
| 4 | DFDV | R | 0b | 0b: DFDV function is NOT supported | |
| 3 | HI_PRES | R | 0b | 0b: HI_PRES telemetry is NOT supported | |
| 2 | IccInMax | R | 0b | 1b: IccInMax is supported for IIN telemetry | |
| 1 | Reserved | R | 0b | Not used and always set to 0. | |
| 0 | VIDo_MAX[8] | R/W | NVM | MSB of 9-bit VIDo_MAX value. See more details in (BEh) VIDO_MAX_L register. | |



7.6.60 (BEh) VIDOMAX_L

| Register Address | BEh |
|--------------------|--------------------------------------------------------------------------------------------------------------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Back-up: | EEPROM |
| Updates: | On-the-fly when the power conversion is disabled. A write is not allowed (NACK response) when the power conversion is enabled. |

The VIDOMAX L command together with the bit[0] in (BDh) EXT CAPABILITY VIDOMAX H forms a 9-bit register to set the maximum value of (VID+Offset) allowed via SVID. Setting the 9-bit VIDo MAX register to 17E (hex) value reaches the maximum possible (VID+Offset) value with 8-bit register for each (VID unsigned, offset signed).

Exceeding VIDo_MAX with (VID + offset) causes a REJ (Reject) response for individual rail SVID requests and a NACK response for all-call SVID requests.

When a write to this register is attempted, the VIDOMAX L value combined with VIDo MAX[8] value (bit[0] in (BDh) EXT_CAPABILITY_VIDOMAX_H register) must satisfy a range check:

- If the combined value is not greater than 0, the write is NACKed.
- If the combined value is greater than 0, then the write is ACKed.

Further, VIDo_MAX bit in (BDh) EXT_CAPABILITY_VIDOMAX_H register does not take effect when updated. It only takes effect when the VIDOMAX L register is written with a value (can be the same value as the current one) and also the combined value satisfies the range check. When attempting to write a new VIDo_MAX value, it is recommended to write in the following order: write into the (BDh) EXT CAPABILITY VIDOMAX H register first, and then write into the VIDOMAX L register. To illustrate, a few examples are listed below:

- Example #1: Firstly, a value is written into (BDh) EXT CAPABILITY VIDOMAX H register and is acknowledged. Secondly, another write command is sent to (BEh) VIDOMAX_L register and this write is acknowledged too.
 - Result: The 9-bit VIDo MAX register is updated and takes effect.
- Example #2: A value is written into (BEh) VIDOMAX_L register and is acknowledged. No write command is sent to (BDh) EXT_CAPABILITY_VIDOMAX_H register.
 - Result: The 9-bit VIDo MAX register is updated in the lower 8-bit (in (BEh) VIDOMAX L register) and the new value takes effect.
- Example #3: Firstly, a value is written into (BEh) VIDOMAX_L register and is acknowledged. Secondly, another write command is sent to (BDh) EXT_CAPABILITY_VIDOMAX_H register to update VIDo_MAX bit with a new value and this write is acknowledged too.
 - Result: The 9-bit VIDo MAX register is updated but the VIDo MAX bit in (BDh) EXT CAPABILITY VIDOMAX H register does not take effect.

Note: (BDh) EXT CAPABILITY VIDOMAX H and (BEh) VIDOMAX L registers acknowledges a write only when the power conversion is disabled. A write is not allowed (NACK response) when the power conversion is enabled.

Return to Supported I²C and Default Values.

| Figure 7-63. (A6n) VOUI_CMD Register Map | | | | | | | | |
|------------------------------------------|-----|-----|-----|-----|-----|-----|-----|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W | |
| VIDOMAX_L | | | | | | | | |

Elauro 7.62 (AGh) VOLLT CMD Degister Mon

LEGEND: R/W = Read/Write; R = Read only





Table 7-82. Register Field Descriptions

| Bit | Field | Access | Reset | Description | | | |
|-----|-----------|--------|-------|-----------------------------------------------------------------------|--|--|--|
| 7:0 | VIDOMAX_L | R/W | NVM | These bits sets the lower 8-bit value for the 9-bit VIDoMAX register. | | | |



7.6.61 (C0h) ICC_MAX

| CMD AddressC0hWrite Transaction:Write ByteRead Transaction:Read ByteFormat:Unsigned Binary (1 byte)NVM Backup:EEPROMUpdates:On-the-fly | | |
|----------------------------------------------------------------------------------------------------------------------------------------|--------------------|--------------------------|
| Read Transaction:Read ByteFormat:Unsigned Binary (1 byte)NVM Backup:EEPROM | CMD Address | C0h |
| Format:Unsigned Binary (1 byte)NVM Backup:EEPROM | Write Transaction: | Write Byte |
| NVM Backup: EEPROM | Read Transaction: | Read Byte |
| | Format: | Unsigned Binary (1 byte) |
| Updates: On-the-fly | NVM Backup: | EEPROM |
| | Updates: | On-the-fly |

The ICC_MAX command sets the effective maximum output current that the device reports through the IOUT telemetry sub-system. ICC_MAX setting is not a fault threshold. Upon acknowledging a new value written into this register, the new ICC_MAX value is loaded into SVID (21h) ICC_MAX register immediately.

Return to Supported I²C and Default Values.

Figure 7-64. (C0h) ICC_MAX Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----------|---|---------|-----|-----|-----|
| R | R | R | R | R | R/W | R/W | R/W |
| | | Reserved | | ICC_MAX | | | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|--------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. |
| 2:0 | ICC_MAX | R/W | NVM | These bits configures the ICC_MAX setting. 000b: ICC_MAX = 6 A (not recommended) 001b: ICC_MAX = 10 A (not recommended) 010b: ICC_MAX = 15 A (recommend using 15 A setting for a design with maximum load less than 10 A) 011b: ICC_MAX = 20 A 100b: ICC_MAX = 25 A 101b: ICC_MAX = 30 A 110b: ICC_MAX = 35 A 111b: ICC_MAX = 40 A Note: ICC_MAX = 6 A or 10 A option is not recommended to use. Instread, using the 15 A option for a design with 10A or less load is recommended. |

Table 7-83. Register Field Descriptions



7.6.62 (C1h) TEMP_MAX

| CMD Address | C1h | |
|--------------------|--------------------------|--|
| Write Transaction: | Write Byte | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |
| NVM Backup: | EEPROM | |
| Updates: | On-the-fly | |

The TEMP_MAX command provides a default value for SVID (22h) TEMP_MAX register. The TEMP_MAX setting is not a fault threshold. Upon acknowledging a new value written into this register, the new TEMP_MAX value is loaded into SVID (22h) TEMP_MAX register immediately.

Return to Supported I²C and Default Values.

Figure 7-65. (C1h) TEMP_MAX Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----------|---|----------|-----|-----|-----|
| R | R | R | R | R | R/W | R/W | R/W |
| | · | Reserved | | TEMP_MAX | | | |

LEGEND: R/W = Read/Write; R = Read only

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|--------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:3 | Reserved | R | 00000b | Not used and always set to 0. |
| 2:0 | TEMP_MAX | R/W | NVM | These bits configures the TEMP_MAX setting. 000b: TEMP_MAX = 95 °C 001b: TEMP_MAX = 100 °C 010b: TEMP_MAX = 105 °C 011b: TEMP_MAX = 110 °C 100b: TEMP_MAX = 115 °C 101b: TEMP_MAX = 120 °C 110b: TEMP_MAX = 125 °C 111b: TEMP_MAX = 130 °C |

Table 7-84. Register Field Descriptions



7.6.63 (C2h) PROTOCOL_ID_SVID

| CMD Address | C2h |
|--------------------|----------------------------------------------------------------------------------------------------------------|
| Write Transaction: | Write Byte |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |
| NVM Back-up: | EEPROM |
| Updates: | Vboot: on-the-fly. PROTOCOL_ID and ALL_CALL_SEL: field value update will wait until the power conversion is |
| | disabled. |

This PROTOCOL ID SVID command contains 3 fields for configuring the SVID Protocol ID, Vboot (boot up voltage), and All-call address selection.

The PROTOCOL_ID bits set the Protocol ID for SVID communication. The setting also programs an internal precision resistor divider thus determines the VOUT scaling (mV/LSB) of the device.

The Vboot bits program the initial output voltage at start-up when the output voltage is controlled by SVID interface (e.g. VOUT CTRL = 00b or 01b).

The ALL_CALL_SEL bits set the All-call address for SVID communication.

Return to Supported I²C and Default Values.

Figure 7-66. (C2h) PROTOCOL ID SVID Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------|--------|-------|-----|-----|-----|--------|--------|
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| PROTO | COL_ID | Vboot | | oot | | ALL_CA | LL_SEL |

LEGEND: R/W = Read/Write; R = Read only

| | Table 7-85. Register Field Descriptions | | | | | | | | | |
|-----|-----------------------------------------|--------|-------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|--|--|--|
| Bit | Field | Access | Reset | Description | | | | | | |
| 7:6 | PROTOCOL_ID | R/W | NVM | These bits set the Protocol ID for SVID communication. The setting also programs an internal precision resistor divider thus determines the VOUT scaling (mV/LSB) of the device. 00b: SVID PROTOCOL ID = 04h (VR13, 10 mV). And VOUT_CMD step = 10 mV/LSB 01b: SVID PROTOCOL ID = 07h (VR13, 5 mV). And VOUT_CMD step = 5 mV/LSB 10b: SVID PROTOCOL ID = 09h (VR14, 5 mV). And VOUT_CMD step = 5 mV/LSB 11b: SVID PROTOCOL ID = 09h (VR14, 10 mV). And VOUT_CMD step = 10 mV/LSB 11b: SVID PROTOCOL ID = 0Ah (VR14, 10 mV). And VOUT_CMD step = 10 mV/LSB The function selected in this field is loaded into SVID register (05h) PROTOCOL_ID as well. In order for this field to take effect, the power conversion must be disabled. <i>Note: The TPS544C26 device is VR13 compliant and no support to VR14</i> . | | | | | | |
| 5:2 | Vboot | R/W | NVM | These bits program the initial output voltage at start-up. See Table 7-86 for the available settings. The Vboot and Protocol ID selections have to align based on the listed options on Table 7-86 no matter the VOUT adjustment is controlled by SVID interface or I2C interface. Otherwise, an error check will NACK the write attempt. For example, a write attempt with C2h = 011111xxb (Vboot = 1.8 V and Protocol ID = 5 mV) will be NACKed, while a write attempt with C2h = 011000xxb (Vboot = 1.1V and Protocol ID = 5mV) will be ACKed. The function selected in this field is loaded into SVID register (26h) VBOOT as well, in VID format. | | | | | | |



| | Table 7-85. Register Field Descriptions (continued) | | | | | | | | |
|-----|-----------------------------------------------------|--------|-------------------------------------------|-----------------------------------------------------------------------------------------|--|--|--|--|--|
| Bit | Field | Access | Reset | Description | | | | | |
| 1:0 | ALL_CALL_SEL | R/W | NVM | These bits set the All-call address for SVID communication. | | | | | |
| | | | | 00b: Not support All-call address, will reject both 0Eh and 0Fh address | | | | | |
| | | | 01b: Respond to All-call address 0Fh only | | | | | | |
| | | | | 10b: Respond to All-call address 0Eh only | | | | | |
| | | | | 11b: Respond to All-call address both 0Eh and 0Fh | | | | | |
| | | | | The function selected in this field is loaded into SVID register (0Fh) ALLCALL_ACT | | | | | |
| | | | | as well. In order for this field to take effect, the power conversion must be disabled. | | | | | |

Table 7-86. Vboot settings

| Vboot | VID code ⁽¹⁾ (Hex) | Vboot (V) | PROTOCOL_ID | | | | | | | |
|-------|-------------------------------|-----------|----------------------------------------------------------|--|--|--|--|--|--|--|
| 0000b | 00h | 0 | | | | | | | | |
| 0001b | 65h | 0.75 | | | | | | | | |
| 0010b | 6Fh | 0.80 | | | | | | | | |
| 0011b | 79h | 0.85 | | | | | | | | |
| 0100b | 83h | 0.90 | | | | | | | | |
| 0101b | 8Dh | 0.95 | | | | | | | | |
| 0110b | 97h | 1.00 | Must set PROTOCOL_ID = 01b or 10b (VOUT step = 5 mV) | | | | | | | |
| 0111b | A1h | 1.05 | | | | | | | | |
| 1000b | ABh | 1.10 | | | | | | | | |
| 1001b | AFh | 1.20 | | | | | | | | |
| 1010b | C9h | 1.25 | | | | | | | | |
| 1011b | DDh | 1.35 | | | | | | | | |
| 1100b | FBh | 1.50 | | | | | | | | |
| 1101b | 6Fh | 1.60 | | | | | | | | |
| 1110b | 79h | 1.70 | Must set PROTOCOL_ID = 00b or 11b (VOUT step = 10 mV) | | | | | | | |
| 1111b | 83h | 1.80 | | | | | | | | |



7.6.64 (C6h) VENDOR_ID

| CMD Address | C6h | |
|--------------------|--------------------------|--|
| Write Transaction: | N/A | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |

The VENDOR_ID command reads an unique identity of the IC vendor. This vendor ID value is assigned to Texas Instruments by Intel. The Vendor ID value is loaded into SVID (00h) VENDOR_ID register during the initial power-on.

Return to Supported I²C and Default Values.

Figure 7-67. (C6h) VENDOR_ID Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|---|---|---|------|-------|---|---|---|--|
| R | R | R | R | R | R | R | R | |
| | | | VEND | OR_ID | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-87. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-----------|----------------------------------------|
| 7:0 | VENDOR_I | R | 00100010b | A Vendor ID to identify the IC vendor. |
| | D | | | |



7.6.65 (C8h) PRODUCT_ID

| CMD Address | C8h |
|--------------------|--------------------------|
| Write Transaction: | N/A |
| Read Transaction: | Read Byte |
| Format: | Unsigned Binary (1 byte) |

The PRODUCT_ID command reads an unique identity of the IC. This unique product ID is chosen by Texas Instruments for TPS544C26 device. The product ID value is loaded into SVID (01h) PRODUCT_ID register during the initial power-on.

Return to Supported I²C and Default Values.

Figure 7-68. (C8h) PRODUCT_ID Register Map

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|---|---|---|-------|--------|---|---|---|--|
| R | R | R | R | R | R | R | R | |
| | | | PRODU | JCT_ID | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-88. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|----------|--------|-----------|------------------------------------------------|
| 7:0 | PRODUCT_ | R | 00010011b | A product ID to identify the TPS544C26 device. |
| | ID | | | |



7.6.66 (C9h) PRODUCT_REV_ID

| CMD Address | C9h | |
|--------------------|--------------------------|--|
| Write Transaction: | N/A | |
| Read Transaction: | Read Byte | |
| Format: | Unsigned Binary (1 byte) | |

The PRODUCT_REV_ID command reads the IC's revision. This product revision ID is assigned by Texas Instruments and this value is loaded into SVID (02h) PRODUCT_REV register during the initial power-on.

Return to Supported I²C and Default Values.

Figure 7-69. (C9h) PRODUCT_REV_ID Register Map

| | | • | · / | | • • | | | |
|---|---|---|--------|----------|-----|---|---|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| R | R | R | R | R | R R | | R | |
| | | | PRODUC | T_REV_ID | | | | |

LEGEND: R/W = Read/Write; R = Read only

Table 7-89. Register Field Descriptions

| Bit | Field | Access | Reset | Description |
|-----|--------------------|--------|-------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7:0 | PRODUCT_ REV_ID | R | | These bits read the TPS544C26 device's revision. 00000010b: PG2.1 production unit (current revision) 00000001b: PG2.0 engineering samples (previous revision) 00000000b: PG1.0 engineering samples (previous revision) |



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TPS544C26 device is a highly-integrated, synchronous, step-down DC/DC converter. The TPS544C26 has a simple design procedure where programmable parameters can be configured by I²C and stored to nonvolatile memory (NVM) to minimize external component count.

8.2 Typical Application

8.2.1 Application

This design describes a 1.1-V, 35-A application for a VCCD_HV rail in an Intel Server platform.

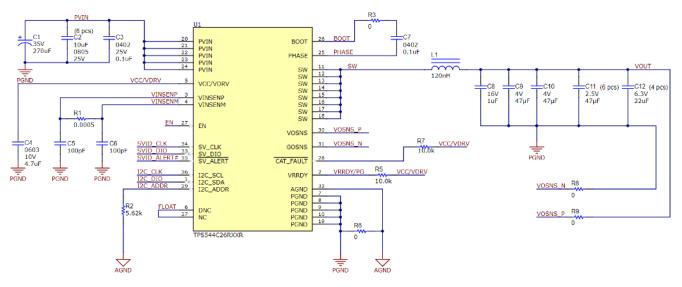


Figure 8-1. VCCD_HV 1.1 V Output Application

8.2.2 Design Requirements

This design uses the parameters listed in Table 8-1.

Table 8-1. Design Parameters

| PARAMETER | VALUE | | | | |
|--------------------------|-----------------|--|--|--|--|
| Input Voltage | 10.8 V – 13.2 V | | | | |
| Output Voltage | 1.1 V | | | | |
| Output Current | 35 A | | | | |
| Switching Frequency | 800 kHz | | | | |
| I ² C Address | 71h | | | | |
| SVID Address | 00h | | | | |



8.2.3 Detailed Design Procedure

This design example leverages the requirements for the VCCD_HV rail in an Intel Server platform. The default settings for this device are optimal for this application. The following steps illustrate how to select key components.

8.2.3.1 Inductor Selection

The inductor must be selected such that the transient performance and ripple requirements are balanced for a particular design. In general, a smaller inductance increases loop bandwidth leading to better transient response at the expense of higher current and voltage ripple. In this example, a 120-nH, 0.228-m Ω inductor is used.

8.2.3.2 Input Capacitor Selection

Input capacitors must be selected to provide reduction in input voltage ripple and high-frequency bypassing, which in return will reduce switching stress on the power stage MOSFETs internal to the device. In this example, a 0.1- μ F, 25-V, 0402 must be placed as close as possible to pin 20 of the device on the same layer as the IC on the PCB. In addition, 6x 10- μ F ceramic capacitors are used and a 270- μ F bulk capacitor is used on the input.

8.2.3.3 Output Capacitor Selection

To meet the output voltage ripple and load transient requirements in the Intel specification, use a $1-\mu$ F and 2 x $47-\mu$ F ceramic capacitors local to the output of the inductor. Additionally, use 6 x $47-\mu$ F on the top-side of the CPU socket cavity combined with 4 x $22-\mu$ F capacitors on the bottom-side of the CPU socket cavity.

8.2.3.4 VCC/VRDV Bypass Capacitor

Use a minimum of 2.2-µF to 4.7-µF, 10-V rated capacitor for bypassing of the VCC/VDRV pin. This bypass capcitor must refer to PGND to minimize the length of high-frequency driving current path.

8.2.3.5 BOOT Capacitor Selection

Use a minimum of a $0.1-\mu$ F capacitor connected from Phase (pin 25) to Boot (pin 26). An optional serires boot resistor of $0-\Omega$ or $2.2-\Omega$ can be added.

8.2.3.6 RSENSE Selection

In this application, a $0.5-\Omega$ resistor is selected to sense the input current (IIN) on a 12 V bus for DDR5 DIMMs. The sensed input current and the sensed input voltage on pin 4 VINSENM are used to calculate the total input power. The input power information can be read through telemetry registers and used for power management.

8.2.3.7 VINSENP and VINSENN Capacitor Selection

Use a 100-pF ceramic capacitor referenced to PGND on both the VINSENP (pin 3) and VINSENN (pin 4). The decoupling capacitors minimizes the impact from switching noise on the 12 bus and thus help the device to achieve high accuracy on IIN reporting.

8.2.3.8 VRRDY Pullup Resistor Selection

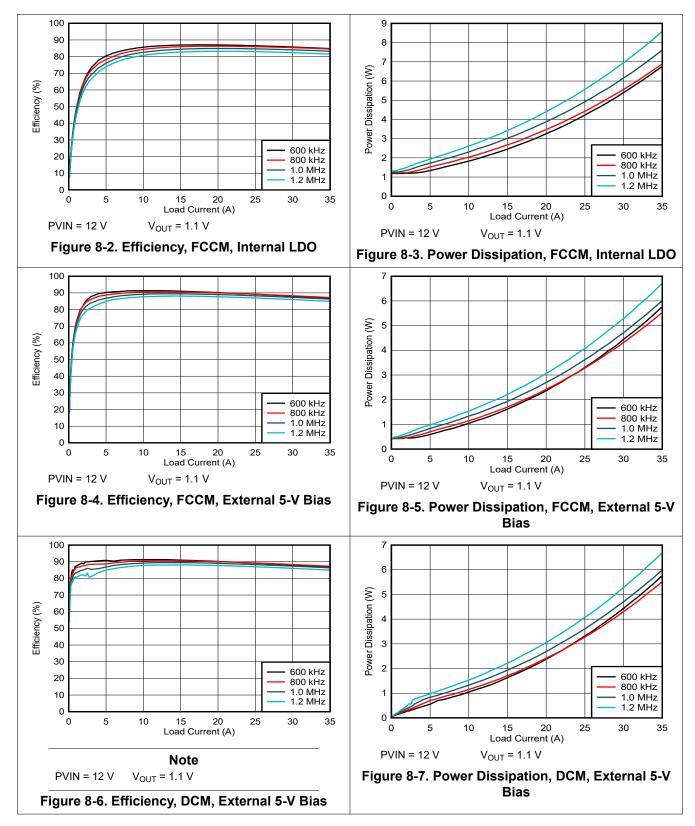
The VRRDY output is an open-drain output and must be pulled up externally through a pullup resistor. Place a pull-up resistor, within a 1-k Ω to 100-k Ω range, at the VRRDY pin (pin 2). In this example, VRRDY is pulled up to VCC/VDRV with a 10-k Ω resitor.

8.2.3.9 I²C Address Resistor Selection

Refer to Table 7-16 for the list of I²C addresses selectable by an external resistor. A resistor between the I²C_ADDR (pin 29) and AGND sets the preconfigured I²C address in the memory map. In this application, the 5.62-k Ω resistor selects an I²C address of 71h.

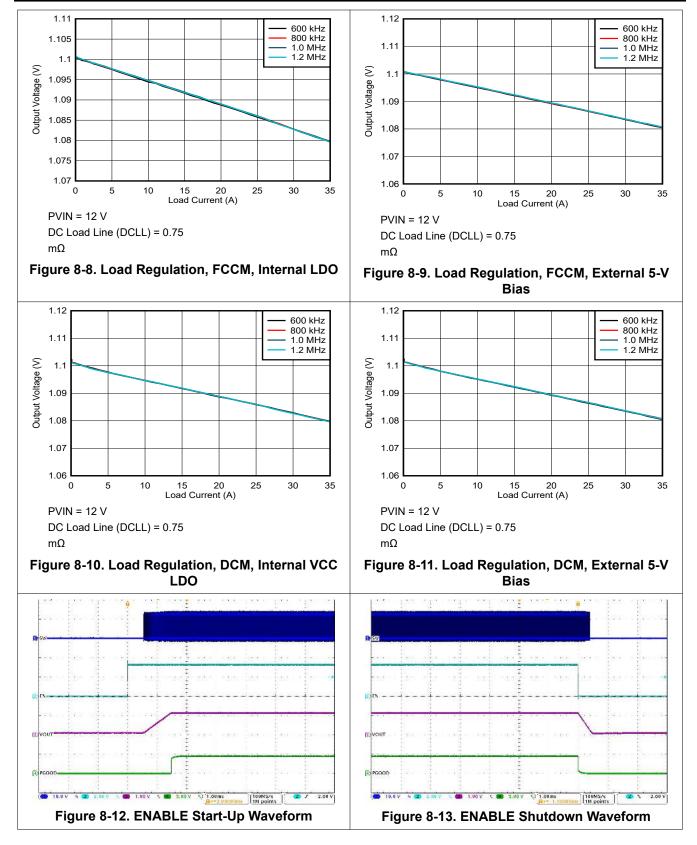


8.2.4 Application Curves

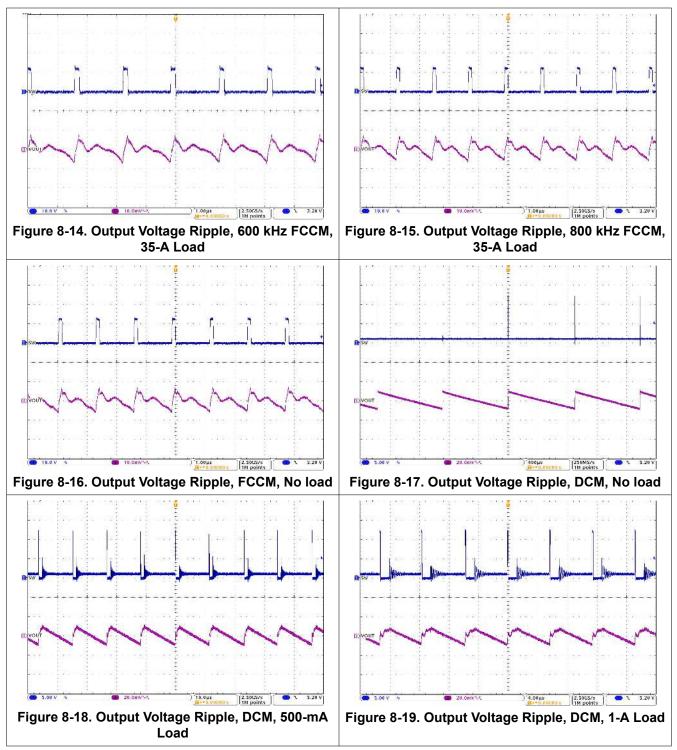




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8.3 Power Supply Recommendations

The device is designed to operate from a wide input voltage supply range between 2.7 V and 16 V when the VCC/VDRV pin is powered by an external bias ranging from 4.75 V to 5.3 V. Both input supplies (PVIN and VCC bias) must be well regulated. Proper bypassing of input supplies (PVIN and VCC/VDRV) is also critical for noise performance, as are PCB layout and grounding scheme. See the recommendations in *Layout Guidelines*.



8.4 Layout

8.4.1 Layout Guidelines

Layout is critical for good power-supply design. Layout example shows the recommended PCB-layout configuration. A list of PCB layout considerations using the device is listed as follows:

- Place the power components (including input and output capacitors, the inductor, and the IC) on the top side of the PCB. To shield and isolate the small signal traces from noisy power lines, insert at least one solid ground inner plane.
- PVIN-to-PGND decoupling capacitors are important for FET robustness. Besides the large volume 0603 or 0805 ceramic capacitors, TI highly recommends a 0.1-µF 0402 ceramic capacitor with 25 V / X7R rating on PVIN pin 20 (top layer) to bypass any high frequency current in PVIN to PGND loop. The 25-V rating is recommended but can be lowered to 16-V rating for an application with tightly regulated 12-V input bus.
- When one or more PVIN-to-PGND decoupling capacitors are placed on bottom layer, extra impedance is introduced to bypass IC PVIN node to IC PGND node. Placing at least 3 times PVIN vias on PVIN pad (formed by pin 20 to pin 24) and at least 9 times PGND vias on the thermal pad (underneath of the IC) is important to minimize the extra impedance for the bottom layer bypass capacitors.
- Except the PGND vias underneath the thermal pad, at least 4 PGND vias are required to be placed as close as possible to the PGND pin 7 to pin 10. At least 2 PGND vias are required to be placed as close as possible to the PGND pin 19. Thisaction minimizes PGND bounces and also lowers thermal resistance.
- Place the VCC/VDRV-to-PGND decoupling capacitor as close as possible to the device. TI recommends a2.2-µF/6.3-V/X7R/0603 or 4.7-µF/6.3-V/X6S/0603 ceramic capacitor. The voltage rating of this bypass capacitor must be at least 6.3 V but no more than 10 V to lower ESR and ESL. The recommended capacitor size is 0603 to minimize the capacitance drop due to DC bias effect. Ensure the VCC/VDRV to PGND decoupling loop is the smallest and ensure the routing trace is wide enough to lower impedance.
- For remote sensing, the connections from the VOSNS/GOSNS pins to the remote location must be a pair of PCB traces with at least 12 mil trace width, and must implement Kelvin sensing across a high bypass capacitor of 0.1 µF or higher. The ground connection of the remote sensing signal must be connected to GOSNS pin. The VOUT connection of the remote sensing signal must be connected to the VOSNS pin. To maintain stable output voltage and minimize the ripple, the pair of remote sensing lines must stay away from any noise sources such as inductor and SW nodes, or high frequency clock lines. And TI recommends to shield the pair of remote sensing lines with ground planes above and below.
- For single-end sensing, connect the VOSNS pin to a high-frequency local bypass capacitor of 0.1 µF or higher, and short GOSNS to AGND with shortest trace.
- To minimize the impact from switching noise and achieve high accuracy on the input power monitoring feature, a PGND referenced bypass capacitor is required for each of VINSENP and VINSENM pins, with at least 100-pF volume and at least 25-V rating. These bypass capacitors must be placed close to VINSENP or VINSENM pin accordingly.
- In a case that the input power feature is not used, follow below connection for pin 3 VINSENP and pin 4 VINSENM so that the device can report the input voltage level on PVIN node:
 - 1. Short pin 3 VINSENP to pin 4 VINSENM,
 - 2. Place a 0.1 µF ceramic bypass capacitor on pin 4 VINSENM referring to AGND,
 - 3. Connect pin 4 VINSENM to PVIN node of TPS544C26 device.
- The AGND pin 32 must be connected to a solid PGND plane. TI recommends to place two AGND vias close to pin 32 to route AGND from top layer to bottom layer, and then connect the AGND trace to the PGND vias (underneath IC) through either a net-tie or a 0 Ω resistor on the bottom layer.
- Connecting a resistor from pin 29 (I²C_ADDR) to AGND sets I²C address. It is required not to have any capacitor on pin 29. A capacitor on pin 29 likely leads to a wrong detection result for I²C address.
- Pin 6 (DNC) is a Do-Not-Connect pin. Pin 6 can be shorted to pin 37, which is an NC pin (No internal Connection). Do not connect pin 6 to any other net including ground.



8.4.2 Layout Example

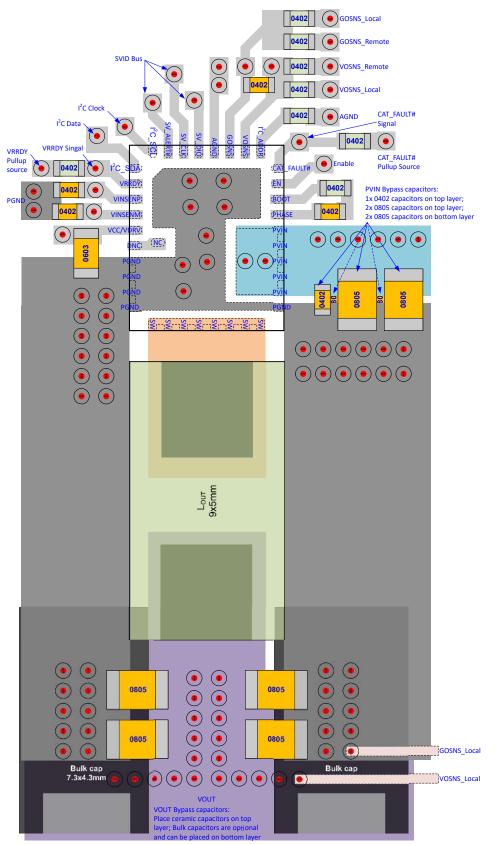
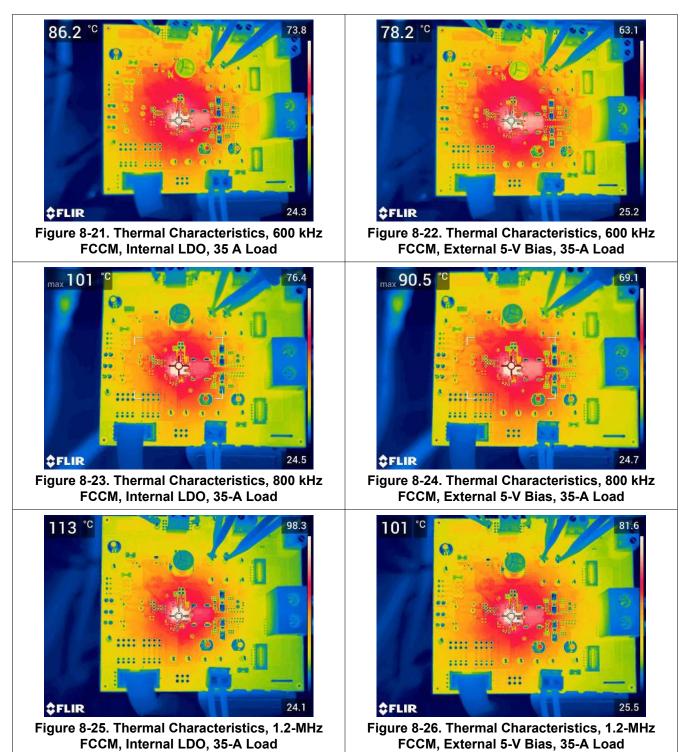


Figure 8-20. Layout Recommendation



8.4.2.1 Thermal Performance on TPS544C26EVM

Below are thermal results captured on the TPS544C26EVM with PVIN = 12 V, V_{OUT} = 1.1 V conditions.





9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Documentation Support

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.



10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|-------------------------------|----------------------|--------------|-------------------------|---------|
| | | | | | | | (6) | | | | |
| TPS544C26RXXR | ACTIVE | WQFN-FCRLF | RXX | 37 | 3000 | RoHS & Green | Call TI NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 544C26 | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

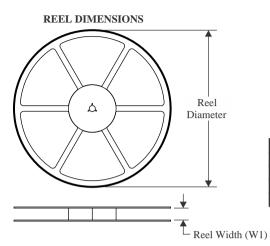
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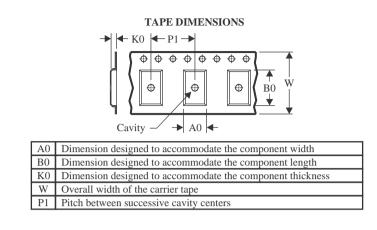
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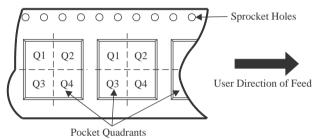
www.ti.com

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions a | re nominal |
|-------------------|------------|
|-------------------|------------|

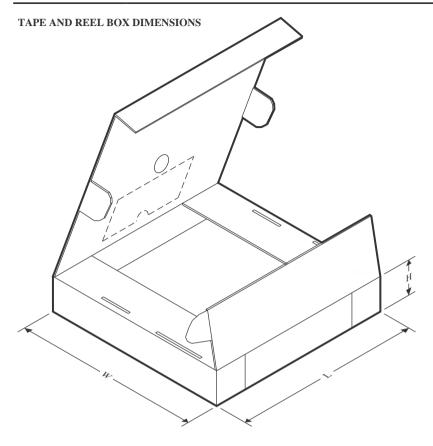
| Device | | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TPS544C26RXXR | WQFN- FCRLF | RXX | 37 | 3000 | 330.0 | 12.4 | 5.25 | 6.3 | 1.0 | 8.0 | 12.0 | Q1 |



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PACKAGE MATERIALS INFORMATION

17-Apr-2023



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS544C26RXXR | WQFN-FCRLF | RXX | 37 | 3000 | 338.0 | 355.0 | 50.0 |

RXX 37

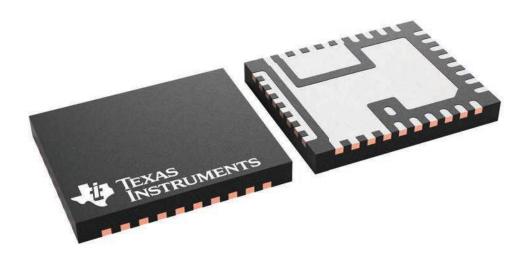
5 x 6, 0.5 mm pitch

GENERIC PACKAGE VIEW

VQFN-FCRLF - 1.05 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

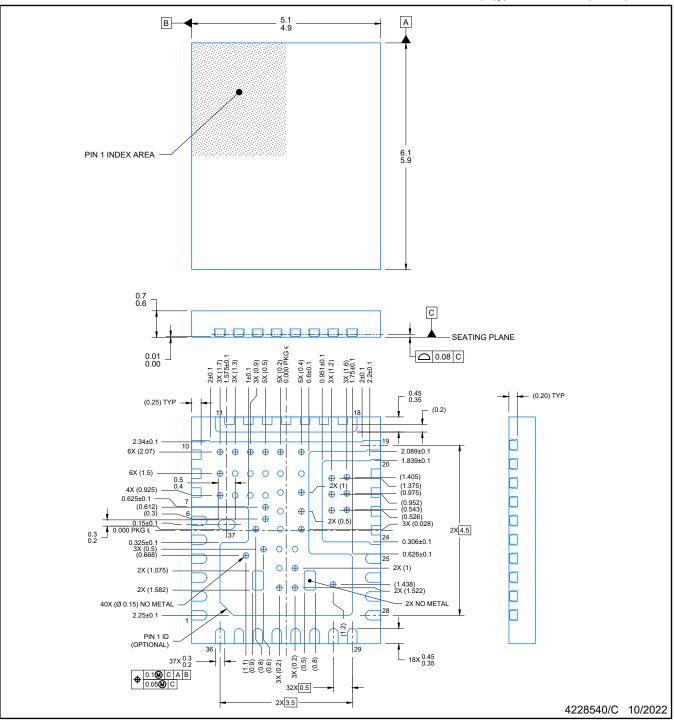




RXX0037B

PACKAGE OUTLINE WQFN-FCRLF - 0.7 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

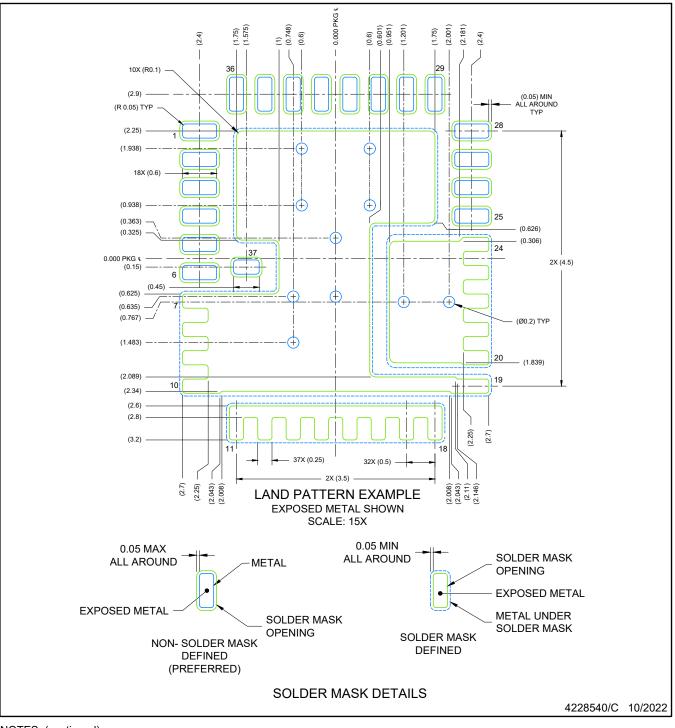


RXX0037B

EXAMPLE BOARD LAYOUT

WQFN-FCRLF - 0.7 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

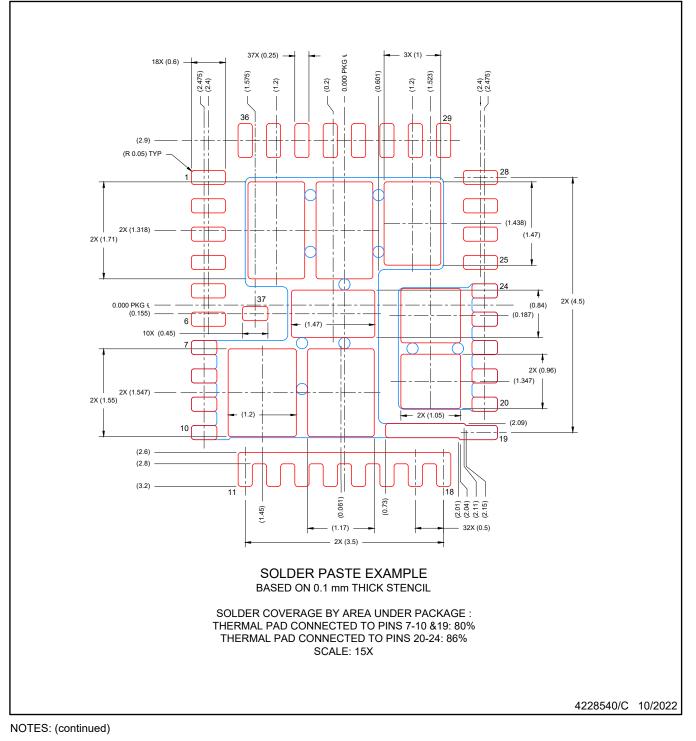


RXX0037B

EXAMPLE STENCIL DESIGN

WQFN-FCRLF - 0.7 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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